

## 80 V Automotive Three-Phase MOSFET Driver

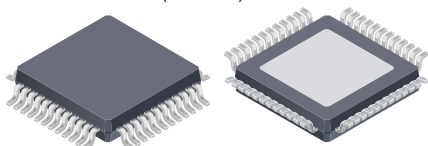
### FEATURES AND BENEFITS

- 3-phase bridge MOSFET driver
- Bootstrap gate drive for N-channel MOSFET bridge
- Cross-conduction protection with adjustable dead time
- Fixed-frequency buck converter
- Operation at any PWM duty cycle up to and including 100%
- Programmable gate drive strength
- 10 to 80 V supply voltage operating range
- Programmable 3.3 or 5 V CMOS compatible logic I/O
- Three programmable current sense amplifiers
- SPI-compatible serial interface
- Bridge control by direct logic inputs or serial interface
- Programmable control input logic sense
- Extensive programmable diagnostics
- Diagnostic verification
- Safety-assist features
- Automotive AEC-Q100 qualified
- A<sup>2</sup>-SIL™ product—device features for safety-critical systems\*



### PACKAGE:

48-pin LQFP with  
exposed thermal pad  
(suffix JP)



*Not to scale*

\*The AMT49100 was developed in accordance with ISO 26262:2011 as a hardware safety element out of context with ASIL D capability for use in automotive safety-related systems when integrated and used in the manner prescribed in the applicable safety application note and datasheet.

### DESCRIPTION

The AMT49100 is an N-channel power MOSFET driver capable of controlling MOSFETs connected in a 3-phase bridge arrangement and is specifically designed for 48 V automotive power applications with high-power inductive loads, such as BLDC motors.

A fixed-frequency buck converter provides a regulated gate drive and bootstrap charge voltage over the full supply voltage range from 10 to 80 V. A bootstrap capacitor is used to provide the above-battery supply voltage required for N-channel MOSFETs. The bootstrap charge is maintained by an additional charge pump providing 0-100% PWM with no duty cycle restriction.

Full control over all six power MOSFETs in the 3-phase bridge is provided, allowing motors to be driven with block commutation or sinusoidal excitation. The power MOSFETs are protected from shoot-through by integrated crossover control and optional programmable dead time.

Integrated diagnostics provide indication of multiple internal faults, system faults, and power bridge faults, and can be configured to protect the power MOSFETs under most short-circuit conditions. For safety-critical systems, the integrated diagnostic operation can be verified under control of the serial interface.

In addition to providing full access to the bridge control, the serial interface is also used to alter programmable settings such as dead time, VDS threshold, and fault blank time. Detailed diagnostic information can be read through the serial interface.

The AMT49100 is supplied in a 48-pin QFP package (suffix JP) with exposed thermal pad. The package is lead (Pb) free with 100% matte-tin leadframe plating.

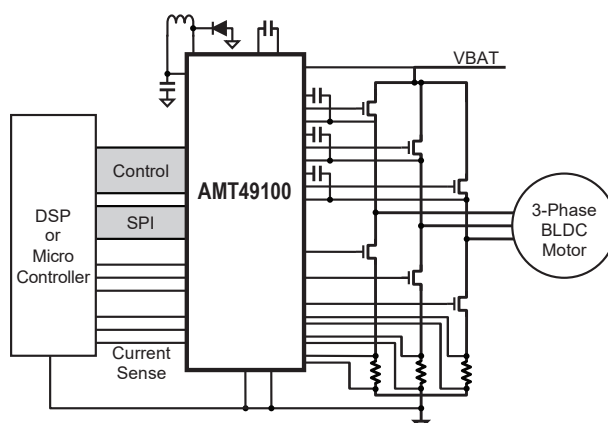


Figure 1: Typical Application

## SELECTION GUIDE

| Part Number       | Buck Regulator | V <sub>IO</sub> (V) | Packing                      | Package                                                                         |
|-------------------|----------------|---------------------|------------------------------|---------------------------------------------------------------------------------|
| AMT49100KJPTR-A-3 | Enabled        | 3.3                 | 1500 pieces per 13-inch reel | 7 mm × 7 mm, 1.6 mm nominal height<br>48-terminal LQFP with exposed thermal pad |
| AMT49100KJPTR-A-5 | Enabled        | 5                   |                              |                                                                                 |
| AMT49100KJPTR-B-3 | Disabled       | 3.3                 |                              |                                                                                 |
| AMT49100KJPTR-B-5 | Disabled       | 5                   |                              |                                                                                 |

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## ABSOLUTE MAXIMUM RATINGS [1][2]

| Characteristic                               | Symbol       | Notes                                                                                                                             | Rating                            | Unit |
|----------------------------------------------|--------------|-----------------------------------------------------------------------------------------------------------------------------------|-----------------------------------|------|
| Supply Voltage                               | $V_{BB}$     |                                                                                                                                   | -0.3 to 80                        | V    |
| Between Ground Terminals                     |              | Connect GND terminals together at package                                                                                         | -0.1 to 0.1                       | V    |
| Drive Regulator Terminal                     | $V_{REG}$    | VREG                                                                                                                              | -0.3 to 16                        | V    |
| Buck Switch Terminal                         | $V_{LX}$     | LX                                                                                                                                | -1 to 80                          | V    |
| Bootstrap Pump Capacitor Terminal            | $V_{CP1}$    | CP1                                                                                                                               | -0.3 to $V_{BRG} + 0.3$           | V    |
| Bootstrap Pump Capacitor Terminal            | $V_{CP2}$    | CP2                                                                                                                               | $V_{CP1} - 0.3$ to $V_{BRG} + 12$ | V    |
| Battery-Compliant Logic Input Terminals      | $V_{IB}$     | HA, HB, HC, LA, LB, LC, ENABLE, RESETn                                                                                            | -0.3 to 80                        | V    |
| Logic Input Terminals                        | $V_I$        | STRn, SCK, SDI                                                                                                                    | -0.3 to 6                         | V    |
| Logic Output Terminals                       | $V_O$        | SDO, SAL, SBL, SCL                                                                                                                | -0.3 to 6                         | V    |
| Diagnostic Output Terminal                   | $V_{DIAG}$   | DIAG                                                                                                                              | -0.3 to 80                        | V    |
| Sense Amplifier Inputs                       | $V_{CSI}$    | CSxP, CSxM                                                                                                                        | -4 to 6.5                         | V    |
| Sense Amplifier Output                       | $V_{CSO}$    | CSxO                                                                                                                              | -0.3 to 6                         | V    |
| Bridge Drain Monitor Terminal                | $V_{BRG}$    | VBRG                                                                                                                              | -5 to 85                          | V    |
| Bootstrap Supply Terminals                   | $V_{Cx}$     | CA, CB, CC                                                                                                                        | -0.3 to $V_{REG} + 80$            | V    |
| High-Side Gate Drive Outputs                 | $V_{GHx}$    | GHA, GHB, GHC                                                                                                                     | $V_{Cx} - 16$ to $V_{Cx} + 0.3$   | V    |
|                                              |              | GHA, GHB, GHC (transient) [3]                                                                                                     | -18 to $V_{Cx} + 0.3$             | V    |
| Motor Phase Terminals                        | $V_{Sx}$     | SA, SB, SC                                                                                                                        | $V_{Cx} - 16$ to $V_{Cx} + 0.3$   | V    |
|                                              |              | SA, SB, SC (transient) [3]                                                                                                        | -18 to $V_{Cx} + 0.3$             | V    |
| Low-Side Gate Drive Outputs                  | $V_{GLx}$    | GLA, GLB, GLC                                                                                                                     | $V_{REG} - 16$ to 18              | V    |
|                                              |              | GLA, GLB, GLC (transient) [3]                                                                                                     | -8 to 18                          | V    |
| Bridge Low-Side Source Terminals             | $V_{LSS}$    | LSSA, LSSB, LSSC                                                                                                                  | $V_{REG} - 16$ to 18              | V    |
|                                              |              | LSSA, LSSB, LSSC (transient) [3]                                                                                                  | -8 to 18                          | V    |
| NVM Maximum Programming Junction Temperature | $T_{NVM}$    | Guaranteed by design characterization                                                                                             | 85                                | °C   |
| Ambient Operating Temperature Range          | $T_A$        | Limited by power dissipation                                                                                                      | -40 to 150                        | °C   |
| Maximum Continuous Junction Temperature      | $T_{J(max)}$ |                                                                                                                                   | 165                               | °C   |
| Transient Junction Temperature               | $T_{Jt}$     | Over temperature event not exceeding 10 seconds, lifetime duration not exceeding 10 hours, guaranteed by design characterization. | 180                               | °C   |
| Storage Temperature Range                    | $T_{stg}$    |                                                                                                                                   | -55 to 150                        | °C   |

[1] With respect to GND. Ratings apply when no other circuit operating constraints are present.

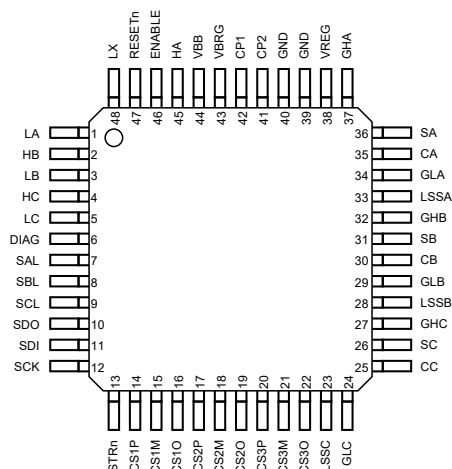
[2] Lowercase "x" in terminal names and symbols indicates a variable sequence character.

[3] Not tested in production. Confirmed by design and characterization. Duration less than 1  $\mu$ s.

## THERMAL CHARACTERISTICS: May require derating at maximum conditions

| Characteristic                | Symbol          | Test Conditions [4]                                            | Value | Unit |
|-------------------------------|-----------------|----------------------------------------------------------------|-------|------|
| JP Package Thermal Resistance | $R_{\theta JA}$ | 4-layer PCB based on JEDEC standard                            | 23    | °C/W |
|                               |                 | 2-layer PCB with 3.8 in. <sup>2</sup> of copper area each side | 44    | °C/W |
|                               | $R_{\theta JP}$ |                                                                | 2     | °C/W |

[4] Additional thermal information available on the Allegro website.



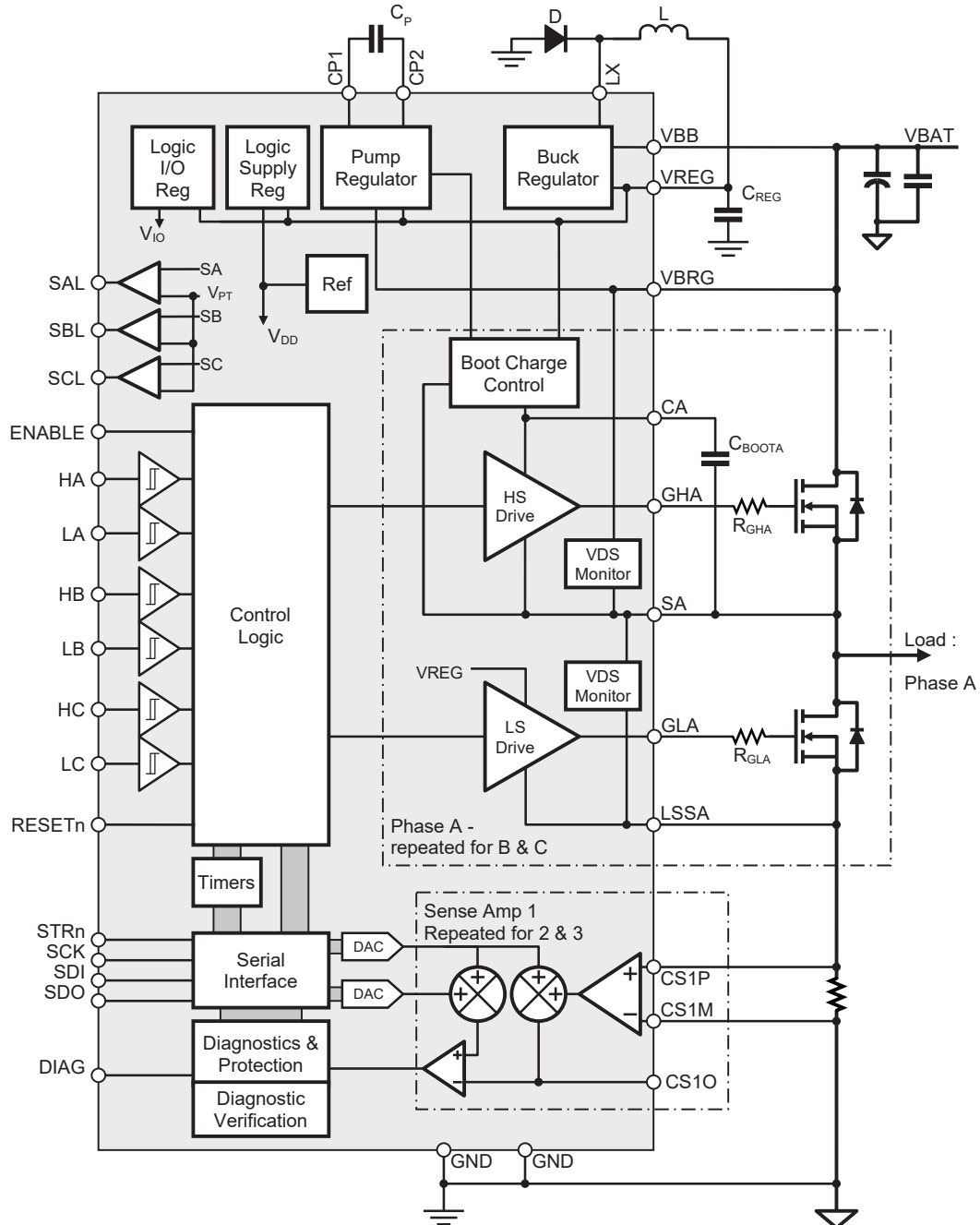
QFP-48 (JP) Package Pinout Diagram

## Pinout List

| Name   | Number | Function                         |
|--------|--------|----------------------------------|
| CA     | 35     | Bootstrap Capacitor Phase A      |
| CB     | 30     | Bootstrap Capacitor Phase B      |
| CC     | 25     | Bootstrap Capacitor Phase C      |
| CP1    | 42     | Pump Capacitor Terminal          |
| CP2    | 41     | Pump Capacitor Terminal          |
| CS1M   | 15     | Current Sense Amplifier 1 -Input |
| CS1O   | 16     | Current Sense Amplifier 1 Output |
| CS1P   | 14     | Current Sense Amplifier 1 +Input |
| CS2M   | 18     | Current Sense Amplifier 2 -Input |
| CS2O   | 19     | Current Sense Amplifier 2 Output |
| CS2P   | 17     | Current Sense Amplifier 2 +Input |
| CS3M   | 21     | Current Sense Amplifier 3 -Input |
| CS3O   | 22     | Current Sense Amplifier 3 Output |
| CS3P   | 20     | Current Sense Amplifier 3 +Input |
| DIAG   | 6      | Programmable Diagnostic Output   |
| ENABLE | 46     | Direct Output Activity Control   |
| GHA    | 37     | High-Side Gate Drive Phase A     |
| GHB    | 32     | High-Side Gate Drive Phase B     |
| GHC    | 27     | High-Side Gate Drive Phase C     |
| GLA    | 34     | Low-Side Gate Drive Phase A      |
| GLB    | 29     | Low-Side Gate Drive Phase B      |
| GLC    | 24     | Low-Side Gate Drive Phase C      |
| GND    | 39     | Ground                           |
| GND    | 40     | Ground                           |
| PAD    | Pad    | Connect To Ground                |

| Name   | Number | Function                          |
|--------|--------|-----------------------------------|
| HA     | 45     | Control Input A High Side         |
| HB     | 2      | Control Input B High Side         |
| HC     | 4      | Control Input C High Side         |
| LA     | 1      | Control Input A Low Side          |
| LB     | 3      | Control Input B Low Side          |
| LC     | 5      | Control Input C Low Side          |
| LSSA   | 33     | Low-Side Source Phase A           |
| LSSB   | 28     | Low-Side Source Phase B           |
| LSSC   | 23     | Low-Side Source Phase C           |
| LX     | 48     | Buck Regulator Switch Terminal    |
| RESETn | 47     | RESET input                       |
| SA     | 36     | Load Connection Phase A           |
| SAL    | 7      | Phase A Logic Output              |
| SB     | 31     | Load Connection Phase B           |
| SBL    | 8      | Phase B Logic Output              |
| SC     | 26     | Load Connection Phase C           |
| SCK    | 12     | Serial Clock Input                |
| SCL    | 9      | Phase C Logic Output              |
| SDI    | 11     | Serial Data Input                 |
| SDO    | 10     | Serial Data Output                |
| STRn   | 13     | Serial Strobe (Chip Select) Input |
| VBB    | 44     | Main Power Supply                 |
| VBRG   | 43     | High-Side Drain Voltage Sense     |
| VREG   | 38     | Gate Drive Supply Output          |

## FUNCTIONAL BLOCK DIAGRAM



## ELECTRICAL CHARACTERISTICS: Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80$ V, unless otherwise specified

| Characteristic                                                        | Symbol             | Test Conditions                                                                                                                                        | Min. | Typ. | Max. | Unit |
|-----------------------------------------------------------------------|--------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| <b>SUPPLY AND REFERENCE</b>                                           |                    |                                                                                                                                                        |      |      |      |      |
| V <sub>BB</sub> Functional Operating Range, Regulator Active          | V <sub>BB</sub>    | Operating; outputs active                                                                                                                              | 10   | –    | 80   | V    |
|                                                                       |                    | Operating <sup>[1]</sup> ; outputs disabled                                                                                                            | 5    | –    | 80   | V    |
|                                                                       |                    | No unsafe states                                                                                                                                       | 0    | –    | 80   | V    |
| V <sub>BB</sub> Quiescent Current, Regulator Active                   | I <sub>BBQ</sub>   | V <sub>BB</sub> = 48 V, all gate drive outputs low                                                                                                     | –    | 6    | 15   | mA   |
| V <sub>BB</sub> Quiescent Current, Regulator Inactive                 | I <sub>BBQ</sub>   | V <sub>BB</sub> = V <sub>REG</sub> = 12 V, all gate drive outputs low                                                                                  | –    | 1    | 2    | mA   |
| V <sub>BB</sub> Sleep Current                                         | I <sub>BBS</sub>   | V <sub>RESETn</sub> ≤ 300 mV, sleep mode, V <sub>BB</sub> < 60 V                                                                                       | –    | –    | 10   | μA   |
| V <sub>BRG</sub> Operating Range                                      | V <sub>BRG</sub>   |                                                                                                                                                        | 4.5  | 48   | 80   | V    |
| V <sub>BRG</sub> Input Current                                        | I <sub>BRGQ</sub>  |                                                                                                                                                        | –    | 3    | 5    | mA   |
|                                                                       | I <sub>BRGS</sub>  | V <sub>RESETn</sub> ≤ 300 mV, sleep mode, V <sub>BRG</sub> < 60 V                                                                                      | –    | –    | 2    | μA   |
| V <sub>REG</sub> Functional Operating Input Range, Regulator Inactive | V <sub>REG</sub>   | Operating; outputs active                                                                                                                              | 11   | –    | 14.5 | V    |
|                                                                       |                    | Operating <sup>[1]</sup> ; outputs disabled                                                                                                            | 4.5  | –    | 15   | V    |
|                                                                       |                    | No unsafe states                                                                                                                                       | 0    | –    | 16   | V    |
| V <sub>REG</sub> Quiescent Current, Regulator Inactive                | I <sub>REGQ</sub>  | V <sub>REG</sub> = 12 V, all gate drive outputs low                                                                                                    | –    | 20   | 30   | mA   |
|                                                                       | I <sub>REGS</sub>  | V <sub>RESETn</sub> ≤ 300 mV, sleep mode, V <sub>REG</sub> = 12 V                                                                                      | –    | –    | 100  | μA   |
| Buck Regulator Switching Frequency                                    | f <sub>BR</sub>    |                                                                                                                                                        | 370  | 410  | 450  | kHz  |
| V <sub>REG</sub> Output Voltage, Regulator Active                     | V <sub>REG</sub>   | V <sub>BB</sub> > 20 V, 0 mA < I <sub>VREG</sub> < 100 mA                                                                                              | 11.5 | 12.5 | 13.5 | V    |
| Internal Logic Supply Regulator Voltage <sup>[4][5]</sup>             | V <sub>DD</sub>    | V <sub>REG</sub> > 6.5 V                                                                                                                               | –    | 3.3  | –    | V    |
| Internal Logic I/O Regulator Voltage <sup>[4][5]</sup>                | V <sub>IO</sub>    | V <sub>IO</sub> = 0, V <sub>REG</sub> > 6.5 V                                                                                                          | 3.1  | 3.3  | 3.5  | V    |
|                                                                       |                    | V <sub>IO</sub> = 1, V <sub>REG</sub> > 8.5 V                                                                                                          | 4.8  | 5.0  | 5.2  | V    |
| Logic I/O Regulator Drop-Out Voltage                                  | V <sub>IODO</sub>  | w.r.t. V <sub>REG</sub>                                                                                                                                | 0.5  | 1.5  | 3.0  | V    |
| Bootstrap Boost Voltage                                               | V <sub>CX</sub>    | w.r.t. V <sub>BRG</sub> , Boot capacitor fully charged                                                                                                 | 7.9  | 9.1  | 11   | V    |
|                                                                       |                    | w.r.t. V <sub>BRG</sub> , I <sub>CA</sub> = I <sub>CB</sub> = I <sub>CC</sub> = 3 mA (9 mA total), 11 V ≤ V <sub>REG</sub> ≤ 14.4 V                    | 7.4  | 8.6  | 10.5 | V    |
| Bootstrap Diode Forward Voltage                                       | V <sub>fBOOT</sub> | I <sub>D</sub> = 10 mA                                                                                                                                 | 0.4  | 0.7  | 1.0  | V    |
|                                                                       |                    | I <sub>D</sub> = 100 mA                                                                                                                                | 1.4  | 2.2  | 2.8  | V    |
| Bootstrap Diode Resistance                                            | r <sub>D</sub>     | r <sub>D(100 mA)</sub> = (V <sub>fBOOT(150 mA)</sub> – V <sub>fBOOT(50 mA)</sub> ) / 100 mA                                                            | 5    | 11   | 22   | Ω    |
| Bootstrap Diode Current Limit                                         | I <sub>DBOOT</sub> |                                                                                                                                                        | 250  | 500  | 750  | mA   |
| High-Side Gate Drive Static Load Resistance                           | R <sub>GSH</sub>   |                                                                                                                                                        | 100  | –    | –    | kΩ   |
| Start-Up Time, Buck Regulator Active <sup>[8]</sup>                   | t <sub>INIT</sub>  | V <sub>BB</sub> > 10 V to gate drives enabled, C <sub>REG</sub> ≤ 10 μF, V <sub>RESETn</sub> > V <sub>IH</sub> , V <sub>BRG</sub> > V <sub>BRGUV</sub> | –    | –    | 3    | ms   |
| Start-Up Time, Buck Regulator Inactive <sup>[8]</sup>                 | t <sub>INIT</sub>  | V <sub>REG</sub> > 10 V to gate drives enabled, V <sub>RESETn</sub> > V <sub>IH</sub> , V <sub>BRG</sub> > V <sub>BRGUV</sub>                          | –    | –    | 3    | ms   |
| System Clock Period                                                   | t <sub>OSC</sub>   |                                                                                                                                                        | 45   | 50   | 55   | ns   |

Continued on the next page...

## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80\text{ V}$ , unless otherwise specified

| Characteristic                                       | Symbol         | Test Conditions                                                                                | Min.  | Typ. | Max. | Unit     |
|------------------------------------------------------|----------------|------------------------------------------------------------------------------------------------|-------|------|------|----------|
| <b>NVM – PROGRAMMING PARAMETERS</b>                  |                |                                                                                                |       |      |      |          |
| Programming Voltage Applied To VBRG When Programming | $V_{PP}$       | $V_{PU} = 0$                                                                                   | 24    | –    | –    | V        |
|                                                      |                | $V_{PU} = 1$                                                                                   | 40    | –    | –    | V        |
| Programming Supply Setup Time                        | $t_{PRS}$      | $V_{PP} > V_{PPMIN}$ to start of NVM write                                                     | 10    | –    | –    | ms       |
| Number of Write Cycles [8]                           | $N_{WC}$       | $T_J \leq 85^{\circ}\text{C}$                                                                  | –     | –    | 400  | –        |
| <b>GATE OUTPUT DRIVE</b>                             |                |                                                                                                |       |      |      |          |
| Turn-On Time (High-Side)                             | $t_{r(HS)}$    | $C_{LOAD} = 30\text{ nF}$ , $2\text{ V}$ to $8\text{ V}$ , $V_{CX} - V_{SX} = 11\text{ V}$     | 110   | –    | 454  | ns       |
| Turn-On Time (Low-Side)                              | $t_{r(LS)}$    | $C_{LOAD} = 30\text{ nF}$ , $2\text{ V}$ to $8\text{ V}$ , $V_{VREG} - V_{LSSx} = 11\text{ V}$ | 110   | –    | 454  | ns       |
| Turn-Off Time (High-Side)                            | $t_{f(HS)}$    | $C_{LOAD} = 30\text{ nF}$ , $8\text{ V}$ to $2\text{ V}$ , $V_{CX} - V_{SX} = 11\text{ V}$     | 47    | –    | 250  | ns       |
| Turn-Off Time (Low-Side)                             | $t_{f(LS)}$    | $C_{LOAD} = 30\text{ nF}$ , $8\text{ V}$ to $2\text{ V}$ , $V_{VREG} - V_{LSSx} = 11\text{ V}$ | 47    | –    | 250  | ns       |
| Pull-Up On-Resistance                                | $R_{DS(on)UP}$ | $T_J = 25^{\circ}\text{C}$ , $I_{GH} = -150\text{ mA}$ [2]                                     | 2.5   | –    | 8    | $\Omega$ |
|                                                      |                | $T_J = 150^{\circ}\text{C}$ , $I_{GH} = -150\text{ mA}$ [2]                                    | 4     | –    | 11.9 | $\Omega$ |
| Pull-Up Peak Source Current (High-Side) [2]          | $I_{PUPK(HS)}$ | $V_{CX} - V_{SX} = 11\text{ V}$                                                                | –2400 | –    | –600 | mA       |
| Pull-Up Peak Source Current (Low-Side) [2]           | $I_{PUPK(LS)}$ | $V_{VREG} - V_{LSSx} = 11\text{ V}$                                                            | –2400 | –    | –600 | mA       |
| Pull-Down On-Resistance                              | $R_{DS(on)DN}$ | $T_J = 25^{\circ}\text{C}$ , $I_{GL} = 150\text{ mA}$ [2]                                      | 0.6   | –    | 1.9  | $\Omega$ |
|                                                      |                | $T_J = 150^{\circ}\text{C}$ , $I_{GL} = 150\text{ mA}$ [2]                                     | 0.9   | –    | 2.7  | $\Omega$ |
| Pull-Down Peak Sink Current (High-Side) [2]          | $I_{PDPK(HS)}$ | $V_{CX} - V_{SX} = 11\text{ V}$                                                                | 1100  | –    | 4200 | mA       |
| Pull-Down Peak Sink Current (Low-Wide) [2]           | $I_{PDPK(LS)}$ | $V_{VREG} - V_{LSSx} = 11\text{ V}$                                                            | 1100  | –    | 4200 | mA       |
| High-Side Minimum Turn-On Time                       | $t_{HRM}$      | $THR = 0$                                                                                      | 42    | 55   | 65   | ns       |
| High-Side Turn-On Time Mean Step Size                | $t_{HRS}$      | $THR > 0$                                                                                      | 12    | 16   | 20   | ns       |
| High-Side Turn-On Current 1                          | $I_{HR1}$      | $V_{GS} = 0\text{ V}$ , $I_{HR1} = 15$                                                         | –1050 | –240 | –160 | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | –240  | –    | –16  | mA       |
| High-Side Turn-On Current 2                          | $I_{HR2}$      | $V_{GS} = 0\text{ V}$ , $I_{HR2} = 15$                                                         | –1050 | –240 | –160 | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | –240  | –    | –16  | mA       |
| High-Side Minimum Turn-Off Time                      | $t_{HFM}$      | $THF = 0$                                                                                      | 42    | 55   | 65   | ns       |
| High-Side Turn-Off Time Mean Step Size               | $t_{HFS}$      | $THF > 0$                                                                                      | 12    | 16   | 20   | ns       |
| High-Side Turn-Off Current 1                         | $I_{HF1}$      | $V_{GS} = 9\text{ V}$ , $I_{HF1} = 15$                                                         | 160   | 240  | 320  | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | 16    | –    | 240  | mA       |
| High-Side Turn-Off Current 2                         | $I_{HF2}$      | $V_{GS} = 9\text{ V}$ , $I_{HF2} = 15$                                                         | 160   | 240  | 320  | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | 16    | –    | 240  | mA       |
| Low-Side Minimum Turn-On Time                        | $t_{LRM}$      | $TLR = 0$                                                                                      | 42    | 55   | 65   | ns       |
| Low-Side Turn-On Time Mean Step Size                 | $t_{LRS}$      | $TLR > 0$                                                                                      | 12    | 16   | 20   | ns       |
| Low-Side Turn-On Current 1                           | $I_{LR1}$      | $V_{GS} = 0\text{ V}$ , $I_{LR1} = 15$                                                         | –1050 | –240 | –160 | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | –240  | –    | –16  | mA       |
| Low-Side Turn-On Current 2                           | $I_{LR2}$      | $V_{GS} = 0\text{ V}$ , $I_{LR2} = 15$                                                         | –1050 | –240 | –160 | mA       |
|                                                      |                | Programmable range $DT[6:0] > 0$                                                               | –240  | –    | –16  | mA       |
| Low-Side Minimum Turn-Off Time                       | $t_{LFM}$      | $TLF = 0$                                                                                      | 42    | 55   | 65   | ns       |

Continued on the next page...

## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80\text{ V}$ , unless otherwise specified

| Characteristic                              | Symbol          | Test Conditions                                                                                   | Min.             | Typ. | Max.               | Unit          |
|---------------------------------------------|-----------------|---------------------------------------------------------------------------------------------------|------------------|------|--------------------|---------------|
| <b>GATE OUTPUT DRIVE (continued)</b>        |                 |                                                                                                   |                  |      |                    |               |
| Low-Side Turn-Off Time<br>Mean Step Size    | $t_{LFS}$       | $TLF > 0$                                                                                         | 12               | 16   | 20                 | ns            |
| Low-Side Turn-Off Current 1                 | $I_{LF1}$       | $V_{GS} = 9\text{ V}$ , $ILF1 = 15$                                                               | 160              | 240  | 320                | mA            |
|                                             |                 | Programmable range $DT[6:0] > 0$                                                                  | 16               | —    | 240                | mA            |
| Low-Side Turn-Off Current 2                 | $I_{LF2}$       | $V_{GS} = 9\text{ V}$ , $ILF2 = 15$                                                               | 160              | 240  | 320                | mA            |
|                                             |                 | Programmable range $DT[6:0] > 0$                                                                  | 16               | —    | 240                | mA            |
| GHx Output Voltage High                     | $V_{GHH}$       | Bootstrap capacitor fully charged                                                                 | $V_{C_X} - 0.02$ | —    | —                  | V             |
| GHx Output Voltage Low                      | $V_{GHL}$       | $-10\text{ }\mu\text{A} < I_{GH} < 10\text{ }\mu\text{A}$                                         | —                | —    | $V_{S_X} + 0.02$   | V             |
| GLx Output Voltage High                     | $V_{GLH}$       |                                                                                                   | $V_{REG} - 0.02$ | —    | —                  | V             |
| GLx Output Voltage Low                      | $V_{GLL}$       | $-10\text{ }\mu\text{A} < I_{GL} < 10\text{ }\mu\text{A}$                                         | —                | —    | $V_{LSS_X} + 0.02$ | V             |
| Gate-Source Voltage, MOSFET On              | $V_{GSon}$      | No faults present                                                                                 | $V_{ROFF}$       | —    | $V_{REG}$          | V             |
| GHx Passive Pull-Down                       | $R_{GHPD}$      | $V_{BB} = 0\text{ V}$ , $V_{GH_X} - V_{S_X} = 0.1\text{ V}$                                       | 0.25             | —    | 2                  | M $\Omega$    |
|                                             |                 | $V_{BB} = 0\text{ V}$ , $I_{GH_X} = 500\text{ }\mu\text{A}$                                       | 0.5              | —    | 10                 | k $\Omega$    |
| GLx Passive Pull-Down                       | $R_{GLPD}$      | $V_{BB} = 0\text{ V}$ , $V_{GL_X} - V_{LSS_X} = 0.1\text{ V}$                                     | 0.25             | —    | 2                  | M $\Omega$    |
|                                             |                 | $V_{BB} = 0\text{ V}$ , $I_{GL_X} = 500\text{ }\mu\text{A}$                                       | 0.5              | —    | 10                 | k $\Omega$    |
| GHx Active Pull-Down                        | $R_{GHPA}$      | $V(C_X - S_X) > 4\text{ V}$                                                                       | 0.3              | —    | 20                 | $\Omega$      |
| GLx Active Pull-Down                        | $R_{GLPA}$      | $V(V_{REG} - LSS_X) > 4\text{ V}$                                                                 | 0.3              | —    | 20                 | $\Omega$      |
| Turn-Off Propagation Delay <sup>[6]</sup>   | $t_{P(off)}$    | Phase input change to unloaded gate output change (see Figure 4); $DT[6:0] = 0$                   | —                | —    | 73                 | ns            |
|                                             |                 | Phase input change to unloaded gate output change, excluding jitter (see Figure 4); $DT[6:0] > 0$ | —                | —    | 148                | ns            |
| Turn-On Propagation Delay <sup>[6]</sup>    | $t_{P(on)}$     | Phase input change to unloaded gate output change (see Figure 4); $DT[6:0] = 0$                   | —                | —    | 58                 | ns            |
|                                             |                 | Phase input change to unloaded gate output change, excluding jitter (see Figure 4); $DT[6:0] > 0$ | —                | —    | 133                | ns            |
| Propagation Delay Matching (Phase-to-Phase) | $\Delta t_{PP}$ | Same state change, $DT[6:0] = 0$                                                                  | —                | —    | 15                 | ns            |
| Propagation Delay Matching (On-to-Off)      | $\Delta t_{OO}$ | Single phase, $DT[6:0] = 0$                                                                       | —                | —    | 22                 | ns            |
| Propagation Delay Matching (GHx-to-GLx)     | $\Delta t_{HL}$ | Same state change, $DT[6:0] = 0$                                                                  | —                | —    | 17                 | ns            |
| Dead Time (Turn-Off to Turn-On Delay)       | $t_{DEAD}$      | Default power-up state (see Figure 4)                                                             | 1.35             | 1.6  | 1.85               | $\mu\text{s}$ |
|                                             |                 | Programmable range                                                                                | 0.1              | —    | 6.35               | $\mu\text{s}$ |
| Phase Output Leakage Current                | $I_{S_X}$       | CPM1 = 1, CPM0 = 1                                                                                | –500             | —    | 500                | $\mu\text{A}$ |

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## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80\text{ V}$ , unless otherwise specified

| Characteristic                                              | Symbol     | Test Conditions                                                                         | Min.                | Typ.           | Max.                | Unit          |
|-------------------------------------------------------------|------------|-----------------------------------------------------------------------------------------|---------------------|----------------|---------------------|---------------|
| <b>LOGIC INPUTS &amp; OUTPUTS</b>                           |            |                                                                                         |                     |                |                     |               |
| Input Low Voltage                                           | $V_{IL}$   | Except RESETn                                                                           | –                   | –              | $0.3 \times V_{IO}$ | V             |
| Input High Voltage                                          | $V_{IH}$   | Except RESETn                                                                           | $0.7 \times V_{IO}$ | –              | –                   | V             |
| Input Hysteresis                                            | $V_{Ihys}$ | Except RESETn                                                                           | 200                 | 550            | 800                 | mV            |
| Input Low Voltage                                           | $V_{IL}$   | RESETn                                                                                  | –                   | –              | 0.8                 | V             |
| Input High Voltage                                          | $V_{IH}$   | RESETn                                                                                  | 2.4                 | –              | –                   | V             |
| Input Hysteresis                                            | $V_{Ihys}$ | RESETn                                                                                  | 200                 | 400            | 600                 | mV            |
| Input Pull-Down ENABLE, RESETn                              | $R_{PD}$   | $0\text{ V} < V_{IN} < V_{IO}$                                                          | 25                  | 50             | 85                  | k $\Omega$    |
|                                                             | $I_{PD}$   | $V_{IO} < V_{IN} < 80\text{ V}$                                                         | 40                  | 100            | 200                 | $\mu\text{A}$ |
| Input Pull-Down HA, HB, HC                                  | $R_{PD}$   | $HSI = 0, 0\text{ V} \leq V_{IN} \leq V_{IO}$                                           | 30                  | 50             | 77                  | k $\Omega$    |
|                                                             | $I_{PD}$   | $V_{IO} < V_{IN} < 80\text{ V}$                                                         | 40                  | –              | 800                 | $\mu\text{A}$ |
| Input Pull-Down LA, LB, LC                                  | $R_{PD}$   | $LSI = 0, 0\text{ V} \leq V_{IN} \leq V_{IO}$                                           | 30                  | 50             | 77                  | k $\Omega$    |
|                                                             | $I_{PD}$   | $V_{IO} < V_{IN} < 80\text{ V}$                                                         | 40                  | –              | 800                 | $\mu\text{A}$ |
| Input Pull-Up HA, HB, HC                                    | $R_{PU}$   | $HSI = 0, 0\text{ V} \leq V_{IN} \leq 0.7 \times V_{IO}$                                | 30                  | 50             | 77                  | k $\Omega$    |
|                                                             | $I_{PD}$   | $0.7 \times V_{IO} < V_{IN} < 80\text{ V}$                                              | –50                 | –              | 800                 | $\mu\text{A}$ |
| Input Pull-Up LA, LB, LC                                    | $R_{PU}$   | $LSI = 0, 0\text{ V} \leq V_{IN} \leq 0.7 \times V_{IO}$                                | 30                  | 50             | 77                  | k $\Omega$    |
|                                                             | $I_{PD}$   | $0.7 \times V_{IO} < V_{IN} < 80\text{ V}$                                              | –50                 | –              | 800                 | $\mu\text{A}$ |
| Input Pull-Down SDI, SCK                                    | $R_{PDS}$  | $0\text{ V} < V_{IN} < V_{IO}$                                                          | 30                  | 50             | 77                  | k $\Omega$    |
| Input Pull-Up STRn (to $V_{IO}$ )                           | $R_{PUS}$  |                                                                                         | 30                  | 50             | 77                  | k $\Omega$    |
| Output Low Voltage                                          | $V_{OL}$   | $I_{OL} = 1\text{ mA}$                                                                  | –                   | 0.2            | 0.4                 | V             |
| Output High Voltage                                         | $V_{OH}$   | $I_{OL} = -1\text{ mA}^{[2]}$                                                           | $V_{IO} - 0.4$      | $V_{IO} - 0.2$ | –                   | V             |
| Output Leakage SDO <sup>[2]</sup>                           | $I_{OSD}$  | $0\text{ V} < V_{SDO} < V_{IO}, \text{STRn} = 1$                                        | –1                  | –              | 1                   | $\mu\text{A}$ |
| Output Leakage DIAG <sup>[2]</sup>                          | $I_{ODI}$  | $0\text{ V} < V_{DIAG} < V_{IO}, \text{DG}[1:0] = 0$                                    | –                   | –              | 1                   | $\mu\text{A}$ |
| <b>LOGIC I/O – DYNAMIC PARAMETERS</b>                       |            |                                                                                         |                     |                |                     |               |
| Reset Pulse Width                                           | $t_{RST}$  |                                                                                         | 1                   | –              | 4.5                 | $\mu\text{s}$ |
| Reset Shutdown Time, Buck Regulator Active <sup>[8]</sup>   | $t_{RSD}$  | $V_{RESETn} \leq 300\text{ mV}$ to regulator switching stopped and gate drives disabled | 5                   | –              | 20                  | $\mu\text{s}$ |
| Reset Shutdown Time, Buck Regulator Inactive <sup>[8]</sup> | $t_{RSD}$  | $V_{RESETn} \leq 300\text{ mV}$ to gate drives disabled                                 | 5                   | –              | 20                  | $\mu\text{s}$ |
| Clock High Time                                             | $t_{SCKH}$ | A in Figure 3                                                                           | 50                  | –              | –                   | ns            |
| Clock Low Time                                              | $t_{SCKL}$ | B in Figure 3                                                                           | 50                  | –              | –                   | ns            |
| Strobe Lead Time                                            | $t_{STLD}$ | C in Figure 3                                                                           | 100                 | –              | –                   | ns            |
| Strobe Lag Time                                             | $t_{STLG}$ | D in Figure 3                                                                           | 30                  | –              | –                   | ns            |
| Strobe High Time                                            | $t_{STRH}$ | E in Figure 3                                                                           | 350                 | –              | –                   | ns            |
| Data Out Enable Time                                        | $t_{SDOE}$ | F in Figure 3; $C_{LOAD} = 10\text{ pF}$                                                | –                   | –              | 40                  | ns            |
| Data Out Disable Time                                       | $t_{SDOD}$ | G in Figure 3                                                                           | –                   | –              | 30                  | ns            |
| Data Out Valid Time From Clock Falling                      | $t_{SDOV}$ | H in Figure 3; $C_{LOAD} = 10\text{ pF}$                                                | –                   | –              | 40                  | ns            |
| Data Out Hold Time From Clock Falling                       | $t_{SDOH}$ | I in Figure 3                                                                           | 5                   | –              | –                   | ns            |
| Data In Setup Time To Clock Rising                          | $t_{SDIS}$ | J in Figure 3                                                                           | 15                  | –              | –                   | ns            |
| Data In Hold Time From Clock Rising                         | $t_{SDIH}$ | K in Figure 3                                                                           | 10                  | –              | –                   | ns            |

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## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80$ V, unless otherwise specified

| Characteristic                                  | Symbol           | Test Conditions                                                                     | Min. | Typ.     | Max. | Unit                           |
|-------------------------------------------------|------------------|-------------------------------------------------------------------------------------|------|----------|------|--------------------------------|
| <b>CURRENT SENSE AMPLIFIERS</b>                 |                  |                                                                                     |      |          |      |                                |
| Input Offset Voltage                            | $V_{IOS}$        | After $V_{IOS}$ calibration                                                         | -1   | -        | +1   | mV                             |
| Input Offset Voltage Drift Over Temperature     | $\Delta V_{IOS}$ |                                                                                     | -2   | -        | +2   | $\mu\text{V}/^{\circ}\text{C}$ |
| Input Bias Current <sup>[2]</sup>               | $I_{BIAS}$       | $V_{ID} = 0$ V, $V_{CM}$ in range                                                   | -100 | -35      | -5   | $\mu\text{A}$                  |
| Input Offset Current <sup>[2]</sup>             | $I_{OS}$         | $V_{ID} = 0$ V, $V_{CM}$ in range                                                   | -1.5 | -        | 1.5  | $\mu\text{A}$                  |
| Input Common-Mode Range (DC)                    | $V_{CM}$         | $V_{ID} = 0$ V                                                                      | -1.5 | -        | 2    | V                              |
| Gain                                            | $A_V$            | Default power-up value                                                              | -    | 20       | -    | V/V                            |
| Gain Error                                      | $E_A$            | $V_{CM}$ in range                                                                   | -1.6 | -        | 1.6  | %                              |
| Gain Drift Over Temperature                     | $E_{AD}$         | $V_{CM}$ in range                                                                   | -50  | -        | 50   | ppm/ $^{\circ}\text{C}$        |
| Output Offset                                   | $V_{OOS}$        | Default power-up value                                                              | -    | 2.5      | -    | V                              |
| Output Offset Error                             | $E_{VO}$         | $V_{CM}$ in range, $V_{OOS} > 0$ V                                                  | -75  | $\pm 25$ | 75   | mV                             |
| Output Offset Drift                             | $V_{OOSD}$       | $V_{CM}$ in range, $V_{OOS} > 0$ V                                                  | -135 | -        | 135  | $\mu\text{V}/^{\circ}\text{C}$ |
| Small Signal -3 dB Bandwidth <sup>[8]</sup>     | BW               | Gain = 20 V/V, $V_{IN} = 10$ mVpp                                                   | 1    | -        | -    | MHz                            |
| Output Settling Time (to within 40 mV)          | $t_{SET}$        | $V_{CSO} = 1$ Vpp square wave, Gain = 20 V/V, $C_{OUT} = 50$ pF                     | 0.2  | -        | 1    | $\mu\text{s}$                  |
| Output Dynamic Range                            | $V_{CSOUT}$      | $V_{CL} = 0$ , $-100 \mu\text{A} < I_{CSO} < 100 \mu\text{A}$ <sup>[2]</sup>        | 0.3  | -        | 3.1  | V                              |
|                                                 |                  | $V_{CL} = 1$ , $-100 \mu\text{A} < I_{CSO} < 100 \mu\text{A}$ <sup>[2]</sup>        | 0.3  | -        | 4.8  | V                              |
| Output Voltage Clamp                            | $V_{CSC}$        | $V_{CL} = 0$ , $I_{CSO} = -2$ mA <sup>[2]</sup>                                     | 3.2  | 3.5      | 3.9  | V                              |
|                                                 |                  | $V_{CL} = 1$ , $I_{CSO} = -2$ mA <sup>[2]</sup>                                     | 4.9  | 5.2      | 5.6  | V                              |
| Output Voltage Clamp Current <sup>[2]</sup>     | $I_{CSC}$        | $V_{CSOUT(MAX)} < V_{CSOUT} < V_{CSC}$                                              | -10  | -        | -    | mA                             |
| Output Current Sink <sup>[2]</sup>              | $I_{CSsink}$     | $V_{ID} = 0$ V, $V_{CSO} = 1.5$ V, Gain = 20 V/V                                    | 230  | -        | 480  | $\mu\text{A}$                  |
| Output Current Sink (Boosted) <sup>[2][7]</sup> | $I_{CSsinkb}$    | $V_{OOS} = 1.5$ V, $V_{ID} = -50$ mV, Gain = 20 V/V, $V_{CSO} = 1.5$ V              | 1.9  | -        | 4.4  | mA                             |
| Output Current Source <sup>[2]</sup>            | $I_{CSsource}$   | $V_{CL} = 1$ , $V_{OOS} = 0$ V, $V_{ID} = 200$ mV, Gain = 20 V/V, $V_{CSO} = 1.5$ V | -5   | -        | -1.2 | mA                             |
| VBB Supply Ripple Rejection                     | PSRR             | $V_{ID} = 0$ V, 100 kHz, Gain = 20 V/V                                              | -    | 75       | -    | dB                             |
|                                                 |                  | $V_{CSP} = V_{CSM} = 0$ V, DC, Gain = 20 V/V                                        | 75   | -        | -    | dB                             |
| DC Common-Mode Rejection                        | CMRR             | $V_{CM}$ step from 0 to 200 mV, Gain = 20 V/V                                       | 52   | 100      | -    | dB                             |
| AC Common-Mode Rejection                        | CMRR             | $V_{CM} = 200$ mVpp, 100 kHz, Gain = 20 V/V                                         | -    | 62       | -    | dB                             |
|                                                 |                  | $V_{CM} = 200$ mVpp, 1 MHz, Gain = 20 V/V                                           | -    | 43       | -    | dB                             |
|                                                 |                  | $V_{CM} = 200$ mVpp, 10 MHz, Gain = 20 V/V                                          | -    | 25       | -    | dB                             |
| Common-Mode Recovery Time (to within 100 mV)    | $t_{CMrec}$      | $V_{CM}$ step from -4 V to +1 V, Gain = 20 V/V, $C_{OUT} = 50$ pF                   | -    | -        | 2.1  | $\mu\text{s}$                  |
| Output Slew Rate 10% to 90%                     | SR               | $V_{ID}$ step from 0 V to 175 mV, Gain = 20 V/V, $C_{OUT} = 50$ pF                  | 1.8  | -        | 5    | V/ $\mu\text{s}$               |
| Input Overload Recovery (to within 40 mV)       | $t_{IDrec}$      | $V_{ID}$ step from 250 mV to 0 V, Gain = 20 V/V, $C_{OUT} = 50$ pF                  | 0.4  | -        | 2.3  | $\mu\text{s}$                  |
| Offset Calibration Time                         | $t_{Cal}$        | From STRn rising edge                                                               | -    | -        | 100  | $\mu\text{s}$                  |

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## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80\text{ V}$ , unless otherwise specified

| Characteristic                       | Symbol         | Test Conditions                                                                         | Min.              | Typ.             | Max.             | Unit          |
|--------------------------------------|----------------|-----------------------------------------------------------------------------------------|-------------------|------------------|------------------|---------------|
| <b>DIAGNOSTICS AND PROTECTION</b>    |                |                                                                                         |                   |                  |                  |               |
| VREG Undervoltage                    | $V_{RON}$      | $V_{REG}$ rising                                                                        | 7.7               | 8.0              | 8.3              | V             |
|                                      | $V_{ROFF}$     | $V_{REG}$ falling                                                                       | 7.0               | 7.25             | 7.5              | V             |
| VREG Overvoltage Warning             | $V_{ROV}$      | $V_{REG}$ rising                                                                        | 14.8              | 15.4             | 16.1             | V             |
| VREG Overvoltage Hysteresis          | $V_{ROVHys}$   |                                                                                         | 1100              | 1400             | 1620             | mV            |
| VBRG Overvoltage Warning             | $V_{BRGOV}$    | $V_{PO} = 0$ , $V_{BRG}$ rising                                                         | 52                | 54               | 58               | V             |
|                                      |                | $V_{PO} = 1$ , $V_{BRG}$ rising                                                         | 57                | 60               | 63               | V             |
| VBRG Overvoltage Hysteresis          | $V_{BRGOVHys}$ |                                                                                         | 2.2               | 2.8              | 3.8              | V             |
| VBRG Undervoltage                    | $V_{BRGUV}$    | $V_{PU} = 0$ , $V_{BRG}$ falling                                                        | 18                | 19               | 20               | V             |
|                                      |                | $V_{PU} = 1$ , $V_{BRG}$ falling                                                        | 32                | 34               | 36               | V             |
| VBRG Undervoltage Hysteresis         | $V_{BRGUVHys}$ |                                                                                         | 1.3               | 1.6              | 2.1              | V             |
| VBB Undervoltage                     | $V_{BBON}$     | $V_{BB}$ rising                                                                         | 9.1               | 9.5              | 9.9              | V             |
|                                      | $V_{BBOFF}$    | $V_{BB}$ falling                                                                        | 8.1               | 8.5              | 8.9              | V             |
| Bootstrap Undervoltage               | $V_{BCON}$     | $V_{BOOT}$ rising, $V_{BOOT} = V_{Cx} - V_{Sx}$                                         | 6.3               | 7.1              | 8                | V             |
|                                      | $V_{BCOFF}$    | $V_{BOOT}$ falling, $V_{BOOT} = V_{Cx} - V_{Sx}$                                        | 5.6               | 6.4              | 7.4              | V             |
| Gate Drive Off Overvoltage Threshold | $V_{GSOV}$     | High-side                                                                               | $V_{Sx} + 1.05$   | $V_{Sx} + 1.2$   | $V_{Sx} + 1.4$   | V             |
|                                      |                | Low-Side                                                                                | $V_{LSSx} + 1.05$ | $V_{LSSx} + 1.2$ | $V_{LSSx} + 1.4$ | V             |
| Gate Drive On Undervoltage Threshold | $V_{GSUV}$     | High-side                                                                               | $V_{Cx} - 1.15$   | $V_{Cx} - 1.0$   | $V_{Cx} - 0.85$  | V             |
|                                      |                | Low-Side                                                                                | $V_{REG} - 1.15$  | $V_{REG} - 1.0$  | $V_{REG} - 0.85$ | V             |
| VIO Undervoltage Threshold           | $V_{IOON}$     | $V_{IO} = 0$ , $V_{IO}$ rising                                                          | 2.7               | 2.9              | 3.1              | V             |
|                                      | $V_{IOOFF}$    | $V_{IO} = 0$ , $V_{IO}$ falling                                                         | 2.4               | 2.6              | 2.8              | V             |
|                                      | $V_{IOON}$     | $V_{IO} = 1$ , $V_{IO}$ rising                                                          | 4.3               | 4.5              | 4.7              | V             |
|                                      | $V_{IOOFF}$    | $V_{IO} = 1$ , $V_{IO}$ falling                                                         | 3.7               | 3.9              | 4.1              | V             |
| Logic Terminal Overvoltage Warning   | $V_{LOV}$      | Voltage rising on HA, LA, HB, LB, HC, LC, ENABLE, or DIAG                               | 6.5               | –                | 9.5              | V             |
| ENABLE Input Timeout                 | $t_{ETO}$      |                                                                                         | 90                | 100              | 110              | ms            |
| VBRG Input Voltage                   | $V_{BRG}$      | When VDS monitor is active                                                              | 4.5               | $V_{BB}$         | 80               | V             |
| VDS Threshold – High-Side            | $V_{DSTH}$     | Default power-up value                                                                  | –                 | 1.2              | –                | V             |
|                                      |                | Programmable range, $5\text{ V} \leq V_{BRG} \leq 80\text{ V}$                          | 0                 | –                | 3.15             | V             |
|                                      |                | Programmable range, $4.5\text{ V} < V_{BRG} < 5\text{ V}$                               | 0                 | –                | 2.5              | V             |
| High-Side VDS Threshold Offset [3]   | $V_{DSTHO}$    | High-side on, $V_{DSTH} \geq 1\text{ V}$ , $4.5\text{ V} \leq V_{BRG} \leq 80\text{ V}$ | –200              | $\pm 100$        | +200             | mV            |
|                                      |                | High-side on, $V_{DSTH} < 1\text{ V}$ , $4.5\text{ V} \leq V_{BRG} \leq 80\text{ V}$    | –150              | $\pm 50$         | +150             | mV            |
| VDS Threshold – Low-Side             | $V_{DSTL}$     | Default power-up value                                                                  | –                 | 1.2              | –                | V             |
|                                      |                | Programmable range                                                                      | 0                 | –                | 3.15             | V             |
| Low-Side VDS Threshold Offset [3]    | $V_{DSTLO}$    | Low side on, $V_{DSTL} \geq 1\text{ V}$ , $4.5\text{ V} \leq V_{BRG} \leq 80\text{ V}$  | –200              | $\pm 100$        | +200             | mV            |
|                                      |                | Low side on, $V_{DSTL} < 1\text{ V}$ , $4.5\text{ V} \leq V_{BRG} \leq 80\text{ V}$     | –150              | $\pm 50$         | +150             | mV            |
| VDS and VGS Fault Qualification Time | $t_{VDQ}$      | Default power-up value (Figure 7)                                                       | 1.46              | 1.7              | 1.91             | $\mu\text{s}$ |
|                                      |                | Programmable range                                                                      | 0                 | –                | 6.3              | $\mu\text{s}$ |

Continued on the next page...

## ELECTRICAL CHARACTERISTICS (continued): Valid at $T_J = -40^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , $V_{BB} = 10$ to $80\text{ V}$ , unless otherwise specified

| Characteristic                                | Symbol       | Test Conditions                                                                       | Min.   | Typ.  | Max. | Unit                   |
|-----------------------------------------------|--------------|---------------------------------------------------------------------------------------|--------|-------|------|------------------------|
| <b>DIAGNOSTICS AND PROTECTION (continued)</b> |              |                                                                                       |        |       |      |                        |
| Phase Comparator Threshold                    | $V_{PT}$     | Phase voltage rising, $4.5\text{ V} < V_{BRG} < 80\text{ V}$ , Default power-up value | 48     | 50    | 52.5 | $\%V_{BRG}$            |
|                                               |              | Programmable range                                                                    | 0      | –     | 98.4 | $\%V_{BRG}$            |
| Overcurrent Threshold Voltage                 | $V_{OCT}$    | Default power-up value                                                                | 0.8    | 0.9   | 1.08 | V                      |
|                                               |              | Programmable range                                                                    | 0.3    | –     | 4.8  | V                      |
| Overcurrent Qualify Time                      | $t_{OCQ}$    | Default power-up value                                                                | 6.7    | 7.5   | 8.3  | $\mu\text{s}$          |
|                                               |              | Programmable range                                                                    | 0      | –     | 15.5 | $\mu\text{s}$          |
| On-State Open-Load Threshold Voltage          | $V_{OLTH}$   | Default power-up value                                                                | 90     | 200   | 260  | mV                     |
|                                               |              | Programmable range                                                                    | 0      | –     | 375  | mV                     |
| Off-State Test Sink Current                   | $I_{SD}$     | $V(Sx) = 3\text{ V}$                                                                  | 1.25   | 2.5   | 3.75 | mA                     |
| Off-State Test Source Current <sup>[2]</sup>  | $I_{SU}$     | $YSC = 0, V(Sx) = 1\text{ V}$                                                         | –120   | –90   | –50  | $\mu\text{A}$          |
|                                               |              | $YSC = 1, V(Sx) = 1\text{ V}$                                                         | –460   | –410  | –300 | $\mu\text{A}$          |
| On-State Open Load Timeout                    | $t_{OLTO}$   |                                                                                       | 85     | 100   | 115  | ms                     |
| LSS Open Threshold (Rising)                   | $V_{LSO}$    |                                                                                       | 4.5    | 5     | 5.5  | V                      |
| LSS Open Threshold Hysteresis                 | $V_{LSOHys}$ |                                                                                       | 420    | 500   | 620  | mV                     |
| LSS Current                                   | $I_{LU}$     | $V(LSSx) = 5\text{ V}, V_{TL} = 1.2\text{ V}$                                         | –165   | –130  | –80  | $\mu\text{A}$          |
| Current Sense Amplifier Input Open Threshold  | $V_{SAD}$    |                                                                                       | 1.9    | 2.2   | 2.5  | V                      |
| DIAG Output: Fault Pulse Period               | $t_{FP}$     | $DG[1:0] = 0, 1$                                                                      | 90     | 100   | 110  | ms                     |
| DIAG Output: Fault Pulse Duty Cycle           | $D_{FP}$     | $DG[1:0] = 0, 1$ : No Fault present                                                   | 80     |       |      | %                      |
|                                               |              | $DG[1:0] = 0, 1$ : Fault present                                                      | 20     |       |      | %                      |
| DIAG Output: Temperature Range                | $V_{TJD}$    | $DG[1:0] = 1, 0, T_J = 0^{\circ}\text{C}$                                             | –      | 1440  | –    | mV                     |
| DIAG Output: Temperature Slope                | $A_{TJD}$    | $DG[1:0] = 1, 0$                                                                      | –      | –3.92 | –    | mV/ $^{\circ}\text{C}$ |
| DIAG Output: Clock Division Ratio             | $N_D$        | $DG[1:0] = 1, 1$                                                                      | 256000 |       |      | –                      |
| Temperature Warning Threshold <sup>[9]</sup>  | $T_{JW}$     | Temperature increasing                                                                | 125    | 135   | 145  | $^{\circ}\text{C}$     |
| Temperature Warning Hysteresis <sup>[9]</sup> | $T_{JWhys}$  |                                                                                       | 13.8   | 15    | 20.6 | $^{\circ}\text{C}$     |
| Overtemperature Threshold <sup>[9]</sup>      | $T_{JF}$     | Temperature increasing                                                                | 165    | 175   | 185  | $^{\circ}\text{C}$     |
| Overtemperature Hysteresis <sup>[9]</sup>     | $T_{JFhys}$  | Recovery = $T_{JF} - T_{JFhys}$                                                       | 11.3   | 15    | 19.8 | $^{\circ}\text{C}$     |

[1] No internal reset.

[2] For input and output current specifications, negative current is defined as coming out of (being sourced by) the specified device terminal.

[3] VDS offset is the difference between the programmed threshold,  $V_{DSTH}$  or  $V_{DSTL}$  and the actual trip voltage.

[4]  $V_{DD}$  and  $V_{IO}$  derived from  $V_{BB}$  for internal use only. Not accessible on any device terminal.

[5] Confirmed by design. Not production tested.

[6] For  $DT[6:0] > 0$ , jitter of  $\pm 25\text{ ns}$  must be added to the limits shown.

[7] If the amplifier output voltage ( $V_{CSO}$ ) is more positive than the value demanded by the applied differential input ( $V_{ID}$ ) and output offset ( $V_{OOS}$ ) conditions, output current sink capability is boosted to enhance negative going transient response.

[8] Confirmed by characterization and design. Not production tested.

[9] Stated values confirmed by design and characterization (not production tested). Associated function production tested.

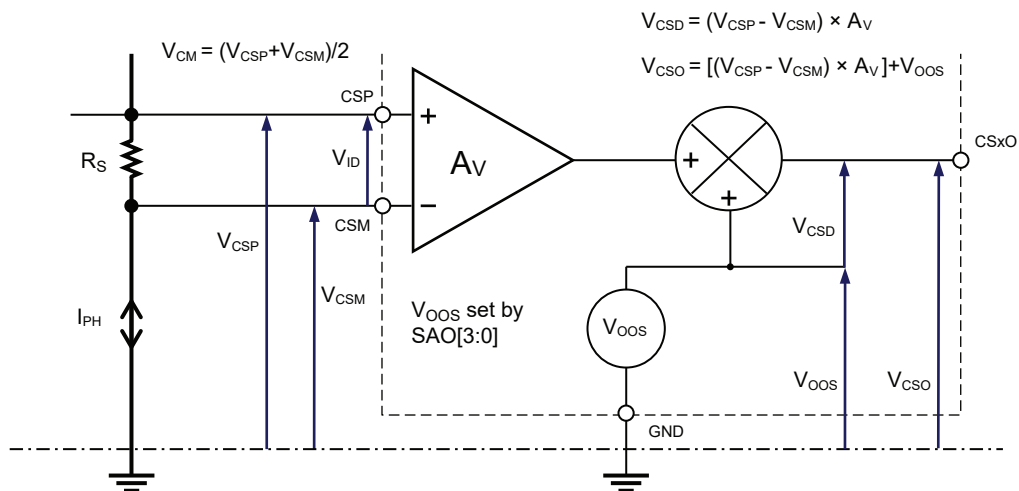
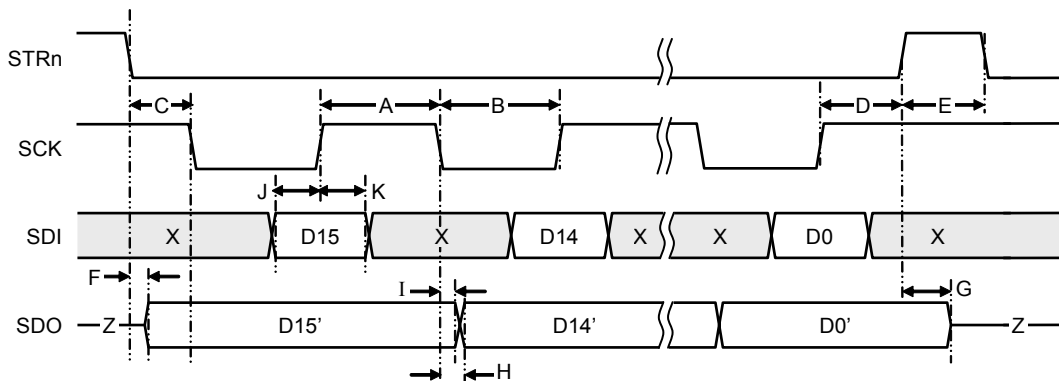


Figure 2: Sense Amplifier Voltage Definitions



X=don't care, Z=high impedance (tri-state)

Figure 3: Serial Interface Timing

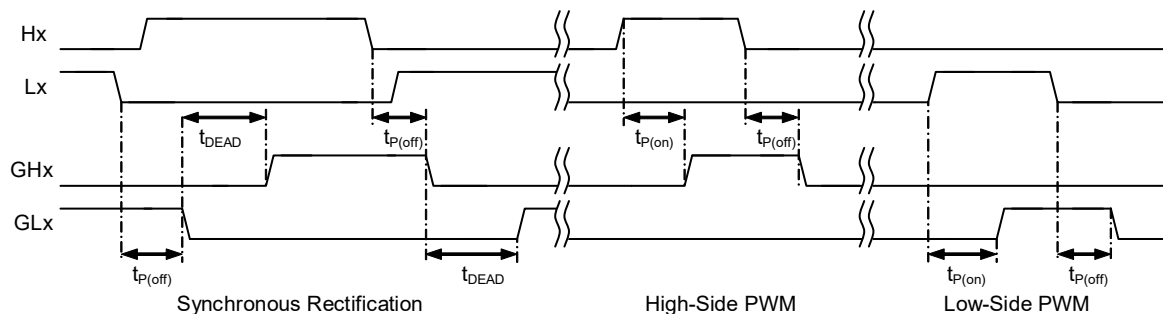
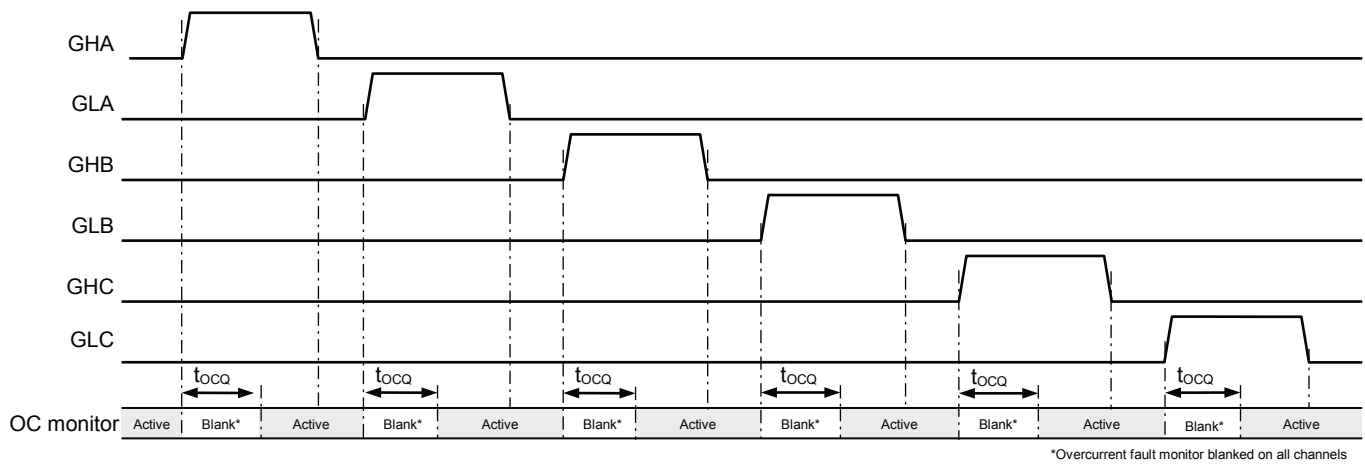
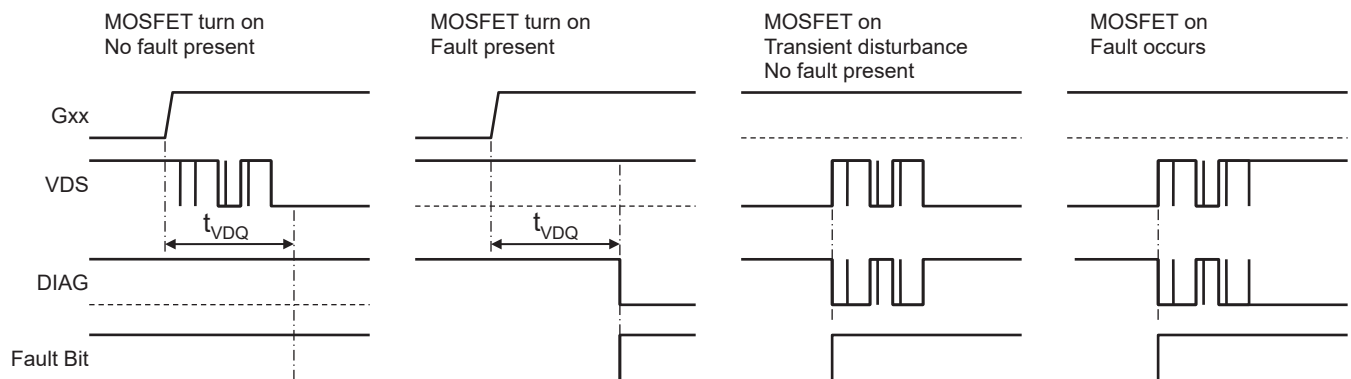


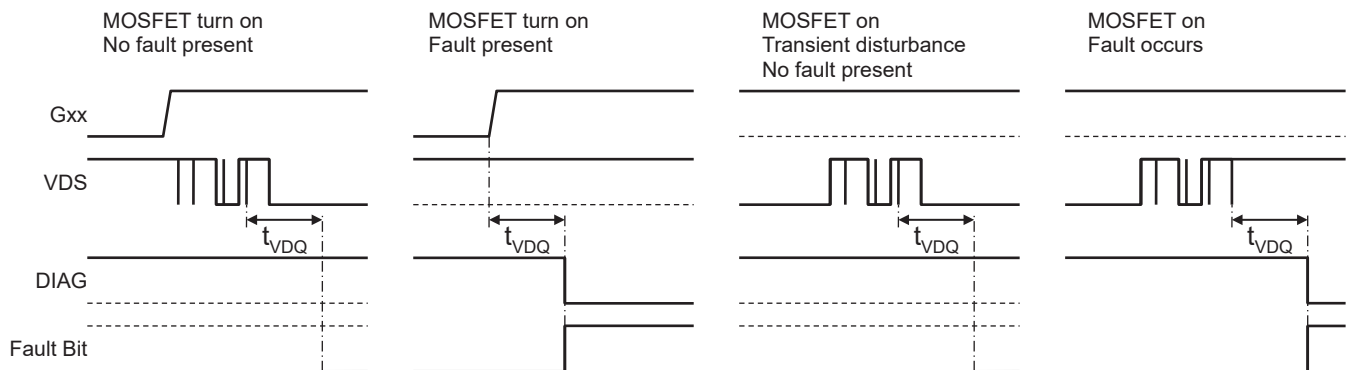
Figure 4: Gate Drive Timing, Phase Logic Control Inputs



**Figure 5: Overcurrent Fault Monitor – Blank Mode Timing (OCQ = 1)**



**Figure 6: VDS Fault Monitor – Blank Mode Timing (VDQ = 1)**



**Figure 7: VDS Fault Monitor – Debounce Mode Timing (VDQ = 0)**

## LOGIC TRUTH TABLES

Table 1: Control Logic – Logic Inputs

| Normal: HSI = 0, LSI = 0 |     |    |    |     |     |    |
|--------------------------|-----|----|----|-----|-----|----|
| HSI                      | LSI | Hx | Lx | GHx | GLx | Sx |
| 0                        | 0   | 0  | 0  | LO  | LO  | Z  |
| 0                        | 0   | 0  | 1  | LO  | HI  | LO |
| 0                        | 0   | 1  | 0  | HI  | LO  | HI |
| 0                        | 0   | 1  | 1  | LO  | LO  | Z  |

| High-Side Inverted: HSI = 1, LSI = 0 |     |    |    |     |     |    |
|--------------------------------------|-----|----|----|-----|-----|----|
| HSI                                  | LSI | Hx | Lx | GHx | GLx | Sx |
| 1                                    | 0   | 0  | 0  | HI  | LO  | HI |
| 1                                    | 0   | 0  | 1  | LO  | LO  | Z  |
| 1                                    | 0   | 1  | 0  | LO  | LO  | Z  |
| 1                                    | 0   | 1  | 1  | LO  | HI  | LO |

| Both Inverted: HSI = 1, LSI = 1 |     |    |    |     |     |    |
|---------------------------------|-----|----|----|-----|-----|----|
| HSI                             | LSI | Hx | Lx | GHx | GLx | Sx |
| 1                               | 1   | 0  | 0  | LO  | LO  | Z  |
| 1                               | 1   | 0  | 1  | HI  | LO  | HI |
| 1                               | 1   | 1  | 0  | LO  | HI  | LO |
| 1                               | 1   | 1  | 1  | LO  | LO  | Z  |

| Low-Side Inverted: HSI = 0, LSI = 1 |     |    |    |     |     |    |
|-------------------------------------|-----|----|----|-----|-----|----|
| HSI                                 | LSI | Hx | Lx | GHx | GLx | Sx |
| 0                                   | 1   | 0  | 0  | LO  | HI  | LO |
| 0                                   | 1   | 0  | 1  | LO  | LO  | Z  |
| 0                                   | 1   | 1  | 0  | LO  | LO  | Z  |
| 0                                   | 1   | 1  | 1  | HI  | LO  | HI |

HI = high-side FET active, LO = low-side FET active

Z = high impedance, both FETs off

All control register bits set to 0; ENABLE = 1, RESETn = 1

Table 2: Control Logic – Serial Register

| Phase A |    |     |     |    | Phase B |    |     |     |    | Phase C |    |     |     |    |
|---------|----|-----|-----|----|---------|----|-----|-----|----|---------|----|-----|-----|----|
| AH      | AL | GHA | GLA | SA | BH      | BL | GHB | GLB | SB | CH      | CL | GHC | GLC | SC |
| 0       | 0  | LO  | LO  | Z  | 0       | 0  | LO  | LO  | Z  | 0       | 0  | LO  | LO  | Z  |
| 0       | 1  | LO  | HI  | LO | 0       | 1  | LO  | HI  | LO | 0       | 1  | LO  | HI  | LO |
| 1       | 0  | HI  | LO  | HI | 1       | 0  | HI  | LO  | HI | 1       | 0  | HI  | LO  | HI |
| 1       | 1  | LO  | LO  | Z  | 1       | 1  | LO  | LO  | Z  | 1       | 1  | LO  | LO  | Z  |

HI = high-side FET active, LO = low-side FET active

Z = high impedance, both FETs off

Logic 0 input on HA, LA, HB, LB, HC, and LC. ENABLE = 1, RESETn = 1, HSI = LSI = 0

Table 3: Control Combination Logic – Logic Inputs and Serial Register

| Terminal | Register | Internal |
|----------|----------|----------|
| Hx       | xH       | HIx      |
| 0        | 0        | 0        |
| 0        | 1        | 1        |
| 1        | 0        | 1        |
| 1        | 1        | 1        |

| Terminal | Register | Internal |
|----------|----------|----------|
| Lx       | xL       | LOx      |
| 0        | 0        | 0        |
| 0        | 1        | 1        |
| 1        | 0        | 1        |
| 1        | 1        | 1        |

The three phases are controlled independently.

Internal control signals (HIx, LOx) are derived by combining the logic states applied to the control input terminals (Hx, Lx) with the bit patterns held in the Control register (xH, xL).

Table 3 assumes HSI and LSI = 0.

Normally the input terminals or the Control register method is used for control with the other being held inactive (all terminals or bits at logic 0).

| ENABLE | HIx | LOx | GHx | GLx | Sx | Comment        |
|--------|-----|-----|-----|-----|----|----------------|
| 1      | 0   | 0   | L   | L   | Z  | Phase disabled |
| 1      | 0   | 1   | L   | H   | LO | Phase sinking  |
| 1      | 1   | 0   | H   | L   | HI | Phase sourcing |
| 1      | 1   | 1   | L   | L   | Z  | Phase disabled |
| 0      | X   | X   | L   | L   | Z  | Phase disabled |

X = don't care

Table 4: Open-Load Detect Mode

|     |     |     |     |     |     | OL detect |          |
|-----|-----|-----|-----|-----|-----|-----------|----------|
| HIA | LOA | HIB | LOB | HIC | LOC | Off-State | On-State |
| 0   | 0   | 0   | 0   | 0   | 0   | Yes       |          |
| 0   | 0   | 0   | 0   | 0   | 1   |           |          |
| 0   | 0   | 0   | 0   | 1   | 0   |           |          |
| 0   | 0   | 0   | 0   | 1   | 1   | Yes       |          |
| 0   | 0   | 0   | 1   | 0   | 0   |           |          |
| 0   | 0   | 0   | 1   | 0   | 1   |           |          |
| 0   | 0   | 0   | 1   | 1   | 0   |           | Yes      |
| 0   | 0   | 0   | 1   | 1   | 1   |           |          |
| 0   | 0   | 1   | 0   | 0   | 0   |           |          |
| 0   | 0   | 1   | 0   | 0   | 1   |           | Yes      |
| 0   | 0   | 1   | 0   | 1   | 0   |           |          |
| 0   | 0   | 1   | 0   | 1   | 1   |           |          |
| 0   | 0   | 1   | 1   | 0   | 0   | Yes       |          |
| 0   | 0   | 1   | 1   | 0   | 1   |           |          |
| 0   | 0   | 1   | 1   | 1   | 0   |           |          |
| 0   | 0   | 1   | 1   | 1   | 1   | Yes       |          |
| 0   | 1   | 0   | 0   | 0   | 0   |           |          |
| 0   | 1   | 0   | 0   | 0   | 1   |           |          |
| 0   | 1   | 0   | 0   | 1   | 0   |           | Yes      |
| 0   | 1   | 0   | 0   | 1   | 1   |           |          |
| 0   | 1   | 0   | 1   | 0   | 0   |           |          |
| 0   | 1   | 0   | 1   | 0   | 1   |           |          |
| 0   | 1   | 0   | 1   | 1   | 0   |           | Yes      |
| 0   | 1   | 0   | 1   | 1   | 1   |           |          |
| 0   | 1   | 1   | 0   | 0   | 0   |           | Yes      |
| 0   | 1   | 1   | 0   | 0   | 1   |           | Yes      |
| 0   | 1   | 1   | 0   | 1   | 0   |           | Yes      |
| 0   | 1   | 1   | 0   | 1   | 1   |           |          |
| 0   | 1   | 1   | 1   | 0   | 0   |           |          |
| 0   | 1   | 1   | 1   | 0   | 1   |           |          |
| 0   | 1   | 1   | 1   | 1   | 0   |           |          |
| 0   | 1   | 1   | 1   | 1   | 1   |           |          |

|     |     |     |     |     |     | OL detect |          |
|-----|-----|-----|-----|-----|-----|-----------|----------|
| HIA | LOA | HIB | LOB | HIC | LOC | Off-State | On-State |
| 1   | 0   | 0   | 0   | 0   | 0   |           |          |
| 1   | 0   | 0   | 0   | 0   | 1   |           | Yes      |
| 1   | 0   | 0   | 0   | 1   | 0   |           |          |
| 1   | 0   | 0   | 0   | 1   | 1   |           |          |
| 1   | 0   | 0   | 1   | 0   | 0   |           | Yes      |
| 1   | 0   | 0   | 1   | 0   | 1   |           | Yes      |
| 1   | 0   | 0   | 1   | 1   | 0   |           | Yes      |
| 1   | 0   | 0   | 1   | 1   | 1   |           | Yes      |
| 1   | 0   | 1   | 0   | 0   | 0   |           |          |
| 1   | 0   | 1   | 0   | 0   | 1   |           | Yes      |
| 1   | 0   | 1   | 0   | 1   | 0   |           |          |
| 1   | 0   | 1   | 0   | 1   | 1   |           |          |
| 1   | 0   | 1   | 1   | 0   | 0   |           |          |
| 1   | 0   | 1   | 1   | 0   | 1   |           | Yes      |
| 1   | 0   | 1   | 1   | 1   | 0   |           |          |
| 1   | 0   | 1   | 1   | 1   | 1   |           |          |
| 1   | 1   | 0   | 0   | 0   | 0   | Yes       |          |
| 1   | 1   | 0   | 0   | 0   | 1   |           |          |
| 1   | 1   | 0   | 0   | 1   | 0   |           |          |
| 1   | 1   | 0   | 0   | 1   | 1   | Yes       |          |
| 1   | 1   | 0   | 1   | 0   | 0   |           |          |
| 1   | 1   | 0   | 1   | 0   | 1   |           |          |
| 1   | 1   | 0   | 1   | 1   | 0   |           | Yes      |
| 1   | 1   | 0   | 1   | 1   | 1   |           |          |
| 1   | 1   | 1   | 0   | 0   | 0   |           |          |
| 1   | 1   | 1   | 0   | 0   | 1   |           | Yes      |
| 1   | 1   | 1   | 0   | 1   | 0   |           |          |
| 1   | 1   | 1   | 0   | 1   | 1   |           |          |
| 1   | 1   | 1   | 1   | 0   | 0   | Yes       |          |
| 1   | 1   | 1   | 1   | 0   | 1   |           |          |
| 1   | 1   | 1   | 1   | 1   | 0   |           |          |
| 1   | 1   | 1   | 1   | 1   | 1   | Yes       |          |

Hlx, LOx derived from Table 3.

RESETn = 1, ENABLE = 1, HSI = 0, LSI = 0, AOL = 1.

## FUNCTIONAL DESCRIPTION

The AMT49100 provides six high current gate drives capable of driving a wide range of n-channel power MOSFETs. The gate drives are configured as three half bridges, each with a high-side drive and a low-side drive. The three half bridges can be operated independently or together as a three-phase bridge driver for BLDC or PMSM motors.

Gate drives have programmable drive strength and can be controlled individually with logic inputs or through the SPI-compatible serial interface. The high-side and low-side gate drive control logic inputs can be inverted as groups and provide a very flexible solution for many motor control applications. Independent control over each MOSFET allows each driver to be driven with an independent PWM signal for full sinusoidal excitation. All logic inputs have standard CMOS threshold levels and can be programmed to be compatible with 3.3 or 5 V logic outputs. The gate drive control logic inputs are battery voltage compliant, meaning they can be shorted to ground or supply without damage, up to the maximum battery voltage of 80 V.

The AMT49100 can operate with the fixed-frequency buck regulator, producing the main regulated voltage ( $V_{REG}$ ) at the VREG terminal, or with an externally generated regulated supply driving the VREG terminal. In the buck regulator mode, a single unregulated supply of 10 to 80 V is applied to the VBB terminal. In the externally regulated supply mode, a voltage of nominally 12 V is applied to both the VBB and VREG terminals. In this mode, the external inductor and Schottky diode are not required.

A charge pump regulator generates a positive voltage referenced to the applied bridge voltage ( $V_{BRG}$ ) to allow operation at high PWM duty cycles. This voltage is not available on any device terminal. The supply current required by the charge pump regulator is drawn from VREG.

Two internal linear regulators are integrated: one provides the internal logic supply voltage,  $V_{DD}$ , and a second independent programmable regulator provides the supply,  $V_{IO}$ , for the digital I/O.

Circuit functions are provided within the AMT49100 to ensure that, under normal operating conditions, all external power MOS-

FETs are fully enhanced at supply voltages down to 10 V. For extreme battery voltage drop conditions, the AMT49100 is guaranteed not to reset any internal states at supply voltages down to 5 V. A low-power sleep mode allows the AMT49100, the power bridge, and the load to remain connected to a vehicle battery supply without the need for an additional supply switch.

The AMT49100 includes a number of diagnostic features to provide indication of and/or protection against undervoltage, overvoltage, overtemperature, and power bridge faults. A single diagnostic output terminal can be programmed to provide optional diagnostic outputs, and detailed diagnostic information is available through the serial interface.

For systems requiring a higher level of safety integrity, the AMT49100 includes additional overvoltage monitors on the supplies and the control inputs. In addition, the integrated diagnostics include self-test and verification circuits to ensure verifiable diagnostic operation. When used in conjunction with appropriate system level control, these features can assist power drive systems using the AMT49100 to meet stringent ASIL D safety requirements.

The serial interface also provides access to programmable dead time, fault blanking time, programmable  $V_{DS}$  threshold for short detection, and programmable thresholds and currents for open-load detection.

The AMT49100 includes three low-side self-calibrating current sense amplifiers with common programmable output offset and independently programmable gain. These amplifiers are specifically designed for current sensing in the presence of high voltage and current transients. These amplifiers can be used independently to provide low-side current sensing in three phases or can be used together to provide redundant current sensing. The AMT49100 can also check the connections from the current sense amplifiers to the sensing links using integrated verification circuits. The programmed output offset voltage can be made available at the output of each amplifier, measured, stored, and used as the zero output reference potential for each sense amplifier.

## Input and Output Terminal Functions

**VBB:** Main power supply for the buck regulator. The main power supply should be connected to VBB through a reverse voltage protection circuit and should be decoupled with ceramic capacitors connected close to the supply and ground terminals.

**VBRG:** Sense input to the top of the external MOSFET bridge. Allows accurate measurement of the voltage at the drain of the high-side MOSFETs in the bridge. Also used as the reference voltage for the bootstrap charge pump and the non-volatile memory (NVM) programming supply. A ceramic capacitor of at least 100 nF should be connected from VBRG to GND close to the device terminals.

**VREG:** regulated voltage,  $V_{REG}$ , nominally 12 V, used to supply the low-side gate drivers and to charge the bootstrap capacitors. VREG may be provided by the buck regulator or by an external regulated supply. A sufficiently large storage capacitor must be connected to this terminal to provide the transient charging current.

**LX:** Buck converter inductor switching node.

**CP1, CP2:** Pump capacitor connection for bootstrap charge pump. A suitable capacitor as described in the Charge Pump Regulator description below must be connected between CP1 and CP2.

**GND:** Ground. Connect both GND terminals together at the AMT49100—see layout recommendations for further information.

**CA, CB, CC:** High-side connections for the bootstrap capacitors and positive supply for high-side gate drivers.

**GHA, GHB, GHC:** High-side gate drive outputs for external N-channel MOSFETs.

**SA, SB, SC:** Load phase connections. These terminals sense the voltages switched across the load. They are also connected to the negative side of the bootstrap capacitors and are the negative supply connections for the floating high-side drivers.

**GLA, GLB, GLC:** Low-side gate drive outputs for external N-channel MOSFETs.

**LSSA, LSSB, LSSC:** Low-side return path for discharge of the capacitance on the MOSFET gates, connected to the sources of the low-side external MOSFETs independently through a low-impedance track.

**HA, HB, HC:** Logic inputs to control the high-side gate drive outputs. The sense of these inputs can be selected as active high or active low. A pull-down or pull-up is connected to each input depending on the selected sense of the input. Battery voltage compliant terminal.

**LA, LB, LC:** Logic inputs to control the low-side gate drive outputs. The sense of these inputs can be selected as active high or active low. A pull-down or pull-up is connected to each input depending on the selected sense of the input. Battery voltage compliant terminal.

**SDI:** Serial data logic input with pull-down. 16-bit serial word input MSB first.

**SDO:** Serial data output. High impedance when STRn is high. Outputs bit 15 of the status register, the fault flag, as soon as STRn goes low.

**SCK:** Serial clock logic input with pull-down. Data is latched in from SDI on the rising edge of SCK. There must be 16-rising edges per write, and SCK must be held high when STRn changes.

**STRn:** Serial data strobe and serial access enable logic input with pull-up. When STRn is high, any activity on SCK or SDI is ignored and SDO is high impedance, allowing multiple SDI slaves to have common SDI, SCK, and SDO connections.

**CS1P, CS1M, CS2P, CS2M, CS3P, CS3M:** Current sense amplifier inputs.

**CS1O, CS2O, CS3O:** Current sense amplifier outputs.

**DIAG:** Diagnostic output. Programmable output to provide one of four functions: fault flag, pulsed fault flag, temperature, and internal timer. Default is fault flag.

**ENABLE:** Disables all gate drive outputs when pulled low in direct mode or after a timeout in watchdog mode. Provides an independent output disable, directly to the gate drive outputs, to allow a fast disconnect on the power bridge. Can be pulled to VBB.

**RESETn:** Resets faults when pulsed low. Forces low-power shutdown (sleep) when held low for more than the RESET shutdown time,  $t_{RSD}$ . Can be pulled to VBB.

**SAL, SBL, SCL:** Logic-level outputs representing the state of each phase determined by the output of a programmable threshold comparator.

## Power Supplies

The AMT49100 can operate with an integrated fixed-frequency buck regulator producing the main regulated voltage,  $V_{REG}$ , at the VREG terminal or with a regulated supply driving the VREG terminal. All internal operating supplies, except for the start-up and sleep state supply and the NVM programming voltage, are derived exclusively from  $V_{REG}$ . The start-up and sleep state supply is taken directly from the VBB terminal. The NVM programming voltage is taken from the VBRG terminal.

## Buck Regulator Mode

In buck regulator mode, the BRE bit is set to 1 and a single unregulated supply,  $V_{BB}$ , of 10 to 80 V is applied to the VBB terminal. If negative supply voltage is expected, then VBB should be connected through a reverse voltage protection circuit. The buck regulator requires a single inductor ( $L = 100 \mu\text{H} \pm 20\%$ ,  $I_{SAT} \geq 420 \text{ mA}$ ) mounted between the LX and the VREG terminals and a Schottky diode ( $V_R \geq 100 \text{ V}$ ,  $I_F \geq 1 \text{ A}$ ) between the LX and GND terminals. A ceramic decoupling capacitor of at least  $4.7 \mu\text{F}$  should be connected between VBB and GND close to the terminals. The switching frequency of the buck regulator is fixed at 410 kHz.

## External Regulated Supply Mode

If an external regulated 12 V supply is already available in the system, then the buck regulator can be disabled by setting the BRE bit to 0. An external 12 V supply can then be applied to the VREG terminal and the VBB terminal together, and the buck regulator components are not required. In this mode, the bridge voltage,  $V_{BRG}$ , at the VBRG terminal can vary over its full operating range from 4.5 to 80 V. A ceramic decoupling capacitor of at least 100 nF should be connected between VBB and GND close to the terminals.

Note that the BRE bit must be set in NVM. Changing the value of BRE in the SPI register will have no effect on operation. Only the value of the BRE bit stored in NVM can set the regulator mode.

## VREG Supply

In both cases, the voltage at the VREG terminal,  $V_{REG}$ , is the main operating supply for most of the circuits in the AMT49100. It provides the supply for the internal low-voltage linear regula-

tors, the reference voltage generator, the sense amplifiers, the above VBRG charge pump and the gate drivers. For the gate drivers, this includes the charge current and bias current for the low-side gate drive and the initial charge current for the bootstrap capacitors. A sufficiently large ceramic capacitor must be connected to the VREG terminal to provide the switching currents for the internal logic and logic I/O, the charge pump, and the transient currents for the low-side gate drive and bootstrap charging. This capacitor should have a minimum value of  $10 \mu\text{F}$ , but may need to be larger depending on the total gate charge of the MOSFETs being driven.

## Charge Pump Regulator

This regulator generates a voltage above the bridge supply voltage,  $V_{BRG}$ . It provides some of the switching current for the high-side drives, the charge current for the bootstrap capacitors at high PWM duty cycles, and the bias current and the gate drive current to hold the high-side MOSFET in the on state.

This regulator uses a charge pump scheme with a switching frequency of 62.5 kHz. The pump capacitor connected between the CP1 and CP2 terminals is charged to  $V_{REG}$ , then switches this voltage to be referenced to  $V_{BRG}$ . This produces a voltage approximately  $V_{REG}$  above  $V_{BRG}$ , and provides the required charge current for the high-side gate drive circuits.

The pump capacitor,  $C_p$ , between CP1 and CP2, should be ceramic and have a value of at least  $1 \mu\text{F}$ . The maximum voltage across CP1 and CP2 during operation will not exceed the VREG voltage (regardless of whether VREG is generated by the buck regulator or provided by an external supply).

One of four modes of operation may be selected according to the value of the CPM[1:0] bits in the System register (Register 7). If CPM[1:0] is set to 00b, the regulator runs in auto mode. Average regulator current is greater than 5 mA per phase until internal device logic detects that no high-side gate drive has been commanded on for more than 200  $\mu\text{s}$ , and then it drops back to a value of just over 200  $\mu\text{A}$  per phase to reduce device dissipation. Alternatively, if CPM[1:0] is set to 01b or 10b, the regulator will drive a fixed current of 200  $\mu\text{A}$  or 5 mA respectively. If CPM[1:0] is set to 11b, the regulator is turned off.

## Internal Regulators

Two internal linear regulators are integrated: one provides the internal logic supply voltage,  $V_{DD}$ , and a second independent programmable regulator provides the supply,  $V_{IO}$ , for all logic inputs and push-pull outputs.

The internal logic regulator is only used for the internal logic and is not available or accessible outside the AMT49100.

The logic I/O regulator can be selected as 3.3 or 5 V by the value in the VIO bit. VIO = 0 sets the I/O voltage to 3.3 V and VIO = 1 sets the I/O voltage to 5 V. This supply is only used to provide the supply for logic inputs and push-pull outputs and is not available or accessible outside the AMT49100.

The sense amplifier outputs are not referenced to the I/O voltage but driven directly from  $V_{REG}$ . All three sense amplifier outputs are clamped with a common clamp voltage,  $V_{CSC}$ . The sense amplifier clamps are independent from  $V_{IO}$ . Care must be taken to select the correct sense amplifier output limit.

## Power-Up Sequence

The initial supply is taken from VBB. This energizes the internal logic supply regulator and the internal bias circuits, sets the POR bit to 1, and makes the general fault flag active. Following this, the contents of the NVM are read into the device serial registers. Once the NVM read has completed, the buck regulator is activated if the BRE bit is set to 1. The POR bit in the Status register remains set to 1 until a valid Status register read is completed. During startup, the general fault flag remains in the active state until all gate drive and bridge operating voltages are above their respective undervoltage thresholds. This includes  $V_{REG}$ ,  $V_{BRG}$ , and all three bootstrap voltages. The bridge operating voltage bits in the Diagnostic and Status registers may be set and should be cleared by reading the relevant registers. The AMT49100 will then be fully operational and will respond as specified.

## Low Supply Voltage Operation

The AMT49100 will operate within specified parameters with  $V_{BB}$  from 10 to 80 V. In all cases, the AMT49100 will operate safely between 0 and 80 V under all supply switching conditions. This provides a very rugged solution for use in the harsh automotive environment.

## Low Power Sleep State

RESETn is an active-low input that allows the AMT49100 to enter a sleep state where the current consumption from the main supply and the internal logic regulator is reduced to its mini-

mum level. When RESETn is held low for longer than the reset shutdown time,  $t_{RSD}$ , the regulator and all internal circuitry is disabled and the AMT49100 enters the sleep state. In the sleep state, the buck regulator is disabled and the latched faults and corresponding fault flags are cleared, as are any fault bits in the Diagnostic and Status registers. When in the sleep state, all power is taken directly from the VBB terminal. When coming out of the sleep state, the protection logic ensures that the gate drive outputs are off until all gate drive and bridge operating voltages are above their respective undervoltage thresholds and any latched fault states are cleared.

To allow the AMT49100 to start up without the need for an external logic input, the RESETn terminal can be pulled to VBB with an external pull-up resistor.

RESETn can also be used to clear any fault conditions without entering the sleep state by taking it low for the reset pulse width,  $t_{RST}$ . Any latched fault conditions such as short detection or bootstrap capacitor undervoltage, which disable the outputs, will be cleared, but any fault bits set in the Diagnostic and/or Status registers will not be cleared.

## Gate Drives

The AMT49100 is designed to drive external, low on-resistance, power N-channel MOSFETs. It will supply the large transient currents necessary to quickly charge and discharge the external MOSFET gate capacitance in order to reduce dissipation in the external MOSFET during switching. The charge current for the low-side drives and the main recharge current for the bootstrap capacitors are provided by the capacitor on the VREG terminal. The charge current for the high-side drives is provided by the bootstrap capacitors connected between the Cx and Sx terminals, one for each phase. MOSFET gate charge and discharge rates may be controlled by setting a group of parameters via the serial interface.

## Bootstrap Supply

When the high-side drivers are active, the reference voltage for the gate drive output will rise close to the bridge supply voltage. The supply to the gate drive then must be above the bridge supply voltage to ensure that it remains active. This temporary high-side supply is provided by bootstrap capacitors, one for each high-side driver. These three bootstrap capacitors are connected between the bootstrap supply terminals, CA, CB, and CC, and the corresponding high-side reference terminal, SA, SB, and SC.

The bootstrap capacitors are independently charged to approximately  $V_{REG}$  when the associated reference Sx terminal is low. When the output swings high, the voltage on the bootstrap supply

terminal rises with the output to provide the boosted gate voltage needed for the high-side N-channel power MOSFETs.

When the Sx terminal remains high for extended periods of time, the gate drive voltage is maintained by an additional charge pump that provides a regulated voltage to charge the bootstrap capacitor. This charge pump also provides the charging current when the output PWM duty cycle is too high to permit the bootstrap capacitor to be recharged between high-side turn-on events. This combination of bootstrap drive and charge pump provides the most efficient gate drive system for a PWM system able to operate between 0 and 100% without restriction.

## High-Side Gate Drive

High-side, gate-drive outputs for external N-channel MOSFETs are provided on terminals GHA, GHB, and GHC. GHx = 1 (or “high”) means that the upper half of the driver is turned on and its drain will source current to the gate of the high-side MOSFET in the external motor-driving bridge, turning it on. GHx = 0 (or “low”) means that the lower half of the driver is turned on and its drain will sink current from the external MOSFET’s gate circuit to the respective Sx terminal, turning it off.

The reference points for the high-side drives are the load phase connections, SA, SB, and SC. These terminals sense the voltages at the load connections. They also connect to the negative side of the bootstrap capacitors and are the negative supply reference connections for the floating high-side drivers. The discharge current from the high-side MOSFET gate capacitance flows through these connections, which should have low impedance traces, to the MOSFET bridge.

MOSFET gate charge and discharge rates may be controlled via the serial interface as detailed in the Gate Drive Control section below.

The PCB should be designed to minimize stray inductance and incorporate ceramic capacitors to bypass the bridge supply local to each half bridge. Snubber circuits across each MOSFET can be used where additional noise suppression is needed. For additional information, refer to the Layout Recommendations section within this datasheet and Allegro application note AN296215, Motor Drive Discrete MOSFET Bridge Circuit Design and Layout.

## Low-Side Gate Drive

The low-side gate-drive outputs on GLA, GLB, and GLC are referenced to the corresponding LSSx terminal. These outputs are designed to drive external N-channel power MOSFETs. GLx = 1 (or “high”) means that the upper half of the driver is turned on and its drain will source current to the gate of the low-side MOSFET in the external power bridge, turning it on. GLx = 0 (or

“low”) means that the lower half of the driver is turned on and its drain will sink current from the external MOSFET’s gate circuit to the LSSx terminal, turning it off.

The LSSx terminals provide the return paths for discharge of the capacitance on the low-side MOSFET gates. These terminals should be connected independently to the common sources of the low-side external MOSFETs through a low-impedance tracks.

MOSFET gate charge and discharge rates may be controlled via the serial interface as detailed in the Gate Drive Control section below.

The PCB should be designed to minimize stray inductance and incorporate ceramic capacitors to bypass the bridge supply local to each half bridge. Snubber circuits across each MOSFET can be used where additional noise suppression is needed. For additional information, refer to the Layout Recommendations section within this datasheet and Allegro application note AN296215, Motor Drive Discrete MOSFET Bridge Circuit Design and Layout.

## Gate Drive Passive Pull-Down

Each gate drive output includes a discharge circuit to ensure that any external MOSFET connected to the gate drive output is held off when the power is removed. This discharge circuit appears as a variable resistance pull-down but is not active when the AMT49100 is in normal operating mode. At low gate source voltage, the resistance is approximately 1 MΩ to ensure that any charge accumulated on the MOSFET gate has a discharge path. This resistance reduces rapidly as the voltage increases such that any MOSFET gate that becomes charged by external means is rapidly discharged to below the turn-on threshold. In some applications, this can eliminate the requirement for a permanent external gate source resistor.

## Dead Time

To prevent cross-conduction (shoot-through) in any phase of the power MOSFET bridge, it is necessary to have a dead-time delay between a high- or low-side turn off and the next complementary turn-on event. The potential for cross-conduction occurs when any complementary high-side and low-side pair of MOSFETs are switched at the same time, for example, at the PWM switch point. In the AMT49100, the dead time for all phases is set by the contents of the DT[6:0] bits in Bridge Timing register. These seven bits contain a positive integer that determines the dead time by division from the system clock.

The dead time is defined as:

$$t_{DEAD} = n \times 50 \text{ ns}$$

where  $n$  is a positive integer defined by  $DT[6:0]$  and  $t_{DEAD}$  has a minimum active value of 100 ns.

For example, when  $DT[6:0]$  contains  $[011\ 0000]$  (= 48 in decimal), then  $t_{DEAD} = 2.4\ \mu s$ , typically.

The accuracy of  $t_{DEAD}$  is determined by the accuracy of the system clock as defined in the Electrical Characteristics table. The range of  $t_{DEAD}$  is 100 ns to 6.35  $\mu s$ . A value of 1 or 2 in  $DT[6:0]$  sets the minimum active dead time of 100 ns.

If  $DT[6:0]$  is set to zero, the dead timer is disabled and no minimum dead time is generated by the AMT49100. The logic that prevents permanent cross-conduction is, however, still active. Adequate dead time must be generated externally by, for example, the microcontroller producing the drive signals applied to the AMT49100 logic inputs or control register.

If using gate drive control, the extended MOSFET switching times that result must be accounted for when setting dead time, as described in the Gate Drive Control section below.

The internally generated dead time is only present if the on command for one MOSFET occurs within one dead time after the off command for its complementary partner. In the case where one side of a phase drive is permanently off, for example when using diode rectification with slow decay, then the dead time does not occur. In this case, the gate drive turns on within the specified propagation delay after the corresponding phase input goes high. (See Figure 4).

## Gate Drive Control

MOSFET gate drives are controlled according to the values set in registers 8 through 13.

High-side off-to-on transitions are controlled as detailed in Figure 8a. When a gate drive is commanded to turn on a current,  $I_1$  (as defined by  $IHR1[3:0]$ ), is sourced on the relevant GHx terminal for a duration,  $t_1$  (defined by  $THR[3:0]$ ). These parameters should typically be set to quickly charge the MOSFET input capacitance to the start of the Miller region, as drain-source voltage does not change during this period. Thereafter, the current sourced on GHx is set to a value of  $I_2$  (as defined by  $IHR2[3:0]$ ) and remains at this value while the MOSFET transitions through the Miller region and reaches the fully on-state. For high-side gate drives, the MOSFET fully on-state is defined as the voltage on the GHx gate drive output rising to a value within 1 V(typ) of the Cx terminal.  $I_2$  should be set to achieve the required rising time on the motor phase connection. Once in the fully on-state, the GHx output switches from current to voltage drive to hold the MOSFET in the on-state.

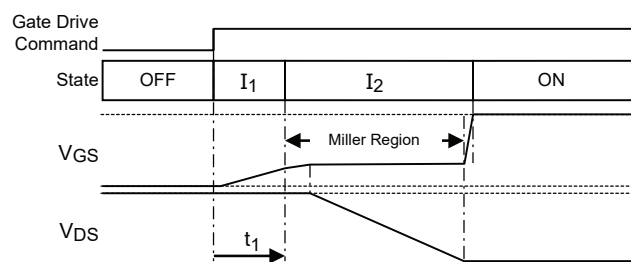


Figure 8a: Off-to-On Transition (Gate Drive Control)

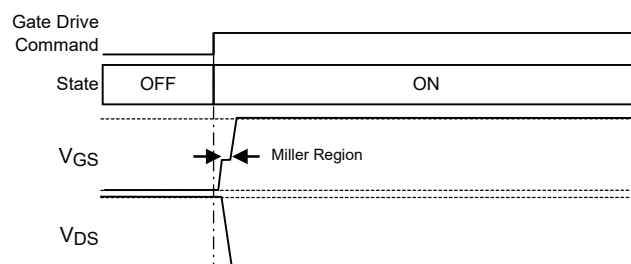


Figure 8b: Off-to-On Transition (Switched)

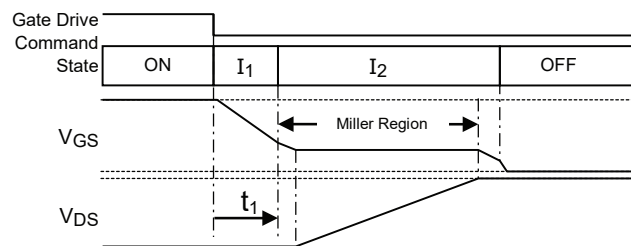


Figure 8c: On-to-Off Transition (Gate Drive Control)

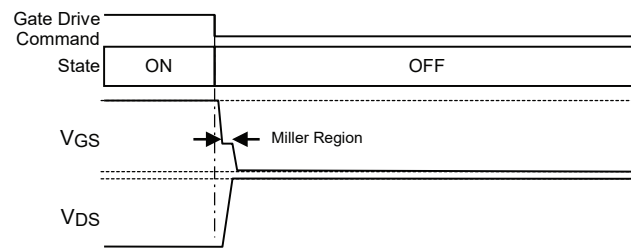


Figure 8d: On-to-Off Transition (Switched)

If the values of IHR1 and IHR2 are set to 0, GHx produces maximum drive to turn on the MOSFET as quickly as possible without attempting to control the input capacitance charge time (Figure 8b). The value of THR has no effect on switching speed.

Low-side off-to-on transitions are controlled in a similar manner by setting TLR[3:0], ILR1[3:0], and ILR2[3:0] to control GLx. For low-side gate drives, the MOSFET fully on-state is defined as the voltage on the GLx gate drive output rising to a value within 1 V(typ) of VREG. I<sub>2</sub> should be set to achieve the required falling slew time on the motor phase connection. High-side on-to-off transitions are controlled as detailed in Figure 8c. When a gate drive is commanded to turn off, a current, I<sub>1</sub> (as defined by IHF1[3:0]), is sunk by the relevant GHx terminal for a duration, t<sub>1</sub> (defined by THF[3:0]). These parameters should typically be set to quickly discharge the MOSFET input capacitance to the start of the Miller region as drain-source voltage does not change during this period. Thereafter, the current sunk by GHx is set to a value of I<sub>2</sub> (as defined by IHF2[3:0]) and remains at this value while the MOSFET transitions through the Miller region and reaches the fully off-state. For high-side gate drives, the MOSFET fully off-state is defined as the voltage on the GHx gate drive output falling to a value within 1 V(typ) of the Sx terminal. I<sub>2</sub> should be set to achieve the required falling slew time on the motor phase connection. Once in the fully off condition, the GHx output switches from current to voltage drive to hold the MOSFET in the off-state.

If the values of IHF1 and IHF2 are set to 0, GHx produces maximum drive to turn off the MOSFET as quickly as possible without attempting to control the input capacitance discharge time (Figure 8d). The value of THF has no effect on switching speed.

Low-side on-to-off transitions are controlled in a similar manner by setting TLF[3:0], ILF1[3:0] and ILF2[3:0] to control GLx. For low-side gate drives the MOSFET fully off-state is defined as the voltage on the GLx gate drive output falling to a value within 1 V(typ) of LSSx. I<sub>2</sub> should be set to achieve the required rising slew time on the motor phase connection.

If non-zero values of I<sub>1</sub> and I<sub>2</sub> are selected, a long enough value of dead time must be set to ensure that any MOSFET turning off fully transitions to the off-state before the complementary MOSFET in the same phase is allowed to start turning on. Gate drive control is active regardless of the set value of dead time.

## Logic Control Inputs

Six logic level digital inputs, HA, LA, HB, LB, HC, LC, provide direct control for the gate drives, one for each drive. The Hx inputs correspond to the high-side drives and the Lx inputs

correspond to the low-side drives. All logic inputs have standard CMOS levels referenced to the voltage of the logic I/O regulator, V<sub>IO</sub>, providing compatibility with 3.3 or 5 V control inputs. Logic inputs have a typical hysteresis of 550 mV to improve noise performance. Each input can be shorted to the VBB supply, up to the absolute maximum supply voltage, without damage to the input.

The sense of the gate drive control inputs can be inverted using the HSI and LSI bits. If HSI = 1, the sense of all three high-side inputs HA, HB, and HC are inverted. If LSI = 1, the sense of all three low-side inputs LA, LB, and LC are inverted. The operation of HSI and LSI are shown in the Control Logic Table of Table 1. A pull-down or pull-up is connected to each input depending on the selected sense of the input to ensure a safe state if the control becomes disconnected.

By inverting either the high-side control inputs or the low-side control inputs, the two inputs for each phase can be connected together and driven by a single PWM signal. Inverting the low-side inputs means that the PWM signal should be active high. Conversely, inverting the high-side inputs means that the PWM signal should be active low. If this mode of operation is selected, then an appropriate dead time must be set using the DT variable to ensure that there is no shoot-through at the PWM switching points.

The gate drive outputs can also be controlled through the serial interface by setting the appropriate bit in the control register. In the control register all bits are active high. The logical relationship between the register bit setting and the gate drive outputs is defined in Table 2.

The logic inputs are combined, using logical OR, with the corresponding bits in the serial interface control register to determine the state of the gate drive. The logical relationship between the combination of logic input and register bit setting and the gate drive outputs is defined in Table 3 (assuming HSI = LSI = 0).

In most applications, either the logic inputs or the serial control will be used. When using only the logic inputs to control the bridge, the serial register should be left in the reset condition with all control bits set to 0. When using only the serial interface to control the bridge, the inputs should be connected to GND and HSI and LSI should be set to 0. The internal pull-down resistors on these inputs ensure that they go to the inactive state should they become disconnected from the control signal level.

Internal lockout logic ensures that the high-side output drive and low-side output drive on any one phase cannot be commanded to be active simultaneously. When the control inputs request both the high-side MOSFET and the low-side MOSFET to be active at the same time for a single phase, then both high-side and low side gate drives will be forced low.

## Output Enable / Disable

The ENABLE input is connected directly to the gate drive output command signal, bypassing the main synchronous logic block on the chip (including all phase control logic). This input can be used to provide a fast output disable (emergency cut-off) or to provide non-synchronous fast decay PWM.

ENABLE can also be monitored by a watchdog timer by setting the EWD bit to 1. In this mode, the signal is routed through the synchronous logic block on the chip before connecting to the gate drive output command signal. The first change of state on the ENABLE input will activate the gate drive outputs under command from the corresponding phase control signals and a watchdog timer is started. The ENABLE input must then change state before the end of the ENABLE timeout period,  $t_{ETO}$ . If the ENABLE input does not change before the end of the timeout period and FEWD = 1, then all gate drive outputs will be driven low, the ETO bit will be set in the Status register, and the general fault flag will be active. Any following change of state on the ENABLE input will re-activate the gate drive outputs and reset the fault. If FEWD = 0, then the outputs are not affected. The ETO bit remains in the Status register until reset.

## Logic Outputs

Any one of the SxL and SDO outputs can be shorted to ground without interfering with signal integrity on the others.

## Current Sense Amplifiers

Three programmable-gain/programmable-offset differential sense amplifiers are provided to allow the use of a low-value sense resistor or current shunt as a current sensing element in the low-side connection of each phase. The input common mode range of the CSxP and CSxM inputs allows below ground current sensing typically required for low-side current sense in PWM control of motors, or other inductive loads, during switching transients. The output of the sense amplifier is available at the CSxO outputs and can be used in peak or average current control systems. The output can drive up to 4.8 V to permit maximum dynamic range with higher input voltage A-to-D converters. The maximum output voltage is clamped to  $V_{CSC}$  as defined in the Electrical Characteristics table and selected to be compatible with 3.3 or 5 V inputs using the VCL bit.

The gain,  $A_v$ , of each sense amplifier is independently programmable and defined by the contents of the S1G[2:0], S2G[2:0], and S3G[2:0] variables as:

| SxG | Gain |
|-----|------|
| 0   | 10   |
| 1   | 15   |
| 2   | 20   |
| 3   | 25   |

| SxG | Gain |
|-----|------|
| 4   | 30   |
| 5   | 35   |
| 6   | 40   |
| 7   | 50   |

A single output offset,  $V_{OOS}$ , is common to all sense amplifiers and is defined by the contents of the SAO[3:0] variable as:

| SAO | $V_{OOS}$ |
|-----|-----------|
| 0   | 0         |
| 1   | 0         |
| 2   | 100 mV    |
| 3   | 100 mV    |
| 4   | 200 mV    |
| 5   | 300 mV    |
| 6   | 400 mV    |
| 7   | 500 mV    |

| SAO | $V_{OOS}$ |
|-----|-----------|
| 8   | 750 mV    |
| 9   | 1 V       |
| 10  | 1.25 V    |
| 11  | 1.5 V     |
| 12  | 1.65 V    |
| 13  | 2 V       |
| 14  | 2.25 V    |
| 15  | 2.5 V     |

Equations describing the relationship between sense amplifier gain and output offset are shown in Figure 1. Current sense amplifier calibration minimizes Input Offset Voltage,  $V_{IOS}$ , and is initiated via the serial interface. Unless calibrated, input offset voltage may exceed the limits detailed in the Electrical Characteristics table. Calibration is not required to achieve the specified Input Offset Voltage Drift Over Temperature,  $\Delta V_{IOS}$ , and leaves this parameter unaltered.

Amplifiers are calibrated by writing a 1 to the appropriate SxC bit. If an SxC bit is already set to 1, it must first be cleared to 0 before writing 1, otherwise a calibration cycle will not take place. Before initiating a calibration, the relevant positive and negative amplifier input terminals (CSxP and CSxM) must be held at the same potential by ensuring that no current is flowing in the associated sense resistor, and this condition must be maintained until the calibration operation is complete. Calibration starts on the STRn rising edge associated with writing 1 to the SxC bit and is completed within an Offset Calibration Time,  $t_{Cal}$ , from this point. After a calibration, the amplifier automatically reverts to normal operating mode. More than one amplifier may be calibrated simultaneously by setting multiple SxC bits on a given serial interface write cycle. The calibration of one amplifier should not be initiated if the calibration of any other is in progress as the accuracy of both operations may be reduced. During calibration, transient voltage variations may be observed on the CSxO terminals.

After completion of automatic calibration, all three SxC bits

are set to a default state of 1 requiring that they are cleared to 0 before initiating another calibration.

To eliminate output offset error and drift, the sense amplifier output offset can be output on each sense amplifier output by setting the YOL bit (on-state open-load verification function) to 1. This internally shorts the sense amplifier input to the offset adder to zero, resulting in only the output offset at each sense amplifier. If the offset is then sampled, it can be used to mathematically remove the offset from the current sense signal.

The sense amplifier, including the sense amplifier output, is powered from the VREG regulated voltage to achieve the required performance. To avoid excessive stress on any input protection circuits of external monitoring or measurement circuits, the sense amplifier output voltage is limited by an active clamp circuit with a selectable clamp voltage. The clamp voltage may be selected as 5.2 V, suitable for 5 V compatible inputs by setting VCL to 1, or 3.5 V, suitable for 3.3 V compatible inputs by setting VCL to 0.

## Diagnostic Monitors

Multiple diagnostic features provide three levels of fault monitoring. These include critical protection for the AMT49100, monitors for operational voltages and states, and detection of power bridge and load fault conditions. All diagnostics, except for POR, serial transfer error, EEPROM error and overtemperature can be masked by setting the appropriate bit in the mask registers.

**Table 5: Diagnostic Functions**

| Name | Diagnostic                                                | Level   |
|------|-----------------------------------------------------------|---------|
| POR  | Internal logic supply undervoltage causing power-on reset | Chip    |
| SE   | Serial transmission error                                 | Chip    |
| EE   | EEPROM error                                              | Chip    |
| OT   | Chip junction overtemperature                             | Chip    |
| TW   | High chip junction temperature warning                    | Monitor |
| VSO  | VBRG supply overvoltage (Load dump detection)             | Monitor |
| VSU  | VBRG supply undervoltage                                  | Monitor |
| VLO  | Logic terminal overvoltage                                | Monitor |
| ETO  | ENABLE input watchdog timeout                             | Monitor |
| VRO  | VREG output overvoltage                                   | Monitor |
| VRU  | VREG output undervoltage                                  | Monitor |
| VBR  | Buck regulator fault                                      | Monitor |
| VLU  | VIO undervoltage                                          | Monitor |
| AHU  | A high-side VGS undervoltage                              | Monitor |
| ALU  | A low-side VGS undervoltage                               | Monitor |
| BHU  | B high-side VGS undervoltage                              | Monitor |
| BLU  | B low-side VGS undervoltage                               | Monitor |
| CHU  | C high-side VGS undervoltage                              | Monitor |
| CLU  | C low-side VGS undervoltage                               | Monitor |
| LAD  | LSSA Disconnect                                           | Monitor |
| LBD  | LSSB Disconnect                                           | Monitor |
| LCD  | LSSC Disconnect                                           | Monitor |
| OC1  | Overcurrent on sense amplifier 1                          | Bridge  |
| OC2  | Overcurrent on sense amplifier 2                          | Bridge  |
| OC3  | Overcurrent on sense amplifier 3                          | Bridge  |
| OL   | Open Load                                                 | Bridge  |
| VA   | Bootstrap undervoltage phase A                            | Bridge  |
| VB   | Bootstrap undervoltage phase B                            | Bridge  |
| VC   | Bootstrap undervoltage phase C                            | Bridge  |
| AHO  | Phase A high-side $V_{DS}$ overvoltage                    | Bridge  |
| ALO  | Phase A low-side $V_{DS}$ overvoltage                     | Bridge  |
| BHO  | Phase B high-side $V_{DS}$ overvoltage                    | Bridge  |
| BLO  | Phase B low-side $V_{DS}$ overvoltage                     | Bridge  |
| CHO  | Phase C high-side $V_{DS}$ overvoltage                    | Bridge  |
| CLO  | Phase C low-side $V_{DS}$ overvoltage                     | Bridge  |

Except for the three phase state outputs, the fault status is available from two sources: the DIAG output terminal, and the diagnostic and status registers accessed through the serial interface.

## DIAG Diagnostic Output

The DIAG terminal is a single diagnostic output signal that can be programmed by setting the contents of the DG[1:0] variable through the serial interface to provide one of four dedicated diagnostic signals:

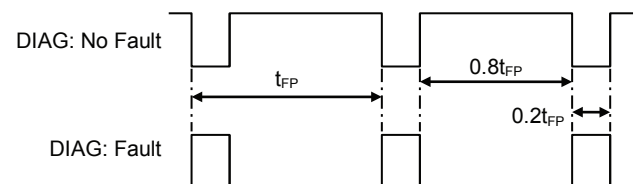
DG = 0 – a general fault flag

DG = 1 – a pulsed fault flag

DG = 2 – a voltage representing the temperature of the internal silicon

DG = 3 – a clock signal derived from the internal chip clock

At power-up, or after a power-on-reset, the DIAG terminal outputs a general logic-level fault flag which will be active-low if a fault is present. This fault flag remains low while the fault is present or if one of the latched faults has been detected and the outputs disabled. When the general fault flag is reset, the DIAG output will be high.



**Figure 9: DIAG – Pulsed Output Mode**

The pulsed fault output option provides a continuous, low frequency, low-duty cycle pulsed output when a fault is present or if one of the latched faults has been detected and the outputs disabled. When the general fault flag is reset and no fault is present, the signal output on the DIAG terminal is a continuous low frequency, high-duty cycle pulse train. The period of the DIAG signal in pulsed mode is defined by  $t_{FP}$  and is typically 100 ms. The two duty cycles are defined by  $D_{FP}$  and are typically 20% when a fault is present and 80% when no fault is present.

The temperature output option provides access to the internal voltage representing the surface temperature of the silicon. Temperature may be approximated from this voltage as:

$$T_J \approx (V_{DIAG} - V_{TJD}) / A_{TJD}$$

where  $T_J$  is the approximate silicon temperature in  $^{\circ}\text{C}$ ,  $V_{\text{DIAG}}$  is the analog voltage on the DIAG terminal in mV, and  $V_{\text{TJD}}$  and  $A_{\text{TJD}}$  are the typical range and slope values presented in the Electrical Characteristics table.

The clock output option provides a logic-level square wave output at a ratio of the internal clock frequency to allow more precise calibration of the timing settings if required.

All digital outputs available on DIAG (DG set to 0, 1, or 3) are open drain. On-state drive capability and off-state leakage current limits are defined in the Electrical Characteristics table by the  $V_{\text{OL}}$  and  $I_{\text{ODI}}$  parameters respectively and may be used to calculate a suitable pull-up resistance. In most applications, a resistor in the range 10 to 20 k $\Omega$  is suitable.

## Diagnostic Registers

The serial interface allows detailed diagnostic information to be read from the diagnostic registers on the SDO output terminal at any time.

A system status register provides a summary of all faults in a single read transaction. The status register is always output on SDO when any register is written.

The first bit (bit 15) of the status register contains a fault flag, FF, which will be high if any of the fault bits in the Status register have been set. This allows fault condition to be detected using the serial interface by simply taking STRn low. As soon as STRn goes low, the first bit in the status register can be read on SDO to determine if a fault has been detected at any time since the last fault register reset. In all cases, the fault bits in the diagnostic registers are latched and only cleared after a diagnostic register reset when DSR = 0.

Note that FF (bit 15) does not provide the same function as the general fault flag output on the DIAG terminal when STRn is high and the DIAG output is in its default mode. The fault output on the DIAG terminal provides an indication that either a fault is present or the outputs have been disabled due to a latched fault state. FF provides an indication that a fault has occurred since the last fault reset and one or more fault bits have been set.

## Chip-Level Protection

Chip-wide parameters critical for correct operation of the AMT49100 are monitored. These include maximum chip temperature, minimum internal logic supply voltage, and serial interface transmission. These three monitors are necessary to ensure that the AMT49100 can respond as specified.

### Chip Fault State: Internal Logic Undervoltage

The AMT49100 has an independent integrated logic regulator to supply the internal logic. This is to ensure that external events, other than loss of supply, do not prevent the AMT49100 from operating correctly. The internal logic supply regulator will continue to operate with a low supply voltage, for example, if the main supply voltage drops to a very low value during transient load event. In extreme low supply voltage circumstances, or during power-up or power-down, an undervoltage detector ensures that the AMT49100 operates correctly. The logic supply undervoltage lockout cannot be masked as it is essential to guarantee correct operation over the full supply range.

When power is first applied to the AMT49100, the internal logic is prevented from operating, and all gate drive outputs held in the off state until the internal regulator voltage,  $V_{\text{DD}}$ , exceeds the logic supply undervoltage lockout rising (turn-on) threshold. At this point, all serial control registers will be reset to their power-on state and all fault states and the general fault flag will be reset. The FF bit and the POR bit in the Status register will be set to one to indicate that a power-on-reset has taken place. The AMT49100 then goes into its fully operational state and begins operating as specified.

Once the AMT49100 is operational, the internal logic supply continues to be monitored. During the operational state, if  $V_{\text{DD}}$  drops below logic supply undervoltage lockout falling (turn-off) threshold, then the logical function of the AMT49100 cannot be guaranteed and the outputs will be immediately disabled. The AMT49100 will enter a power-down state and all internal activity, other than the logic regulator voltage monitor, will be suspended. If the logic supply undervoltage is a transient event, then the AMT49100 will follow the power-up sequence above as the voltage rises.

### Chip Fault State: Overtemperature

If the chip temperature rises above the overtemperature threshold,  $T_{\text{JF}}$ , the general fault flag will be active and the overtemperature bit, OT, will be set in the Status register. If FOT = 1 when an overtemperature is detected, all gate drive outputs will be disabled automatically. If FOT = 0, then no circuitry will be disabled and action must be taken by the user to limit the power dissipation in some way so as to prevent overtemperature damage to the chip and unpredictable device operation. When the temperature drops below  $T_{\text{JF}}$  by more than the hysteresis value,  $T_{\text{JFHYs}}$ , the general fault flag will be reset, but the overtemperature bit remains in the Status register until reset.

## Chip Fault State: Serial Error

The data transfer into the AMT49100 through the serial interface is monitored for two fault conditions: transfer length and parity. A transfer length fault is detected if there are more than 16 rising edges on SCK or if STRn goes high and there have been fewer than 16 rising edges on SCK. A parity fault is detected if the total number of logic 1 states in the 16-bit transfer is an even number. In both cases, the write will be cancelled without writing data to the registers. In addition, the status register will not be reset, and the FF bit and SE bit will be set to indicate a data transfer error. If the transfer is a diagnostic or verification result read, then the addressed register will not be reset.

If a serial error is detected and FSE = 1, then all gate drive outputs will be driven low (disabled). If FSE = 0, no further action will be taken.

## Chip Fault State: EEPROM

Configuration and calibration information is stored within internal EEPROM and loaded into working registers to configure the device at power up. As part of this process, a data integrity check is carried out. If the check returns a single bit error, automatic error correction is applied, and the part starts up. If the check returns a multiple bit error, all gate drives are disabled, the general fault flag is set low, and the EEPROM error bit, EE, is set in the Status register. EEPROM faults can only be cleared by a power-on-reset (POR).

## Chip Fault State: Buck Regulator Fault

If the buck regulator is enabled (BRE = 1) and switching, and an open or short circuit is detected between the Lx terminal and ground, the buck regulator will be held in the off state, the general fault flag will be active, the VBR fault bit will be set in the Diagnostic 1 register, and the VR bit will be set in the Status register. Additionally, V<sub>REG</sub> will not be generated, a VREG undervoltage fault will be indicated, and it will not be possible to turn on any gate drive outputs. To clear the fault, the underlying short or open circuit must be removed and the VBB supply to the AMT49100 must be cycled off and back on. If the buck regulator is not enabled (BRE = 0) or not switching, the VBR bit will never be set.

## Operational Monitors

Parameters related to the safe operation of the AMT49100 in a system are monitored. These include parameters associated with external active and passive components, power supplies, and interaction with external controllers.

Voltages relating to driving the external power MOSFETs are monitored, specifically V<sub>REG</sub>, each bootstrap capacitor voltage and the V<sub>GS</sub> of each gate drive output. The main bridge voltage, V<sub>BRG</sub>, is monitored for overvoltage and undervoltage events.

The battery-compliant logic inputs and outputs are capable of being shorted to the main supply voltage without damage, but any high voltage on these terminals will be detected. In addition, a watchdog timer can be applied to the ENABLE input to verify continued operation of the external controller.

## Monitor: VBB Undervoltage

The voltage at the VBB terminal, V<sub>BB</sub>, is monitored in order to indicate when the supply is rising or falling. This is to ensure a safe startup and shutdown as V<sub>BB</sub> is applied or removed. As V<sub>BB</sub> rises, the buck converter is disabled until V<sub>BB</sub> rises above the VBB undervoltage rising threshold, V<sub>BBOU</sub>. Once above the rising threshold, the buck converter (if enabled) is allowed to start and run. As V<sub>BB</sub> falls below the VBB falling undervoltage threshold, V<sub>BBOF</sub>, the buck converter is disabled. There are no fault bits set nor any fault output when V<sub>BB</sub> is undervoltage.

## Monitor: VREG Undervoltage and Overvoltage

It is critical to ensure that the regulated voltage, V<sub>REG</sub>, at the VREG terminal is sufficiently high before enabling any of the outputs.

If V<sub>REG</sub> goes below the VREG undervoltage threshold, V<sub>ROFF</sub>, the general fault flag is active and the VREG undervoltage bit, VRU, is set in the Diagnostic 1 register.

If a VREG undervoltage state is present and FVRU = 1, all gate drive outputs go low. When V<sub>REG</sub> rises above the rising threshold, V<sub>RON</sub>, the fault is cleared and, if FVRU = 1, the gate drive outputs are re-enabled. The fault bit remains in the Diagnostic register until cleared. If FVRU = 0, fault reporting will be the same, but the gate drive outputs are not disabled and appropriate action to avoid potential misoperation or damage to the AMT49100 and/or bridge MOSFETs must be taken by the external controller.

The VREG undervoltage monitor circuit is active during power up. If FVRU = 1, all gate drives will be low until V<sub>REG</sub> is greater than V<sub>RON</sub>. If FVRU = 0, the gate drive outputs will be active as soon as there is sufficient voltage on VREG to activate the gate drive outputs.

The VREG undervoltage monitor can be disabled by setting the VRU bit in the Mask 1 register. Although not recommended, setting VRU to 1 or setting FVRU to 0 can allow the AMT49100 to operate below its minimum specified supply voltage level with a

severely impaired gate drive. The specified electrical parameters will not be valid in this condition.

The output of the VREG regulator is also monitored to detect any overvoltage applied to the VREG terminal.

If  $V_{REG}$  goes above the VREG overvoltage threshold,  $V_{ROV}$ , the general fault flag is active and the VREG overvoltage bit, VRO, is set in the Diagnostic 1 register. If  $FVRO = 1$ , all gate drive outputs go low, the motor drive is disabled and the motor coasts. If  $FVRO = 0$ , no action is taken and the gate drive outputs are protected from overvoltage by independent Zener clamps. When  $V_{REG}$  falls below  $V_{ROV}$  by more than the hysteresis voltage,  $V_{ROVHys}$ , the general fault flag is cleared, but the VRO bit remains in the Diagnostic 1 register until reset. If the outputs have been disabled because  $FVRO = 1$ , they are re-enabled.

### Monitor: Temperature Warning

If the chip temperature rises above the temperature warning threshold,  $T_{JW}$ , the hot warning bit, TW, will be set in the Status register, and if  $FTW = 1$ , all gate drives will be low. If  $FTW = 0$ , gate drives will remain active. When the temperature drops below  $T_{JW}$  by more than the hysteresis value,  $T_{JWHys}$ , the fault is reset and if  $FTW = 1$ , the outputs are re-enabled. The TW bit remains in the Status register until reset.

### Monitor: VBRG Supply Overvoltage and Undervoltage

The main battery supply to the bridge,  $V_{BRG}$ , is monitored by the AMT49100 on the VBRG terminal to indicate if the supply voltage has exceeded its normal operating range (for example, during a load dump transient). If  $V_{BRG}$  rises above the VBRG overvoltage warning threshold,  $V_{BRGOV}$ , then the general fault flag will be set, the VSO bit will be set in the Diagnostic 2 register, the VS bit (which indicates the logical OR of the VSO and VSU bits) will be set in the Status register, and if  $FVSO = 1$ , all gate drive outputs will be driven low (disabled). When  $V_{BRG}$  drops below the falling VBRG overvoltage warning threshold,  $V_{BRGOV} - V_{BRGOVHys}$ , the general fault flag will be cleared and the gate drive outputs will be re-enabled, but the VSO and VS bits will remain set until the Diagnostic 2 register is read with  $DSR = 0$ . If  $FVSO = 0$ , fault reporting will be the same, but the gate drive outputs will not be disabled. The VBRG overvoltage warning threshold can be set to one of two levels using the VPO bit.

If  $V_{BRG}$  falls below the VBRG undervoltage warning threshold,  $V_{BRGUV}$ , then the VSU bit will be set in the Diagnostic 2 register and the VS bit (which indicates the logical OR of the VSO and VSU bits) will be set in the Status register. If  $FVSU = 1$ , the general fault flag will be set and all gate drive outputs will be driven low (disabled), causing the motor to coast. When  $V_{BRG}$

moves above the rising VBRG undervoltage threshold,  $V_{BRGUV} + V_{BRGUVHys}$ , the general fault flag will be cleared and the gate drive outputs will be re-enabled, but the VSU and VS bits will remain set until the Diagnostic 2 register is read with  $DSR = 0$ . If  $FVSU = 0$ , fault reporting will be the same, but the gate drive outputs will be not be disabled. The VBRG undervoltage warning threshold can be set to one of two levels using the VPU bit.

### Monitor: VGS Undervoltage

To ensure that the gate drive output is operating correctly, each gate drive output voltage is independently monitored, when active, to ensure the drive voltage,  $V_{GS}$ , is sufficient to fully enhance the power MOSFET in the external bridge.

If  $V_{GS}$  on any active gate drive output is lower than the gate drive undervoltage warning threshold,  $V_{GSUV}$ , the general fault flag will be active, the corresponding gate drive undervoltage bit, AHU, ALU, BHU, BLU, CHU, or CLU will be set in the Diagnostic 0 register, and if  $FGSU = 1$ , all gate drive outputs will be inactive (low). The gate drive outputs will remain inactive (low) until the fault state and the general fault flag are reset by a low pulse on the RESETn input, a serial read of the Diagnostic 0 register when  $DSR = 0$ , or by a power-on reset. The gate drive undervoltage bits, AHU, ALU, BHU, BLU, CHU, or CLU will only be reset by a serial read of the Diagnostic 0 register when  $DSR = 0$  or by a power-on reset. If  $FGSU = 0$ , fault reporting will be the same but the gate drive outputs will be not be disabled.

The output from each VGS undervoltage comparator is filtered by a VGS fault qualifier circuit. This circuit uses a timer to verify that the output from the comparator is indicating a valid VGS fault. The duration of the VGS fault qualifying timer,  $t_{VDQ}$ , is determined by the contents of the TVD[5:0] variable.  $t_{VDQ}$  is approximately defined as:

$$t_{VDQ} = n \times 100 \text{ ns}$$

where n is a positive integer defined by TVD[5:0].

The qualifier can operate in one of two ways, debounce mode or blanking mode, selected by the VDQ bit.

In debounce mode (the default setting), a timer is started each time the comparator output indicates a VGS fault detection when the corresponding MOSFET is active. This timer is reset when the comparator changes back to indicate VGS is within 1 V of the voltage on the Cx terminal (high-side gate drives) or VREG (low-side gate drives). If the debounce timer reaches the end of the timeout period, set by  $t_{VDQ}$ , then the VGS fault is considered valid, and the AMT49100 follows the fault action described above.

In blanking mode (optional), a timer is started when any gate drive

is turned on or turned off. The outputs from the VGS undervoltage comparators for all MOSFETs are ignored (blanked) for the duration of the timer's active period, set by  $t_{VDQ}$ . If any gate drive changes state while a blanking period is in progress, then the timer is re-triggered, resulting in an extended overall blanking time. If any comparator output indicates a VGS fault and the blanking timer is not active, then the VGS fault is considered valid and the AMT49100 follows the fault action described above.

The VDQ and TVD[5:0] qualifier parameters apply to both the VGS undervoltage and VDS overvoltage monitors.

### Monitor: Gate Drive Output State

Each gate drive output includes a comparator that detects if the gate drive output is greater or less than 1 V. This is used to provide the output state of each gate drive output. The output of the six comparators are available by reading the xHM and xLM bits in Verify Result 0 register. These bits are continuously updated with the unqualified output of each of the six VGS state comparators. The state of the comparator is captured at the start of each serial transmission.

### Monitor: LSS Disconnect

Each LSS terminal includes a continuous current source,  $I_{LU}$ , to VREG, that will pull each LSSx terminal up if there is no low-impedance path from the LSSx terminal to ground. If the voltage at an LSSx terminal with respect to ground rises above the rising LSS open threshold,  $V_{LSO}$ , then the appropriate LxD bit is set in the Diagnostic 0 register and the general fault flag on DIAG becomes active.

If FLSS = 0, no further action is taken. If the voltage on the LSS pin drops below the falling LSS open threshold,  $V_{LSO} - V_{LSOHys}$ , the general fault flag becomes inactive. The LxD bit in the Diagnostic register may then be cleared by reading the Diagnostic 1 register.

If FLSS = 1 and FDSO = 0, the low-side VDS overvoltage fault on the same phase as the detected LSS disconnect is also indicated. The relevant xLO bit is set in the Diagnostic 1 register along with the DSO and FF bits in the Status register, and all gate drives are disabled. If the voltage on the LSS pin drops below the falling LSS open threshold,  $V_{LSO} - V_{LSOHys}$ , the gate drive outputs are re-enabled. The Diagnostic 0 register may then be read to clear the LxD bit. After this, the Diagnostic 1 register may be read to clear the xLO, DSO, and FF bits and the general fault flag.

If FLSS = 1 and FDSO = 1, the low-side VDS overvoltage fault on the same phase as the detected LSS disconnect is also indicated. The relevant xLO bit is set in the Diagnostic 1 register

along with the DSO and FF bits in the Status register, and all gate drives are disabled. After the voltage on the LSS pin drops below the falling LSS open threshold,  $V_{LSO} - V_{LSOHys}$ , the Diagnostic 0 register may be read to clear the LxD bit. Then, the Diagnostic 1 register may be read to clear the xLO, DSO, and FF bits and to set the general fault flag to inactive.

### Monitor: Logic Terminal Overvoltage

Eight of the logic inputs are capable of being shorted to the main supply voltage, up to 50 V, without damage. These terminals are HA, LA, HB, LB, HC, LC, ENABLE, and RESETn. The DIAG output can also survive connection to the main supply. Except for RESETn, the voltage on these terminals,  $V_L$ , is monitored to provide an indication of an input short-to-battery fault. RESETn is intended to be able to be connected to the supply and is not monitored for overvoltage. If  $V_L$  on any of the remaining terminals rises above the logic terminal overvoltage warning threshold,  $V_{LOV}$ , then the VLO bit is set in the Status register. Additionally, the general fault flag is set to active (low) except in the case of a DIAG terminal overvoltage where the open-drain output maintains a high-impedance (off) state. The DIAG terminal is protected and the overvoltage detect function is active regardless of the signal output selected via the DG variable in the System register. If the fault is on one of the inputs and FVLO = 1, then all gate drive outputs will be disabled. If FVLO = 0, the outputs are not affected. When  $V_L$  on all terminals falls below the logic input overvoltage warning threshold,  $V_{LOV}$ , the fault flag will be reset and the outputs will be re-activated. The VLO bit remains in the Status register until reset.

### Monitor: VIO Undervoltage

The AMT49100 has an independent integrated logic regulator to provide the reference for all logic inputs and outputs. If the combined external load current drawn from the device's push-pull logic outputs (SxL and SDO) is sufficient to pull this regulator voltage down to a level where the specified logic high output voltage,  $V_{OH}$ , cannot be maintained, the general fault flag is activated, the VLU bit is set in the Status register, and if FVLU = 1, the gate drive outputs are disabled. If FVLU = 0, the faults are indicated and recorded but the gate drive outputs remain unaffected. The regulator voltage rises to a sufficiently high value. The fault state is cleared. The VLU bit remains in the register until reset.

### Monitor: ENABLE Watchdog Timeout

The ENABLE input provides a direct connection to all gate drive outputs and can be used as a safety override to immediately disable the outputs. The ENABLE input is programmed to

operate as a direct logic control by default but can be monitored by a watchdog timer by setting the EWD bit to 1. In the direct mode, the input is not monitored other than for input overvoltage as described in the Logic Input Overvoltage section above. In watchdog mode, the first change of state on the ENABLE input will activate the gate drive outputs under command from the corresponding phase control signals, and a watchdog timer is started. The ENABLE input must then change state before the end of the ENABLE timeout period,  $t_{ETO}$ . If the ENABLE input does not change before the end of the timeout period, then the general fault flag will be active, the ETO bit will be set in the Status register, and if FEWD = 1, all gate drive outputs will be driven low (disabled). Any following change of state on the ENABLE input will reset the general fault flag and re-activate the gate drive outputs. If FEWD = 0, the faults will be indicated and stored but the gate drive outputs will not be affected. The ETO bit will remain set in the Status register until reset.

## Power Bridge and Load Faults

### Bridge: Overcurrent Detect

Current sense amplifiers 1, 2, and 3 are fully independent and may be allocated to any phase (A, B, or C).

The output from each of the three sense amplifiers is fed into a comparator referenced to the overcurrent threshold voltage,  $V_{OCT}$ , to provide indication of overcurrent events.  $V_{OCT}$  is generated by a 4-bit DAC with a resolution of 300 mV and defined by the contents of the OCT[3:0] variable.  $V_{OCT}$  is approximately defined as:

$$V_{OCT} = (n + 1) \times 300 \text{ mV}$$

where n is a positive integer defined by OCT[3:0].

Any offset programmed on SAO[3:0] is applied to both the current sense amplifier output and the VOCT threshold and has no effect on the overcurrent threshold,  $I_{OCT}$ . In effect,  $V_{CSD}$  is compared with  $V_{OCT}$  and the relationship between the threshold voltage and threshold current is given by:

$$I_{OCT} = V_{OCT} / (R_S \times A_V)$$

where  $V_{OCT}$  is the overcurrent threshold voltage programmed by OCT[3:0],  $I_{OCT}$  is the corresponding current value,  $R_S$  is the sense resistor value in  $\Omega$ , and  $A_V$  is the sense amplifier gain defined by S1G[2:0], S2G[2:0], or S3G[2:0].

The output from each overcurrent comparator is filtered by an overcurrent qualifier circuit. This circuit uses a timer to verify that the output from the comparator is indicating a valid overcurrent event. The qualifier can operate in one of two ways: debounce or blanking, selected by the OCQ bit.

In the default debounce mode, a timer is started each time a comparator output indicates an overcurrent detection. This timer is reset when the comparator changes back to indicate normal operation. If the debounce timer reaches the end of the timeout period, set by  $t_{OCQ}$ , then the overcurrent event is considered valid and the corresponding overcurrent bit (OC1, OC2, or OC3) will be set in the Diagnostic 2 register.

In the optional blanking mode, a timer is started when any gate drive is turned on. The output from all comparators is ignored (blanked) for the duration of the timeout period, set by  $t_{OCQ}$ . If a comparator output indicates an overcurrent event when the blanking timer is not active, then the overcurrent event is considered valid and the corresponding overcurrent bit (OC1, OC2, or OC3) will be set in the Diagnostic 2 register. If a gate drive is turned on while a timeout period is in progress, the timeout is extended to run for a period of  $t_{OCQ}$  from the new turn on event. If all gate

drives are turned off during a timeout period, the timeout period is terminated.

The duration of the overcurrent qualifying timer,  $t_{OCQ}$ , is determined by the contents of the TOC[4:0] variable.  $t_{OCQ}$  is approximately defined as:

$$t_{OCQ} = n \times 500 \text{ ns}$$

where n is a positive integer defined by TOC[4:0].

When a valid overcurrent is detected with FOC = 1, the general fault flag is set, all gate drive outputs are driven inactive (low), and the corresponding OC1, OC2, and OC3 bits are set. The gate drive outputs will remain inactive (low) until the fault state and the general fault flag are reset by a low pulse on the RESETn input, a serial read of the Diagnostic 2 register when DSR = 0, or by a power-on reset. The OC1, OC2, and OC3 bits will only be reset by a serial read of the Diagnostic 2 register when DSR = 0 or by a power-on reset.

If FOC = 0 and an overcurrent is detected, the general fault flag is set and the corresponding OC1, OC2, and OC3 bits are set, but the outputs remain active.

### Bridge: Open-Load Detect

Two open-load fault detection methods are provided: an on-state current monitor and an off-state open-load detector. An on-state is defined by the state of the gate drive outputs as one or two high-side MOSFETs switched on and one or two low-side MOSFETs switched on. The resulting combinations are the only ones where current can be passed through the low-side sense resistor. An off-state is defined by the state of the gate drive outputs as all MOSFETs switched off. In this state, the load connections are high impedance and can be used to detect the presence or otherwise of a load.

#### On-State Open-Load Detection

On-state open-load detection is only active when AOL = 1, one or two high-side MOSFETs are switched on and one or two low-side MOSFETs are switched on. This excludes the cases where a high-side MOSFET and a low side MOSFET in the same phase are commanded to be on at the same time. Table 4 shows the open-load detection mode for each combination of output demand.

During the on-state, the AMT49100 compares the output from each sense amplifier against the open-load threshold voltage,  $V_{OLTH}$ .  $V_{OLTH}$  is generated by an internal DAC and is defined by the value in the OLT[3:0] variable. These bits provide the input to a 4-bit DAC with a least significant bit value of typically 25 mV.

The output of the DAC produces  $V_{OLTH}$  approximately defined as:

$$V_{OLTH} = n \times 25 \text{ mV}$$

where  $n$  is a positive integer defined by OLT[3:0].

Any offset programmed on SAO[3:0] is applied to both the current sense amplifier output and the  $V_{OLTH}$  threshold and has no effect on the open-load detect threshold current,  $I_{OLT}$ . In effect,  $V_{CSD}$  is compared with  $V_{OLTH}$ , and the relationship between the threshold voltage and threshold current is given by:

$$I_{OLT} = V_{OLTH} / (R_S \times A_V)$$

where  $V_{OLTH}$  is the open-load threshold voltage programmed by OLT[3:0],  $I_{OLT}$  is the corresponding current value,  $R_S$  is the sense resistor value in  $\Omega$ , and  $A_V$  is the sense amplifier gain defined by S1G[2:0], S2G[2:0], or S3G[2:0].

If the output of all sense amplifiers is less than  $V_{OLTH}$  during the on-state, then a timer is allowed to increment. If the output of any amplifier is higher than  $V_{OLTH}$  during the on-state, then the timer is reset. If the timer reaches the open load timeout value  $t_{OLTO}$ , typically 100 ms, then the general fault flag will be active and the open-load fault bit, OL, will be set in the Diagnostic 2 register, indicating a valid open-load condition.

As soon as the output of any amplifier is higher than  $V_{OLTH}$  during the on-state, then the general fault flag will be reset, but the open-load fault bit remains in the Diagnostic 2 register until reset.

If the sense amplifier is not used in the application, then the on-state open-load detection can be completely disabled by setting AOL to 0.

### Off-State Open-Load Detection

Prior to initiating an off-state open-load test, the bootstrap charge pump must be turned off by setting the charge pump mode variable, CPM[1:0], to 3 and all gate drive outputs must be commanded off. Open-load detection is then initiated by setting YPS = 3. While YPS = 3, a current sink,  $I_{SD}$ , is applied to the SB terminal and a current source,  $I_{SU}$ , is applied to the SA and SC terminals.

$I_{SD}$  is typically 2.5 mA, which is low enough to allow the AMT49100 to survive a short to VBB on the SB terminal during the off-state without damage, and high enough to discharge any output capacitance in an acceptable time.

The value of  $I_{SU}$  is selected by the YSC bit. When YSC = 0,  $I_{SU} = -90 \mu\text{A}$ ; when YSC = 1,  $I_{SU} = -410 \mu\text{A}$ .

Off-state open-load detection relies on there being no residual

current in the load or the bridge and no large capacitors connected to the load or the bridge phase connections. If these requirements are not satisfied, then sufficient time must elapse before the state of the load connection is correctly indicated. This timeout is not provided by the AMT49100 and must be managed by the external controller.

Once any residual energy has dissipated, the sink current,  $I_{SD}$ , pulls the SB terminal to ground. The source current,  $I_{SU}$ , applies a test current to the load. As the sink current is much larger than the source current, the current through the load will be the source current. The voltage at the SB terminal,  $V_{SB}$ , should be close to zero and the voltages at the SA and SC terminals,  $V_{SA}$  and  $V_{SC}$ , will allow the load resistance to be measured.  $V_{SA}$  and  $V_{SC}$  are compared to the low-side VDS threshold,  $V_{DSTL}$ . If  $V_{SA}$  or  $V_{SC}$  is greater than  $V_{DSTL}$ , then the open load fault bit, OL, will be set in the Diagnostic 2 register. The LDF and FF bits will not be set in the Status register. If there are external capacitors connected to the bridge phase nodes or there is residual current in the load, then it may take some time for these nodes to discharge to the final value and OL may indicate a fault during this time. On reaching the final steady-state value, if  $V_{SA}$  and  $V_{SC}$  are both less than  $V_{DSTL}$ , then OL will be 0 and a load is assumed to be present.

To allow the external controller to read the present state of the open-load test result, OL is not latched. The point at which the open-load result is read is therefore controlled by the external controller and should be determined by characterization of the system settling time during the open-load test.

The threshold for load resistance is determined by the current source,  $I_{SU}$ , and the low-side VDS threshold,  $V_{DSTL}$ .

For example, if  $V_{DSTL}$  is 1.2 V and  $I_{SU} = -410 \mu\text{A}$ , the equivalent threshold resistance is approximately 3 k $\Omega$ , so any load resistance greater than this value is detected as an open-load.

On completion of the open-load test, the variables YSC, YPS, and CPM should all be set to 0 to resume normal operation.

### Motor Winding Considerations

If driving a star-connected motor, the on-state and off-state methods described above allow the detection of open-load faults in the bridge-to-motor interconnects and within the motor itself. If driving a delta-connected motor, only faults in the bridge-to-motor interconnects may be detected as motor inter-terminal impedance will remain relatively low in the event of a single-point failure internal to the motor (this type of motor having two internal current paths between each terminal).

## Bridge: Bootstrap Capacitor Undervoltage Fault

The AMT49100 attempts to ensure that the bootstrap capacitor always remains charged when it is in the operating state. The bootstrap capacitor voltage is monitored by an undervoltage comparator, which is active when the corresponding high-side gate drive is active (on). If the bootstrap voltage is below the undervoltage threshold,  $V_{BCUV}$ , when the high-side is commanded on, then a bootstrap undervoltage fault will be detected.

The action taken when a valid bootstrap undervoltage fault is detected, and the fault reset conditions, depends on the state of the FVBU bit.

If FVBU = 0, the fault state will be latched, the general fault flag will be active, the associated bootstrap undervoltage fault bit (VA, VB, VC) will be set in the Diagnostic 2 register, and the associated gate drive output will be inactive (low). The fault state and the general fault flag, but not the bootstrap undervoltage fault bit, will be reset the next time the MOSFET is commanded to switch on. If the MOSFET is being driven with a PWM signal, then this will usually mean that the MOSFET will be turned on again each PWM cycle. If this is the case, and the fault condition remains, then a valid fault will again be detected after the timeout period and the sequence will repeat. The general fault flag will only be reset for the duration of the validation timer. The bootstrap undervoltage fault bit will only be reset by a serial read of the Diagnostic 2 register when DSR = 0, by a logic low pulse of duration  $t_{RST}$  on the RESETn input or by a power-on reset. When DSR = 1, the fault bit cannot be reset.

If FVBU = 1, the fault will be latched, the general fault flag will be active, the associated bootstrap undervoltage fault bit (VA, VB, VC) will be set in the Diagnostic 2 register, and all gate drive outputs will be inactive (low).

The gate drive outputs will remain inactive (low) until the fault state and the general fault flag are reset by a low pulse of duration  $t_{RST}$  on the RESETn input, a serial read of the Diagnostic 2 register when DSR = 0, or by a power-on reset. The bootstrap undervoltage fault bit will only be reset by a serial read of the Diagnostic 2 register when DSR = 0 or by a power-on reset.

The bootstrap undervoltage monitor can be disabled for all three phases by setting the BSU bit in the Mask 2 register. Although not recommended, this can allow the AMT49100 to operate below its minimum specified supply voltage level with a severely impaired gate drive. The specified electrical parameters may not be valid in this condition.

## Bridge: MOSFET VDS Overvoltage Fault

Faults on any external MOSFETs are determined by monitoring the drain-source voltage of the MOSFET and comparing it to a drain-source overvoltage threshold. There are two thresholds,  $V_{DSTH}$ , for the high-side MOSFETs, and  $V_{DSTL}$  for the low-side.  $V_{DSTH}$  and  $V_{DSTL}$  are generated by internal DACs and are defined by the values in the VTH[5:0] and VTL[5:0] variables respectively. These variables provide the input to two 6-bit DACs with a least significant bit value of typically 50 mV. The output of the DAC produces the threshold voltage approximately defined as:

$$V_{DSTH} = n \times 50 \text{ mV}$$

where n is a positive integer defined by VTH[5:0],

or

$$V_{DSTL} = n \times 50 \text{ mV}$$

where n is a positive integer defined by VTL[5:0].

The low-side drain-source voltage for any MOSFET is measured between the adjacent Sx terminal and the adjacent LSSx terminal. Using the LSSx terminal rather than the ground connection avoids adding any low-side current sense voltage to the real low-side drain-source voltage and avoids false VDS fault detection.

The high-side drain-source voltage for any MOSFET is measured between the adjacent Sx terminal and the VBRG terminal. Using the VBRG terminal rather than the VBB avoids adding any reverse diode voltage or high-side current sense voltage to the real high-side drain-source voltage and avoids false VDS fault detection.

The VBRG terminal is an independent low-current sense input to the top of the MOSFET bridge. It should be connected independently and directly to the common connection point for the drains of the power bridge MOSFETs at the positive supply connection point in the bridge. The input current drawn by the VBRG terminal is approximately 1 mA.

Note that the VBRG terminal can withstand a negative voltage up to -5 V. This allows the terminal to remain connected directly to the top of the power bridge during negative transients where the body diodes of the power MOSFETs are used to clamp the negative transient. The same applies to the more extreme case where the MOSFET body diodes are used to clamp a reverse battery connection.

The output from each VDS overvoltage comparator is filtered by a VDS fault qualifier circuit. This circuit uses a timer to verify that the output from the comparator is indicating a valid VDS fault. The duration of the VDS fault qualifying timer,  $t_{VDQ}$ , is

determined by the contents of the TVD[5:0] variable.  $t_{VDQ}$  is approximately defined as:

$$t_{VDQ} = n \times 100 \text{ ns}$$

where  $n$  is a positive integer defined by TVD[5:0].

The qualifier can operate in one of two ways: debounce mode or blanking mode, selected by the VDQ bit.

In debounce mode (the default setting), a timer is started each time the comparator output indicates a VDS fault detection when the corresponding MOSFET is active. This timer is reset when the comparator changes back to indicate normal operation. If the debounce timer reaches the end of the timeout period, set by  $t_{VDQ}$ , then the VDS fault is considered valid and the corresponding VDS fault bit, ALO, AHO, BLO, BHO, CLO, or CHO will be set in the Diagnostic 1 register.

In blanking mode (optional), a timer is started when any gate drive is turned on or turned off. The outputs from the VDS over-voltage comparators for all MOSFETs are ignored (blanked) for the duration of the timer's active period, set by  $t_{VDQ}$ . If any gate drive changes state while a blanking period is in progress, the timer will be retriggered, resulting in an extended overall blanking time. If any comparator output indicates a VDS fault and the blanking timer is not active, then the VDS fault is considered valid and the corresponding VDS fault bit, ALO, AHO, BLO, BHO, CLO, or CHO is set in the Diagnostic 1 register.

The VDQ and TVD[5:0] qualifier parameters set in the VDS Qualifier register apply to both the VGS undervoltage and VDS overvoltage monitors.

The action taken when a valid VDS fault is detected and the action then required to clear the fault state depend upon the FDSO bit value. If FDSO = 0, the fault state will be latched, the general fault flag will be active, the associated VDS fault bit will be set, and the gate drive for the associated MOSFET will be inactive (low). The gate drive output will remain inactive (low) until the fault state and the general fault flag are reset the next time the MOSFET, on which the fault was detected, is commanded to switch on. The associated VDS fault bit remains set in the Diagnostic 1 register until reset. If the MOSFET is being driven with a PWM signal, then this will usually mean that the MOSFET will be turned on again each PWM cycle. If this is the case, and the fault condition remains, then a valid fault will again be detected after the timeout period and the sequence will repeat. The general fault flag will only be reset for the duration of the validation timer. The VDS fault bits will only be reset by a serial read of the Diagnostic 1 register with DSR = 0 or by a power-on reset.

If FDSO = 1, the fault will be latched, the general fault flag will be active, the associated VDS fault bit will be set, and all gate drive outputs will be inactive (low). The gate drive outputs will remain inactive (low) until the fault state and the general fault flag are reset by a low pulse on the RESETn input, a serial read of the Diagnostic 1 register with DSR = 0, or by a power-on reset. The VDS fault bit will only be reset by a serial read of the Diagnostic 1 register with DSR = 0 or by a power-on reset.

If FDSO = 0, care must be taken to avoid damage to the MOSFET where the VDS fault is detected. Although the MOSFET will be switched off as soon as the fault is detected at the end of the fault validation timeout, it is possible that it could still be damaged by excessive power dissipation and heating. To limit any damage to the external MOSFETs or the motor, the gate drive outputs should be fully disabled by logic inputs from the external controller.

## Fault Action

The action taken when one of the diagnostic functions indicates a fault is listed in Table 6.

When a fault is detected, a corresponding fault state is considered to exist. In some cases, the fault state only exists during the time the fault is detected. In other cases, when the fault is only detected for a short time, the fault state is latched (held in the fault state) until reset. The faults that are latched are indicated in Table 6. Latched fault states are always reset when a power-on-reset state is present or when the associated fault bit is read through the serial interface with DSR = 0. Any fault bits that have been set in the diagnostic registers are only reset when a power-on-reset state is present or when the associated fault bit is read through the serial interface with DSR = 0.

For most of the diagnostic functions, the action taken when a fault state is detected can be programmed to force the gate drive output into the inactive (low) state or to leave them active. The action is selected by setting a 1 or 0 in the specific stop on fault (SoF) bit associated with the diagnostic. The specific SoF bits for each diagnostic and the actions taken for each setting are listed in Table 6.

If a power-on-reset state is detected, all gate drive outputs are driven low and all MOSFETs in the bridge are held in the off state. This persists until the power-on-reset state is cleared.

Setting any of the FVRU, FVSU, FOT, FLSS, or FGSU bits in the Stop-on-Fault registers to 0 such that the gate drive outputs are not disabled in the event of the corresponding fault being detected means that the AMT49100 will not take any action to

protect itself or the external bridge MOSFETs and damage may occur. Setting either FVBU or FDSO bits in the Stop-on-Fault registers to 0 results in only the MOSFET on which the fault is detected being turned off for a single PWM cycle. This means that the AMT49100 only takes limited action to protect itself and the external bridge MOSFET and damage may still occur in some circumstances. In all cases appropriate action must be taken by the external controller.

**Table 6: Fault Actions**

| Fault Description          | SoF Bit Name | Disable Outputs |             | Fault State Latched |
|----------------------------|--------------|-----------------|-------------|---------------------|
|                            |              | SoF Bit = 0     | SoF Bit = 1 |                     |
| No Fault                   | –            | No              |             | –                   |
| Power-On-Reset             | –            | Yes [1]         |             | No                  |
| Buck Regulator Fault       | –            | –               | –           | –                   |
| VREG Undervoltage          | FVRU         | No [3]          | Yes [1]     | No                  |
| VIO Undervoltage           | FVLU         | No              | Yes [1]     | No                  |
| Bootstrap Undervoltage     | FVBU         | Yes [2][3]      | Yes [1]     | Yes                 |
| Logic Terminal Overvoltage | FVLO         | No              | Yes [1][4]  | No                  |
| ENABLE WD Timeout          | FEWD         | No              | Yes [1]     | No                  |
| Overtemperature            | FOT          | No [3]          | Yes [1]     | No                  |
| LSS Disconnect             | FLSS         | No [3]          | Yes [5]     | No [5]              |
| VDS Fault                  | FDSO         | Yes [2][3]      | Yes [1]     | Yes                 |
| Serial Transmission Error  | FSE          | No              | Yes [1]     | No                  |
| VREG Overvoltage           | FVRO         | No              | Yes [1]     | No                  |
| VBRG Undervoltage          | FVSU         | No [3]          | Yes [1]     | No                  |
| VBRG Overvoltage           | FVSO         | No              | Yes [1]     | No                  |
| VGS Undervoltage           | FGSU         | No [3]          | Yes [1]     | Yes                 |
| Temperature Warning        | FTW          | No              | Yes [1]     | No                  |
| Overcurrent                | FOC          | No              | Yes [1]     | Yes                 |
| Open Load                  | –            | No              | No          | No                  |
| EEPROM                     | –            | Yes [1]         | Yes [1]     | Yes                 |

[1] All gate drives low, all MOSFETs off.

[2] Gate drive for the affected MOSFET low, only the affected MOSFET off.

[3] Stated fault condition may damage the AMT49100 and/or bridge MOSFETs unless appropriate action taken by the external controller.

[4] Outputs disabled on Hx, Lx, ENABLE overvoltage, but not on RESETn, DIAG overvoltage.

[5] Creates VDS fault. VDS fault will be latched but LSS disconnect fault will not.

## Fault Masks

Individual diagnostics except power-on reset, EEPROM error, serial transmission error, overtemperature, open-load, and over-current can be disabled by setting the corresponding bit in the mask registers. Power-on-reset cannot be disabled because the diagnostics and the output control depend on the logic regulator for the internal logic to operate correctly. If a bit is set to one in the mask registers, then the corresponding diagnostic will be completely disabled. No fault states for the disabled diagnostic will be generated, and no fault flags or diagnostic bits will be set. See Mask Register definition for bit allocation.

Care must be taken when diagnostics are disabled to avoid potentially damaging conditions.

## Diagnostic and System Verification

To comply with various aspects of safe system design, it is necessary for higher-level safety systems to verify that any diagnostics or functions used to guarantee safe operation are operating within specified tolerances.

There are four basic aspects to verification of diagnostic functions:

- Verify connections
- Verify comparators
- Verify thresholds
- Verify fault propagation

These must be completed for each diagnostic. In addition, the operation of system functions not directly covered by diagnostics should also be verified.

The AMT49100 includes additional verification functions to help the system design comply with any safety requirements. Many of these functions can only be completed when the diagnostics are not required and must be commanded to run by the main system controller. These functions are referred to “off-line” verification.

A few of the functions can be continuously active but the results must be checked by the main system controller on a regular basis. These functions are referred to “on-line” verification.

The frequency with which these off-line verification functions are run, or on-line verifications results are checked, will depend on the safety requirements of the system using the AMT49100.

**Table 7: Verification Functions**

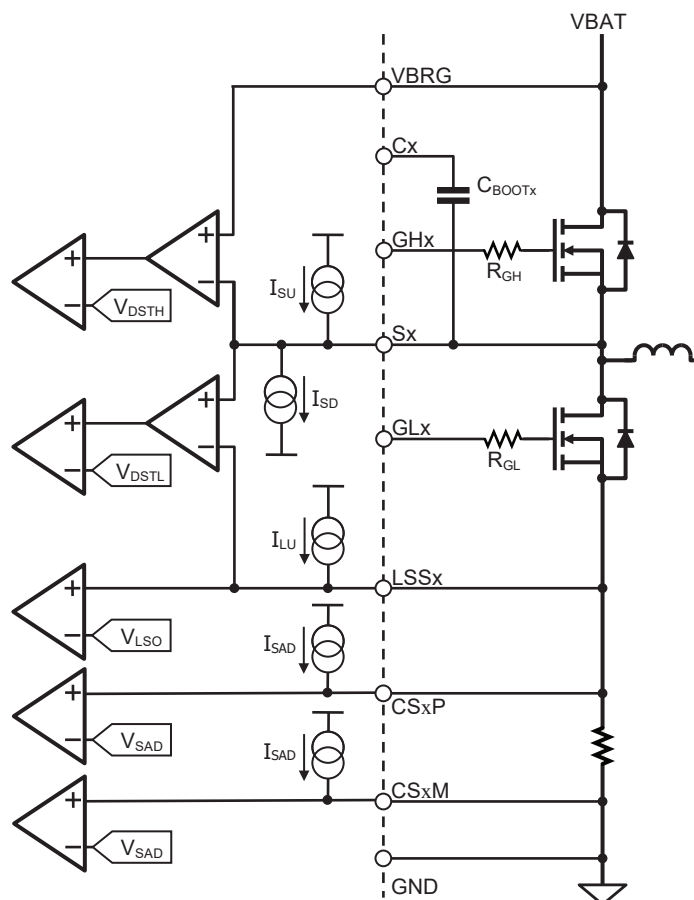
| Verification Type | Function Verified          | Operation |        |
|-------------------|----------------------------|-----------|--------|
|                   |                            | Offline   | Online |
| Connection        | Phase Connection           | Y         |        |
| Connection        | Sense Amp Connection       |           | Y      |
| Monitor           | ENABLE Watchdog            | Y         |        |
| Monitor           | Over Current Detectors     | Y         |        |
| Monitor           | Phase State Monitor        |           | Y      |
| Diagnostic        | LSS Connection             | Y         |        |
| Diagnostic        | Overtemperature            | Y         |        |
| Diagnostic        | Temperature Warning        | Y         |        |
| Diagnostic        | VBRG Undervoltage          | Y         |        |
| Diagnostic        | VBRG Overvoltage           | Y         |        |
| Diagnostic        | VREG Diagnostics           | Y         |        |
| Diagnostic        | Bootstrap Capacitor        | Y         |        |
| Diagnostic        | VIO Undervoltage           | Y         |        |
| Diagnostic        | VGS Undervoltage           | Y         |        |
| Diagnostic        | Logic Terminal Diagnostic  | Y         |        |
| Diagnostic        | Open Load Detectors        | Y         |        |
| Diagnostic        | VDS Overvoltage Diagnostic | Y         |        |
| Diagnostic        | All Gate Drives Off        | Y         |        |

## On-Line Verification

The following functions are permanently active and will set the appropriate bit in the verification result registers to indicate that the verification has failed. No other action will be taken by the AMT49100. These verification functions verify that certain of the AMT49100 terminals are correctly connected to the power bridge circuit.

### Bridge: Phase State Monitor

The bridge phase connections at the SA, SB, and SC terminals are connected to a variable threshold comparator. The output of the comparator is stored in the SAS, SBS, and SCS phase state bits in the Verify Result 1 register, to provide a logic level monitor of the state of the power bridge outputs to the load (logic 1 indicating the voltage on SA, SB, and SC respectively is more positive than the threshold). Additionally, the comparator outputs are made available as discrete logic signals on the SAL, SBL, and SCL terminals (logic high indicating the voltage on SA, SB, and SC respectively, is more positive than the threshold). The threshold for the three comparators,  $V_{PT}$ , is generated, as a ratio of the voltage between the VBRG terminal and the GND terminal, by a 6-bit DAC and determined by the contents of the VPT[5:0] variable. VPT is approximately defined as:



**Figure 10: Bridge Terminal Connection Verification**

$$V_{PT} = (n / 64) \times V_{BRG}$$

where n is a positive integer defined by VPT[5:0].

$V_{PT}$  can be programmed between 0 and 98.4% $V_{BRG}$ .

### Sense Amplifier Disconnect

Each sense amplifier includes continuous current sources,  $I_{SAD}$ , that will allow detection of an input open circuit condition. If an input open circuit occurs, the voltage rises above the sense amplifier open-load detect threshold,  $V_{SAD}$ , and the S1D, S2D, or S3D bit is set in the Verify Result 1 register depending upon the sense amplifier affected. Note that the net current observable at the device CSxP and CSxM pins is the sum of  $I_{SAD}$  and other internal bias currents associated with the current sense amplifier input and is defined by the  $I_{BIAS}$  parameter in the Current Sense Amplifier section of the Electrical Characteristics table.

## Off-Line Verification

The following functions are only active when commanded by setting the appropriate bit in the verification command registers in addition to any required gate drive commands. If the function only verifies a connection, then a fail will set the appropriate bit in the verification result register. No other action will be taken by the AMT49100. If the function is to verify one of the diagnostic circuits in the AMT49100, then the verification is completed by checking that the associated fault bit is set in the diagnostic registers.

### Bridge: Phase Disconnected

The connections from each Sx terminal to the corresponding common node of the high-side MOSFET source and low-side MOSFET drain are verified individually by a combination of MOSFET commands and test currents. The connection to all MOSFETs must be checked to fully verify the connection for each phase.

Connection to each high-side MOSFET is tested by first turning it on using the logic inputs or the serial interface. Other high-side MOSFETs and all low-side MOSFETs must be turned off to avoid corrupting the test result.

The phase to be tested is selected by the value in the verify phase select variable, YPS: 0 for phase B, 1 for phase A, and 2 for phase C. The value of 3 is reserved for open-load testing.

In addition, the bootstrap charge pump must be switched to low current source by setting the charge pump mode variable, CPM, to 1. This is to avoid any unnecessary dissipation in the pump regulator during testing. A pull-down current,  $I_{SD}$ , is then switched on by setting YSK to 1 in order to pull the phase low if the high-side MOSFET is either disconnected or not switched on.  $I_{SD}$  is typically 2.5 mA, which is low enough to allow the AMT49100 to survive a short to VBB on the SB terminal without damage, and high enough to discharge any output capacitance in an acceptable time.

The high-side VDS monitors are used to determine the state of the phase connection by comparing the VDS voltage of the high-side MOSFET, measured between VBRG and Sx with the programmed high-side VDS threshold,  $V_{DSTH}$ .

Test timing is not controlled by the AMT49100 and must be managed by the external controller using the phase disconnect verify command bit, YPH.

Phase disconnect detect relies upon there being no residual current in the load or the bridge and time must be allowed for Sx terminal voltages to stabilize prior to completion of the test.

YPH is taken high to initiate the test and should be held in this state until it is known that any residual energy has dissipated, giving the sink current,  $I_{SD}$ , time to pull the Sx terminal to ground in the case of a phase disconnect. At the end of this period, YPH should be set to 0. The PxD bit will then be 1 if the phase is connected and the MOSFET is on and 0 if the phase is disconnected or the MOSFET is off. The PxD bit is reset when the state of the PxD bit is determined by reading the Verify Result 0 register. The value of the PxD bit is not valid when YPH is high.

The low-side disconnect test is complementary to the high-side test. Connection to each low-side MOSFET is tested by first turning it on using the logic inputs or the serial interface. Other low-side MOSFETs and all high-side MOSFETs must be turned off to avoid corrupting the test result.

The phase to be tested is selected by the value in the verify phase select variable, YPS: 0 for phase B, 1 for phase A, and 2 for phase C. The value of 3 is reserved for open-load testing.

In addition, the bootstrap charge pump must be set to normal operation by setting the charge pump mode variable, CPM, to 0.

A pull-up current,  $I_{SU}$ , is provided in order to pull the phase high if the low-side MOSFET is either disconnected or not switched on. It is recommended that the value of  $I_{SU}$  is switched to  $-410\ \mu\text{A}$  by setting the YSC bit to 1 when performing phase disconnect tests. This allows  $I_{SU}$  to charge any output capacitances in an acceptable time. YSK must be set to 0 during low-side disconnect tests.

The low-side VDS monitors are used to determine the state of the phase connection by comparing the VDS voltage of the low-side MOSFET, measured between Sx and LSSx with the programmed low-side VDS threshold,  $V_{DSTL}$ .

Test timing is not controlled by the AMT49100 and must be managed by the external controller using the phase disconnect verify command bit, YPL.

Phase disconnect detect relies upon there being no residual current in the load or the bridge and time must be allowed for Sx terminal voltages to stabilize prior to completion of the test.

YPL is taken high to initiate the test and should be held in this state until it is known that any residual energy has dissipated, giving the source current,  $I_{SU}$ , time to pull the Sx terminal to VBRG in the case of a phase disconnect. At the end of this period, YPL should be set to 0. The PxD bit will then be 1 if the phase is connected and the MOSFET is on and 0 if the A phase is disconnected or the MOSFET is off. The PxD bit is reset when the state of the PxD bit is determined by reading the Verify Result 0 register. The value of the PxD bit is not valid when YPL is high.

**Verify: VREG Undervoltage**

The VREG undervoltage detector is verified by setting the YRU bit in the Verify Command 0 register to 1. This applies a voltage to the comparator that is lower than the undervoltage threshold and should cause the general fault flag to be active and a VREG undervoltage fault bit, VRU, to be latched in the Diagnostic 1 register. When YRU is reset to 0, the general fault flag will be cleared and the VRU bit will remain set in the Diagnostic 1 register until reset. If the VRU bit is not set, then the verification has failed.

**Verify: VREG Overvoltage**

The VREG overvoltage detector is verified by setting the YRO bit in the Verify Command 0 register to 1. This applies a voltage to the comparator that is higher than the overvoltage threshold and should cause the general fault flag to be active and a VREG overvoltage fault bit, VRO, to be latched in the Diagnostic 1 register. When YRO is reset to 0, the general fault flag will be cleared and the VRO bit will remain set in the Diagnostic 1 register until reset. If the VRO bit is not set, then the verification has failed.

**Verify: VIO Undervoltage**

The VIO undervoltage detector is verified by setting the YLU bit in the Verify Command 1 register to 1. This applies a voltage to the comparator that is lower than the undervoltage threshold and should cause the VIO undervoltage fault bit, VLU, to be latched in the Status register. When YLU is reset to 0, the VLU bit will remain set in the Status register until reset. If the VLU bit is not set, then the verification has failed.

**Verify: Temperature Warning**

The temperature warning detector is verified by setting the YTW bit in the Verify Command 2 register to 1. This applies a voltage to the comparator that is lower than the temperature warning threshold and should cause the general fault flag to be active and a temperature warning fault bit, TW, to be latched in the Status register. When YTW is reset to 0, the general fault flag will be cleared and the TW bit will remain set in the Status register until reset. If the TW bit is not set, then the verification has failed.

**Verify: Overtemperature**

The overtemperature detector is verified by setting the YOT bit in the Verify Command 2 register to 1. This applies a voltage to the comparator that is lower than the overtemperature threshold and should cause the general fault flag to be active and an overtem-

perature fault bit, OT, to be latched in the Status register. When YOT is reset to 0, the general fault flag will be cleared and the overtemperature fault will remain in the Status register until reset. If the OT bit is not set, then the verification has failed.

**Verify: VBRG Supply Overvoltage**

The VBRG overvoltage detector is verified by setting the YSO bit in the Verify Command 0 register to 1. This applies a voltage to the comparator that is higher than the VBRG overvoltage threshold and should cause the general fault flag to be active and a VBRG overvoltage fault bit, VSO, to be latched in the Diagnostic 2 register. When YSO is reset to 0, the general fault flag will be cleared and the VSO bit will remain set in the Diagnostic 2 register until reset. If the VSO bit is not set, then the verification has failed.

**Verify: VBRG Supply Undervoltage**

The VBRG undervoltage detector is verified by setting the YSU bit in the Verify Command 0 register to 1. This applies a voltage to the comparator that is lower than the VBRG undervoltage threshold and should cause the general fault flag to be active and a VBRG undervoltage fault bit, VSU, to be latched in the Diagnostic 2 register. When YSU is reset to 0, the general fault flag will be reset and the VSU bit will remain set in the Diagnostic 2 register until cleared. If the VSU bit is not set, then the verification has failed.

**Verify: VGS Undervoltage**

The VGS undervoltage detectors can be verified individually or in two groups, high-side and low-side. The detectors are verified by switching on the required MOSFET using the serial Control register bits or the logic input terminals and then setting the YGU bit in the Verify Command 0 register to 1. This applies a voltage that is lower than the VGS undervoltage threshold to the active comparator and should cause a VGS undervoltage fault to be latched in the corresponding VGS undervoltage fault bit in the Diagnostic 0 register. (For example, the CHU bit should be set after the CH bit is set in the Control register or the HC input is driven high, etc.) After a period exceeding the programmed VGS qualification time plus a dead time,  $t_{VDQ} + t_{DEAD}$ , YGU must be returned to 0 and all gate drives must be commanded off. The general fault flag will remain active and the VGS undervoltage fault bits will remain in the Diagnostic 0 register until reset. This must be repeated until all MOSFETs have been switched to verify all VGS undervoltage comparators. If any VGS fault bit is not set after all MOSFETs have been switched, then the verification has failed for the corresponding comparator.

**Verify: Bootstrap Capacitor Undervoltage Fault**

The bootstrap capacitor undervoltage detectors are verified by setting the YBU bit in the Verify Command 0 register to 1. This applies a voltage that is lower than the bootstrap undervoltage threshold to each of the three bootstrap circuit detectors and should cause the general fault flag to be active and a bootstrap undervoltage fault to be latched in the corresponding bootstrap undervoltage fault bits (VA, VB, VC) in the Diagnostic 2 register.

When YBU is reset to 0, the states of the bootstrap fault bits are latched into the Diagnostic 2 register. If any of the bootstrap fault bits is not set, then the verification of the corresponding detector has failed. All bootstrap fault bits and the general fault flag are cleared when the Diagnostic 2 register is read.

**Verify: MOSFET VDS Overvoltage Fault**

The VDS overvoltage detectors can be verified individually or in two groups: high-side and low-side. The detectors are verified by commanding the intended MOSFETs to turn on using the serial command register bits or the logic input terminals and then setting the YDO bit in the Verify Command 0 register to 1. This applies a voltage that is higher than the VDS overvoltage threshold to any active detector by turning on the complementary MOSFET in the same phase (rather than the commanded MOSFET) to pull the Sx node toward VBB (low-side verification) or LSSx (high-side verification). In response, a VDS overvoltage fault should be latched in the corresponding VDS overvoltage fault bit in the Diagnostic 1 register. (For example, the CHO bit should be set after the CH bit is set in the Control register or the HC input is set to turn on the GHC output, etc.)

After a period exceeding the programmed VDS qualification time plus a dead time,  $t_{VDQ} + t_{DEAD}$ , the YDO bit must be returned to 0 to exit the verification mode. Diag 1 should then be read to inspect and clear the xLO, xHO bits. This must be repeated until all MOSFETs have been switched to verify all VDS overvoltage comparators. If any VDS overvoltage fault bit has not been set after all MOSFETs have been commanded on, then the verification has failed for the corresponding comparator.

**Verify: LSS Disconnect**

The LSS disconnect detectors are verified by setting the YLS bit in the Verify Command 2 register to 1. This applies a voltage to each LSS open comparator that is greater than the LSS open threshold and should cause the LSS open fault bits, LAD, LBD, and LCD, to be latched in the Diagnostic 0 register. When YLS is reset to 0, the open fault bits will remain set in the Diagnostic 1 register until reset. If the any LSS open fault bits, LAD, LBD, and LCD is not set, then the verification has failed.

**Verify: Logic Terminal Overvoltage**

The logic overvoltage detector is verified by setting the YLO bit in the Verify Command 0 register to 1. This applies a voltage to the comparators associated with each relevant logic terminal that is higher than the logic input overvoltage warning,  $V_{LOV}$ . Consequently, the input overvoltage fault bit, VLO, in the Status register should be set. To complete the verification, the YLO bit should be set to 0 and the state of the VLO bit should then be read from the Status register. If the VLO bit is set to 1, then the verification has passed, and if set to 0, then it has failed. During the period when YLO is set to 1, the general fault flag may be active and the gate drive outputs may be disabled but neither of these conditions indicates a successful logic input voltage verification.

**Verify: Overcurrent Detect and Sense Amplifier**

The overcurrent detector is verified by setting the YOC bit in the Verify Command 1 register to 1. This forces the output of each sense amplifier to positive full-scale which can then be measured. The sense amplifier outputs remain connected to the overcurrent comparators and the full-scale output applies a voltage to the comparator that is higher than the overcurrent threshold and should cause the overcurrent fault bits, OC1, OC2, and OC3 to be latched in the Diagnostic 2 register. When YOC is reset to 0, the sense amplifier outputs will return to normal operation and the OC1, OC2, and OC3 bits will remain set in the Diagnostic 2 register until reset. If any of the OC1, OC2, or OC3 bits are not set, then the verification has failed for the corresponding comparator.

During verification of the overcurrent detector, the overcurrent threshold voltage,  $V_{OCT}$ , set by OCT[3:0], plus any offset,  $V_{OOS}$ , set by SAO[3:0] must not exceed the positive extreme of the sense amplifier output dynamic range of 4.8 V. If it does, then the OC1, OC2, and OC3 bits may not be set and the verification may fail.

**Verify: ENABLE Watchdog Timeout**

The ENABLE watchdog timeout is verified by setting the EWD bit to 1 to select the watchdog mode and then changing the state of the ENABLE input. This change of state will enable the gate drive outputs under command from the corresponding phase control signals and will start the watchdog timer. The ENABLE input must then be held in this state. At the end of the timeout period,  $t_{ETO}$ , the ETO bit should be set in the status register. If the ETO bit is not set then the verification has failed.

***Verify: All Gate Drives Off***

The successful propagation of control inputs demanding all-gate-drives-off to the gate drive outputs is verified by setting up an appropriate input condition and inspecting the GDO bit in the Verify Result 1 register. If the input condition has successfully turned off all six gate drives the GDO bit is set. The control input conditions (i.e the combinational states of Hx, Lx, xH, xL, HSI, LSI, and ENABLE) that demand all outputs off (GHx = L, GLx = L) and hence set the GDO bit as a result of a successful verification test can be determined by inspection of Tables 1 – 3. If the ENABLE watchdog mode is selected (EWD = 1) and the watchdog timeout is allowed to expire, the GDO bit will similarly be set as the result of a successful test. Verification of propagation from an appropriate combination of phase logic inputs (Hx, Lx) and serial register bits (xH, xL) to the gate drive outputs does not verify propagation from the ENABLE input to the gate drive outputs and vice versa. Gate drive off events are not latched in the Verify Result 1 register and the GDO bit returns to 0 as soon as any gate drive is detected to be in the on state.

***Verify: On-State Open-Load Detection and Sense Amplifier***

The on-state open-load detector is verified by turning on a low-side gate drive (to select a phase for test) and at least one high-side (on a different phase), setting the activate open load detection bit, AOL, to 1 and then setting the open-load verify bit, YOL to 1. For this verification operation, sense amplifier 1 is verified by turning on phase A low-side, sense amplifier 2 by turning on phase B low-side and sense amplifier 3 by turning on phase C low-side. Turning on the low-side forces the output of the sense amplifier associated with the selected phase to its zero current output condition (equivalent to zero differential input), which then drives the open-load comparator with a voltage that is lower than the comparator's threshold and produces an on-state open-load fault after the open-load timeout.

When YOL is first set to 1, any open load faults are cleared and the open-load timer is reset. At the end of a 100 ms timeout period, if an open-load state has successfully been detected, the YOL bit is reset to indicate that the timeout is complete and the OL and LDF bits should be inspected. If both bits are set the verification has been successful. The OL bit and the LDF bit remain latched until reset. After a period of 102 ms from YOL being set to 1, if an open-load state has not been successfully detected, the YOL bit is reset by the AMT49100. If YOL is reset to 0 before the timeout has completed, then the verification is terminated without setting any fault bits. All three phases must be tested separately to complete the verification.

## SERIAL INTERFACE

Table 8: Serial Register Definition\*

|                       | 15 | 14 | 13 | 12 | 11 | 10 | 9    | 8     | 7     | 6     | 5     | 4     | 3     | 2     | 1     | 0 |
|-----------------------|----|----|----|----|----|----|------|-------|-------|-------|-------|-------|-------|-------|-------|---|
| 0: Bridge Timing      | 0  | 0  | 0  | 0  | 0  | WR |      | OCQ   | DT6   | DT5   | DT4   | DT3   | DT2   | DT1   | DT0   | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 1     | 0     | 0     | 0     | 0     | 0     |   |
| 1: Bridge Monitor     | 0  | 0  | 0  | 0  | 1  | WR | OCT3 | OCT2  | OCT1  | OCT0  | TOC4  | TOC3  | TOC2  | TOC1  | TOC0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 1     | 0     | 0     | 1     | 1     | 1     | 1     |   |
| 2: VDS Qualifier      | 0  | 0  | 0  | 1  | 0  | WR | VDQ  |       |       | TVD5  | TVD4  | TVD3  | TVD2  | TVD1  | TVD0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 1     | 0     | 0     | 0     | 0     |   |
| 3: Bridge Diagnostics | 0  | 0  | 0  | 1  | 1  | WR | VPO  |       |       | VTL5  | VTL4  | VTL3  | VTL2  | VTL1  | VTL0  | P |
|                       |    |    |    |    |    |    | 1    | 0     | 0     | 0     | 1     | 1     | 0     | 0     | 0     |   |
| 4: Bridge Diagnostics | 0  | 0  | 1  | 0  | 0  | WR |      |       |       | VTH5  | VTH4  | VTH3  | VTH2  | VTH1  | VTH0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 1     | 1     | 0     | 0     | 0     |   |
| 5: Bridge Monitor     | 0  | 0  | 1  | 0  | 1  | WR | AOL  |       |       | VPU   |       | OLT3  | OLT2  | OLT1  | OLT0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 1     | 0     | 0     | 0     |   |
| 6: Bridge Monitor     | 0  | 0  | 1  | 1  | 0  | WR | EWD  |       |       | VPT5  | VPT4  | VPT3  | VPT2  | VPT1  | VPT0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 1     | 0     | 0     | 0     | 0     | 0     |   |
| 7: System             | 0  | 0  | 1  | 1  | 1  | WR | VIO  | VCL   | BRE   | CPM1  | CPM0  | DSR   |       | DG1   | DG0   | P |
|                       |    |    |    |    |    |    | 0/1† | 0/1†  | 0/1†  | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 8: HS Drive Timing    | 0  | 1  | 0  | 0  | 0  | WR |      | THR3  | THR2  | THR1  | THR0  | THF3  | THF2  | THF1  | THF0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 9: HS Drive Current   | 0  | 1  | 0  | 0  | 1  | WR |      | IHR13 | IHR12 | IHR11 | IHR10 | IHF13 | IHF12 | IHF11 | IHF10 | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 10: HS Drive Current  | 0  | 1  | 0  | 1  | 0  | WR |      | IHR23 | IHR22 | IHR21 | IHR20 | IHF23 | IHF22 | IHF21 | IHF20 | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 11: LS Drive Timing   | 0  | 1  | 0  | 1  | 1  | WR |      | TLR3  | TLR2  | TLR1  | TLR0  | TLF3  | TLF2  | TLF1  | TLF0  | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 12: LS Drive Current  | 0  | 1  | 1  | 0  | 0  | WR |      | ILR13 | ILR12 | ILR11 | ILR10 | ILF13 | ILF12 | ILF11 | ILF10 | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 13: LS Drive Current  | 0  | 1  | 1  | 0  | 1  | WR |      | ILR23 | ILR22 | ILR21 | ILR20 | ILF23 | ILF22 | ILF21 | ILF20 | P |
|                       |    |    |    |    |    |    | 0    | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |

\* Power-on reset value shown below each input register bit.

† Factory set power-on reset value is 1 on AMT49100KJPTR-A-3, AMT49100KJPTR-A-5, and 0 on AMT49100KJPTR-B-3, AMT49100KJPTR-B-5.

‡ Factory set power-on reset value is 1 on AMT49100KJPTR-A-5, AMT49100KJPTR-B-5, and 0 on AMT49100KJPTR-A-3, AMT49100KJPTR-B-3.

Continued on the next page...

**Table 8: Serial Register Definition\***

|                      | 15 | 14 | 13 | 12 | 11 | 10 | 9    | 8    | 7    | 6    | 5    | 4    | 3    | 2    | 1    | 0 |
|----------------------|----|----|----|----|----|----|------|------|------|------|------|------|------|------|------|---|
| 14: Sense Amp Offset | 0  | 1  | 1  | 1  | 0  | WR | S3C  | S2C  | S1C  |      |      | SAO3 | SAO2 | SAO1 | SAO0 | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 1    | 1    | 1    | 1    |   |
| 15: Sense Amp Gain   | 0  | 1  | 1  | 1  | 1  | WR | S3G2 | S3G1 | S3G0 | S2G2 | S2G1 | S2G0 | S1G2 | S1G1 | S1G0 | P |
|                      |    |    |    |    |    |    | 0    | 1    | 0    | 0    | 1    | 0    | 0    | 1    | 0    |   |
| 16: NVM Write        | 1  | 0  | 0  | 0  | 0  | WR | SAV1 | SAV0 |      |      |      |      |      |      |      | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 18: Stop on Fault 0  | 1  | 0  | 0  | 1  | 0  | WR | FOT  | FTW  |      | FLSS |      | FSE  | FVLU | FVLO | FEWD | P |
|                      |    |    |    |    |    |    | 1    | 1    | 0    | 0    | 0    | 1    | 1    | 1    | 1    |   |
| 19: Stop on Fault 1  | 1  | 0  | 0  | 1  | 1  | WR | FOC  |      | FDSO | FGSU | FVBU | FVRO | FVRU | FVSO | FVSU | P |
|                      |    |    |    |    |    |    | 1    | 0    | 1    | 1    | 1    | 1    | 1    | 1    | 1    |   |
| 20: Verify Command 0 | 1  | 0  | 1  | 0  | 0  | WR |      | YDO  | YRO  | YRU  | YBU  | YLO  | YSO  | YSU  | YGU  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 21: Verify Command 1 | 1  | 0  | 1  | 0  | 1  | WR | YPH  | YPL  | YOC  | YLU  | YOL  | YPS1 | YPS0 | YSK  | YSC  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 22: Verify Command 2 | 1  | 0  | 1  | 1  | 0  | WR | YTW  | YOT  |      | YLS  |      |      |      |      |      | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 23: Verify Result 0  | 1  | 0  | 1  | 1  | 1  | 0  | PCD  | PBD  | PAD  | CHM  | CLM  | BHM  | BLM  | AHM  | ALM  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 24: Verify Result 1  | 1  | 1  | 0  | 0  | 0  | 0  |      |      | GDO  | SCS  | SBS  | SAS  | S3D  | S2D  | S1D  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 1    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 25: Mask 0           | 1  | 1  | 0  | 0  | 1  | WR | LCD  | LBD  | LAD  | CHU  | CLU  | BHU  | BLU  | AHU  | ALU  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 26: Mask 1           | 1  | 1  | 0  | 1  | 0  | WR | VRO  | VRU  | VBR  | CHO  | CLO  | BHO  | BLO  | AHO  | ALO  | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |
| 27: Mask 2           | 1  | 1  | 0  | 1  | 1  | WR | VS   | VLO  | BSU  | TW   | VLU  |      |      |      |      | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |

\*Power-on reset value shown below each input register bit.

Continued on the next page...

**Table 8: Serial Register Definition\***

|                     | 15 | 14  | 13 | 12 | 11 | 10 | 9   | 8   | 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0 |
|---------------------|----|-----|----|----|----|----|-----|-----|-----|-----|-----|-----|-----|-----|-----|---|
| 28: Diagnostic<br>0 | 1  | 1   | 1  | 0  | 0  | 0  | LCD | LBD | LAD | CHU | CLU | BHU | BLU | AHU | ALU | P |
|                     |    |     |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| 29: Diagnostic<br>1 | 1  | 1   | 1  | 0  | 1  | 0  | VRO | VRU | VBR | CHO | CLO | BHO | BLO | AHO | ALO | P |
|                     |    |     |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| 30: Diagnostic<br>2 | 1  | 1   | 1  | 1  | 0  | 0  | VC  | VB  | VA  | VSO | VSU | OC3 | OC2 | OC1 | OL  | P |
|                     |    |     |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| 31: Control         | 1  | 1   | 1  | 1  | 1  | WR | HSI | LSI |     | CH  | CL  | BH  | BL  | AH  | AL  | P |
|                     |    |     |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| Status              | FF | POR | SE | EE | OT | TW | VS  | VLO | ETO | VR  | VLU | LDF | BSU | GSU | DSO | P |
|                     | 1  | 1   | 0  | 0  | 0  | 0  | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

A three-wire synchronous serial interface, compatible with SPI, is used to control the features of the AMT49100. The SDO terminal can be used, during a serial transfer, to provide diagnostic feedback and readback of the register contents.

The AMT49100 can be operated without the serial interface using the default settings and the logic control inputs; however, application-specific configurations and several verification functions are only possible by setting the appropriate register bits through the serial interface. In addition to setting the configuration bits, the serial interface can also be used to control the bridge MOSFETs directly.

The serial interface timing requirements are specified in the electrical characteristics table and illustrated in Figure 3. Data is received on the SDI terminal and clocked through a shift register on the rising edge of the clock signal input on the SCK terminal. STRn is normally held high and is only brought low to initiate a serial transfer. No data is clocked through the shift register when STRn is high, allowing multiple slave units to use common SDI and SCK connections. Each slave then requires an independent STRn connection. The SDO output assumes a high-impedance state when STRn is high, allowing a common data readback connection.

After 16 data bits have been clocked into the shift register, STRn must be taken high to latch the data into the selected register. When this occurs, the internal control circuits act on the new data and the registers are reset depending on the type of transfer and the state of the DSR bit.

If there are more than 16 rising edges on SCK or if STRn goes high, and there are fewer than 16 rising edges on SCK (either being described as a framing error), the write will be cancelled without latching data to the register. The read-only registers, Status, Diagnostic, or Verification Result will not be reset.

The first five bits, D[15:11], in a serial word are the register address bits giving the possibility of 32 register addresses. The sixth bit, WR (D[10]), is the write/read bit. Except for the read-only registers, when WR is 1 the following 9 bits, D[9:1], clocked in from the SDI terminal are written to the addressed register. When WR is 0 the following 9 bits, D[9:1], clocked in from the SDI terminal are ignored, no data is written to the serial registers and the contents of the addressed register are clocked out on the SDO terminal.

The last bit in any serial transfer, D[0], is a parity bit that is set to ensure odd parity in the complete 16-bit word. Odd parity means that the total number of 1s in any transfer should always be an odd number. This ensures that there is always at least one bit set to 1 and one bit set to 0 and allows detection of stuck-at faults on the serial input and output data connections. The parity bit is not stored but generated on each transfer.

In addition to the addressable registers, a read-only status register is output on SDO for all register addresses when WR is set to 1. For all serial transfers, the first six bits output on SDO will always be the first six bits from the status register. Register data is output on the SDO terminal msb first while STRn is low and changes to the next bit on each falling edge of SCK. The first bit, which is always the FF bit from the status register, is output as soon as STRn goes low.

Registers 20-24 and 28-30 contain verification results and diagnostic fault indicators and are read only. If the WR bit for these registers is set to 1 then the data input through SDI is ignored and the contents of the status register is clocked out on the SDO terminal then reset as for a normal write. No other action is taken. If the WR bit for these registers is set to 0 then the data input through SDI is ignored and the contents of the addressed register is clocked out on the SDO terminal and the addressed register is reset when DSR = 0.

If a framing error is detected and/or the parity of any received transfer is even rather than odd the SE bit is set in the Status register to indicate a data transfer error. Any data write will be cancelled without latching data to the register and read-only registers will not be reset. This fault condition can be cleared by a subsequent valid serial write or by a power-on-reset.

In some systems, it is preferable to be able to read the status or diagnostic registers without causing a reset and allowing the AMT49100 to re-enable the outputs. The DSR (Disable Serial Reset) bit provides this functionality. When DSR is set to one any valid read of any of the read only registers will not result in that register being reset. When DSR = 0, any valid read of any of the read only registers will reset the content of that register. This provides a way for the external controller to access the diagnostic information without automatically re-enabling any outputs but retains a way to reset the faults under control of the controller.

## Configuration Registers

Seventeen registers are used to configure the operating parameters of the AMT49100.

### Register 0: Bridge timing settings:

- OCQ, selects the overcurrent time qualifier mode, blank or debounce.
- DT[6:0], a 7-bit integer to set the dead time,  $t_{DEAD}$ , in 50 ns increments.

### Register 1: Bridge monitor setting:

- OCT[3:0], a 4-bit integer to set the overcurrent threshold voltage,  $V_{OCT}$ , in 300 mV increments.
- TOC[4:0], a 5-bit integer to set the overcurrent verification time,  $t_{OCQ}$ , in 500 ns increments.

### Register 2: VDS Qualifier:

- VDQ, selects the VDS and VGS qualifier mode, blank or debounce.
- TVD[5:0], a 6-bit integer to set the VDS and VGS fault qualification time,  $t_{VDQ}$ , in 100 ns increments.

### Register 3: Bridge diagnostic thresholds:

- VPO, selects the VBRG overvoltage threshold.
- VTL[5:0], a 6-bit integer to set the low-side drain-source threshold voltage,  $V_{DSTL}$ , in 50 mV increments.

### Register 4: Bridge diagnostic thresholds:

- VTH[5:0], a 6-bit integer to set the high-side drain-source threshold voltage,  $V_{DSTH}$ , in 50 mV increments.

### Register 5: Bridge monitor setting:

- AOL, Activate on-state open-load detection.
- VPU, selects VBRG undervoltage threshold.
- OLT[3:0], a 4-bit integer to set the open-load threshold voltage,  $V_{OLTH}$ , in 25 mV increments.

### Register 6: Bridge monitor setting:

- EWD, Activate ENABLE watchdog monitor.
- VPT[5:0], a 6-bit integer to set the phase comparator threshold voltage,  $V_{PT}$ , as a ratio of the bridge voltage,  $V_{BRG}$ , in 1.56% increments from 0 to 98.4%.

### Register 7: System:

- VIO, Selects Logic I/O voltage as 3.3 or 5 V.
- VCL, Selects Sense Amplifier Clamp voltage as 3.5 or 5.2 V.
- BRE, Buck regulator enabled/disabled bit.
- CPM[1:0], two bits to select the charge pump mode.
- DSR, disables reset on serial transfer.
- DG[1:0], a two-bit integer to select the signal output on the DIAG terminal.

### Register 8: High-side gate drive timing:

- THR[3:0], a 4-bit integer to set the high-side rising (GHx low-to-high) I1 Time in 16 ns increments.
- THF[3:0], a 4-bit integer to set the high-side falling (GHx high-to-low) I1 Time in 16 ns increments.

### Register 9: High-side gate drive current:

- IHR1[3:0], a 4-bit integer to set the high-side rising (GHx low-to-high) I1 Current in 16 mA increments.
- IHF1[3:0], a 4-bit integer to set the high-side falling (GHx high-to-low) I1 Current in 16 mA increments.

### Register 10: High-side gate drive current:

- IHR2[3:0], a 4-bit integer to set the high-side rising (GHx low-to-high) I2 Current in 16 mA increments.
- IHF2[3:0], a 4-bit integer to set the high-side falling (GHx high-to-low) I2 Current in 16 mA increments.

### Register 11: Low-side gate drive timing:

- TLR[3:0], a 4-bit integer to set the low-side rising (GLx low-to-high) I1 Time in 16 ns increments.
- TLF[3:0], a 4-bit integer to set the low-side falling (GLx high-to-low) I1 Time in 16 ns increments.

### Register 12: Low-side gate drive current:

- ILR1[3:0], a 4-bit integer to set the low-side rising (GLx low-to-high) I1 Current in 16 mA increments.
- ILF1[3:0], a 4-bit integer to set the low-side falling (GLx high-to-low) I1 Current in 16 mA increments.

### Register 13: Low-side gate drive current:

- ILR2[3:0], a 4-bit integer to set the low-side rising (GLx low-to-high) I2 Current in 16 mA increments.
- ILF2[3:0], a 4-bit integer to set the low-side falling (GLx high-to-low) I2 Current in 16 mA increments.

**Register 14: Sense amplifier offset:**

- S3C, S2C, S1C, initiates current sense amplifier input offset calibration.
- SAO[3:0], a 4-bit integer to set the sense amplifier offset of between 0 and 2.5 V.

**Register 15: Sense amplifier gain:**

- S1G[2:0], a 3-bit integer to set the sense amplifier 1 gain between 10 and 50 V/V.
- S2G[2:0], a 3-bit integer to set the sense amplifier 2 gain between 10 and 50 V/V.
- S3G[2:0], a 3-bit integer to set the sense amplifier 3 gain between 10 and 50 V/V.

**Register 16: NVM Write control:**

- SAV[1:0], Controls and reports saving the register contents to the NVM.

**Stop-On Fault Registers**

Two registers to control whether gate drive outputs are to remain enabled or be disabled in response to faults. See Diagnostics section for further detail of fault actions.

**Register 18: Stop on Fault 0:**

On bit per fault type to define stop on fault behavior for OT, TW, LCD, LBD, LAD, SE, VLU, VLO and EWD diagnostics.

**Register 19: Stop on Fault 1:**

On bit per fault type to define stop on fault behavior for OC, DSO, GSU, VBU, VRO, VRU, VSO and VSU diagnostics.

**Verification Registers**

Four registers are used to manage the system and diagnostic verification features.

**Register 20: Verify Command 0:**

Individual bits to initiate off-line verification tests for VDS, VREG, Bootstrap undervoltage, logic overvoltage, VBRG, and VGS diagnostics.

**Register 21: Verify Command 1:**

Individual bits to initiate off-line verification tests for phase disconnect, overcurrent, logic I/O undervoltage, and open-load diagnostics.

**Register 22: Verify Command 2:**

Individual bits to initiate off-line verification tests for TW, OT, and LSS disconnect diagnostics.

**Register 23: Verify Result 0 (read only):**

Individual bits holding the results of the phase disconnect, verification tests. When DSR = 0, these bits are reset on completion of a successful read of the register. This register also contains the gate drive output state for each MOSFET. These bits are captured at the start of each serial transmission.

**Register 24: Verify Result 1 (read only):**

Individual bits holding the results of phase state, sense amp and gate drive off verification tests. When DSR = 0, these bits are reset on completion of a successful read of the register.

**Diagnostic Registers**

In addition to the read-only status register, three read-only diagnostic registers provide detailed diagnostic management and reporting. When DSR = 0, any bits set in a diagnostic register are reset on completion of a successful read of that register. When DSR = 1, the register will not be reset. Reading one diagnostic register will not affect the fault bits in any other register. Reading the status register will not affect fault bits in any diagnostic register.

**Register 28: Diagnostic 0 (read only):**

Individual bits indicating faults detected in LSS disconnect for each phase and VGS undervoltage diagnostic monitors for each gate drive output.

**Register 29: Diagnostic 1 (read only):**

Individual bits indicating faults detected in VDS diagnostic monitors for each gate drive output, the VREG diagnostic monitors, and the buck regulator monitor.

**Register 30: Diagnostic 2 (read only):**

Individual bits indicating faults detected in bootstrap undervoltage, VBRG, overcurrent, and open-load diagnostic monitors.

**Mask Registers**

Three mask registers allow individual diagnostics to be disabled. If a bit is set to one in the mask registers, then the corresponding diagnostic will be completely disabled. No fault states for the disabled diagnostic will be generated, no fault flags or diagnostic bits will be set, and no action will be taken if the corresponding fault conditions are present.

**Register 25: Mask 0:**

Individual bits for each gate drive output to disable VGS diagnostic monitors and the LSS disconnect monitor for each phase.

## Register 26: Mask 1:

Individual bits to disable VDS diagnostic monitors for each gate drive output, the VREG monitor, and the buck regulator monitor.

## Register 27: Mask 2:

Individual bits to disable VBRG, logic, bootstrap, temperature, and logic I/O regulator diagnostic monitors.

## Control Register

The Control register (register 31) contains one control bit for each MOSFET and the high-side and low-side input invert control:

- HSI: sets the sense of the high-side logic inputs.
- LSI: sets the sense of the low-side logic inputs.
- CH, CL: MOSFET Control bits for Phase C.
- BH, BL: MOSFET Control bits for Phase B.
- AH, AL: MOSFET Control bits for Phase A.

## Status Register

There is one status register in addition to the addressable registers. When any register transfer takes place, the first six bits output on SDO are always the most significant six bits of the status register irrespective of whether the addressed register is being read or written (see serial timing diagram). The content of the remaining ten bits will depend on the state of the WR bit input on SDI. Except for the read-only registers, when WR is 1, the addressed register will be written and the remaining ten bits output on SDO will be the least significant nine bits of the status register followed by a parity bit. For the read-only registers, that is the two verification result registers and the three diagnostic registers. When WR is 1, the data bits will be ignored, no data will be written to the register, and the remaining ten bits output on SDO will be the least significant nine bits of the status register followed by a parity bit.

For both read-only and read/write registers, when WR is 0, the addressed register will be read and the remaining ten bits will be the contents of the addressed register followed by a parity bit.

The read-only status register provides a summary of the chip status by indicating if any diagnostic monitors have detected a fault. The most significant three bits of the status register indicate critical system faults. Bits 11 through 1 provide indicators for specific individual monitors and the contents of the three diagnostic registers. The contents and mapping to the diagnostic registers is listed in Table 9.

The first most significant bit in the register is the diagnostic

status flag, FF. This is high if any bits in the status register are set. If there are no fault bits in the status register, then FF will be zero. When STRn goes low to start a serial write, SDO outputs the diagnostic status flag. This allows the main controller to poll the AMT49100 through the serial interface to determine if a fault has been detected. If no faults have been detected, then the serial transfer may be terminated without generating a serial read fault by ensuring that SCK remains high while STRn is low. When STRn goes high, the transfer will be terminated and SDO will go into its high-impedance state.

The second most significant bit is the POR bit. At power-up or after a power-on-reset, the FF bit and the POR bit are set, indicating to the external controller that a power-on reset has taken place. All other diagnostic bits are reset and all other registers are returned to their default state. Note that a power-on reset only occurs when the output of the internal logic regulator rises above its undervoltage threshold. Power-on reset is not affected by the state of the VBRG supply or VREG regulator output. In general, the VR, VRU, and VLU bits may also be set following a power-on reset as the regulators will not have reached their respective rising undervoltage thresholds until after the register reset is completed.

Table 9: Status Register Mapping

| Status Register Bit | Diagnostic          | Related Diagnostic Register Bits |
|---------------------|---------------------|----------------------------------|
| FF                  | Status Flag         | None                             |
| POR                 | Power-on-reset      | None                             |
| SE                  | Serial Error        | None                             |
| EE                  | EEPROM Error        | None                             |
| OT                  | Overttemperature    | None                             |
| TW                  | Temperature warning | None                             |
| VS                  | VBRG out of range   | VSU, VSO                         |
| VLO                 | Logic OV            | None                             |
| ETO                 | ENABLE timeout      | None                             |
| VR                  | VREG monitor        | VRU, VRO, VBR                    |
| VLU                 | VIO UV              | None                             |
| VLO                 | Logic Overvoltage   | None                             |
| LDF                 | Load monitor        | OC1, OC2, OC3, OL                |
| BSU                 | Bootstrap UV        | VA, VB, VC                       |
| GSU                 | VGS UV              | AHU, BHU, CHU, ALU, BLU, CLU     |
| DSO                 | VDS OV              | AHO, BHO, CHO, ALO, BLO, CLO     |

UV = Undervoltage, OV = Overvoltage

The third bit in the status register is the SE bit, which indicates that the previous serial transfer was not completed successfully.

The fourth bit in the status register is the EE bit, which indicates that an EEPROM error was detected at device power up.

Of the remaining bits, the contents of OT, TW, VLO, ETO, VLU, and VCU are determined by individual diagnostics. These bits along with the POR and SE bits will be reset on the completion of a successful serial write transaction if DSR = 0. If DSR = 1, the fault bits will not be affected. Resetting only affects latched fault bits for faults that are no longer present. For any static faults that are still present, for example overtemperature, the fault flag will remain set after the reset.

The contents of the remaining bits in the status register, VS, VR, LDF, BSU, GSU, and DSO are all derived from the contents of the diagnostic registers. These bits are only cleared when the corresponding contents of the diagnostic registers are read and reset; they cannot be reset by reading the status register. A fault indicated on any of the related diagnostic register bits will set the corresponding status bit to 1. The related diagnostic register must then be read to determine the exact fault and clear the fault state if the fault condition has cleared.

### Non-Volatile Memory

The values in the configuration and control registers are held in non-volatile EEPROM (NVM), allowing the AMT49100 to be pre-programmed with different default values for each application, thus avoiding the need to program the register contents at each power on.

The AMT49100 provides a simple method to write the contents of the registers into the NVM using the serial interface. When the SAV[1:0] bits in register 16 are changed from [01] to [10], in a single serial write, the present contents of registers 0 to 15, 18, 19, 25 to 27, and 31 are saved (written to NVM) as a single operation. The contents of registers 16, 17, 20 to 24, 28 to 30, and the

status register is not written to NVM. The save sequence takes typically 400 ms to complete. It is not possible to save single register values. Although the gate drive may be active during the save sequence, it is recommended that the gate drive outputs are inactive (low) before starting a save sequence to avoid any corruption caused by the electrical noise or any faults from the load.

The register save sequence requires a programming voltage  $V_{PP}$  to be applied to the VBRG terminal.  $V_{PP}$  must be present on the VBRG terminal for a period,  $t_{PRS}$ , before the save sequence is started.  $V_{PP}$  must remain on VBRG until the save sequence is completed.

During the save sequence, the SPI remains active for read only. Any attempt to write to the registers during the save sequence will cause the FF and SE bits to be set in the Status register.

During the save sequence, the AMT49100 will automatically complete all the necessary steps to ensure that the NVM is correctly programmed and will complete the sequence by verifying that the contents of the NVM have been securely programmed. On successful completion of a save sequence, the SAV[1:0] bits will be set to [01]. Register 16 should be read to determine if the save has completed successfully. If SAV[1:0] is reset to [00], then the save sequence has been terminated and has not completed successfully.

If  $V_{PP}$  drops to an unacceptably low level during a save sequence, the sequence will be terminated and SAV[1:0] will be reset to 00.

To externally verify the data saved in the NVM, the VBB supply must be cycled off then on to cause a power-on reset. Following a power-on reset, the contents of the NVM are copied to the serial registers and can then be read through the serial interface and verified.

Refer to the NVM - Programming Parameters section of the Electrical Characteristics table for the permissible number of EEPROM write cycles and the maximum junction temperature limit that applies during programming.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                  |   |   |   |   |   |    |   |     |     |     |     |     |     |     |     |   |
|------------------|---|---|---|---|---|----|---|-----|-----|-----|-----|-----|-----|-----|-----|---|
| 0: Bridge Timing | 0 | 0 | 0 | 0 | 0 | WR |   | OCQ | DT6 | DT5 | DT4 | DT3 | DT2 | DT1 | DT0 | P |
|                  | 0 | 0 | 0 | 0 | 0 | WR | 0 | 0   | 0   | 1   | 0   | 0   | 0   | 0   | 0   |   |

|                   |   |   |   |   |   |    |      |      |      |      |      |      |      |      |      |   |
|-------------------|---|---|---|---|---|----|------|------|------|------|------|------|------|------|------|---|
| 1: Bridge Monitor | 0 | 0 | 0 | 0 | 1 | WR | OCT3 | OCT2 | OCT1 | OCT0 | TOC4 | TOC3 | TOC2 | TOC1 | TOC0 | P |
|                   | 0 | 0 | 0 | 0 | 1 | WR | 0    | 0    | 1    | 0    | 0    | 1    | 1    | 1    | 1    |   |

\*Power-on reset value shown below each input register bit.

### Register 0: Bridge Timing

OCQ Overcurrent time qualifier mode

| OCQ | Qualifier | Default |
|-----|-----------|---------|
| 0   | Debounce  | D       |
| 1   | Blanking  |         |

DT[6:0] Dead time.

$$t_{\text{DEAD}} = n \times 50 \text{ ns}$$

where n is a positive integer defined by DT[6:0]. For example, for the power-on reset condition, DT[6:0] = [010 0000],  $t_{\text{DEAD}} = 1.6 \mu\text{s}$ .

The range of  $t_{\text{DEAD}}$  is 100 ns to 6.35  $\mu\text{s}$ . Selecting a value of 1 or 2 will set the dead time to 100 ns. The default value of DT[6:0] = 32 sets the dead time to 1.6  $\mu\text{s}$ .

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 1: Bridge Monitor

OCT[3:0] Overcurrent threshold.

$$V_{\text{OCT}} = (n + 1) \times 300 \text{ mV}$$

where n is a positive integer defined by OCT[3:0], e.g. for the power-on-reset condition OCT[3:0] = [0010] then  $V_{\text{OCT}} = 0.9 \text{ V}$ . The range of  $V_{\text{OCT}}$  is 0.3 to 4.8 V.

TOC[4:0] Overcurrent qualify time.

$$t_{\text{OCQ}} = n \times 500 \text{ ns}$$

where n is a positive integer defined by TOC[4:0], e.g. for the power-on-reset condition TOC[4:0] = [0 1111] then  $t_{\text{OCQ}} = 7.5 \mu\text{s}$ . The range of  $t_{\text{OCQ}}$  is 0 to 15.5  $\mu\text{s}$ .

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                  |   |   |   |   |   |    |     |   |   |      |      |      |      |      |      |   |
|------------------|---|---|---|---|---|----|-----|---|---|------|------|------|------|------|------|---|
| 2: VDS Qualifier | 0 | 0 | 0 | 1 | 0 | WR | VDQ |   |   | TVD5 | TVD4 | TVD3 | TVD2 | TVD1 | TVD0 | P |
|                  |   |   |   |   |   |    | 0   | 0 | 0 | 0    | 1    | 0    | 0    | 0    | 0    |   |

|                       |   |   |   |   |   |    |     |   |   |      |      |      |      |      |      |   |
|-----------------------|---|---|---|---|---|----|-----|---|---|------|------|------|------|------|------|---|
| 3: Bridge Diagnostics | 0 | 0 | 0 | 1 | 1 | WR | VPO |   |   | VTL5 | VTL4 | VTL3 | VTL2 | VTL1 | VTL0 | P |
|                       |   |   |   |   |   |    | 1   | 0 | 0 | 0    | 1    | 1    | 0    | 0    | 0    |   |

\*Power-on reset value shown below each input register bit.

### Register 2: VDS Qualifier

VDQ VDS and VGS Fault qualifier mode.

| VDQ | VDS and VGS Fault Qualifier | Default |
|-----|-----------------------------|---------|
| 0   | Debounce                    | D       |
| 1   | Blank                       |         |

TVD[5:0] VDS and VGS qualification time.

$$t_{VDQ} = n \times 100 \text{ ns}$$

where n is a positive integer defined by TVD[5:0].

e.g. for the power-on-reset condition

TVD[5:0] = [01 0000] then  $t_{VDQ} = 1.6 \mu\text{s}$ .

The usable range of  $t_{VDQ}$  is 0.6 to 6.3  $\mu\text{s}$ .

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 3: Bridge Diagnostic Thresholds

VPO VBRG Overvoltage threshold.

| VPO | VBRGOV Threshold | Default |
|-----|------------------|---------|
| 0   | 52 V             |         |
| 1   | 58 V             | D       |

VTL[5:0] Low-side VDS overvoltage threshold.

$$V_{DSTL} = n \times 50 \text{ mV}$$

where n is a positive integer defined by VTL[5:0].

e.g. for the power-on-reset condition

VTL[5:0] = [01 1000] then  $V_{DSTL} = 1.2 \text{ V}$ .

The range of  $V_{DSTL}$  is 0 to 3.15 V.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                       |   |   |   |   |   |    |   |   |   |      |      |      |      |      |      |   |
|-----------------------|---|---|---|---|---|----|---|---|---|------|------|------|------|------|------|---|
| 4: Bridge Diagnostics | 0 | 0 | 1 | 0 | 0 | WR |   |   |   | VTH5 | VTH4 | VTH3 | VTH2 | VTH1 | VTH0 | P |
|                       |   |   |   |   |   |    | 0 | 0 | 0 | 0    | 1    | 1    | 0    | 0    | 0    |   |

|                   |   |   |   |   |   |    |     |   |   |     |   |      |      |      |      |   |
|-------------------|---|---|---|---|---|----|-----|---|---|-----|---|------|------|------|------|---|
| 5: Bridge Monitor | 0 | 0 | 1 | 0 | 1 | WR | AOL |   |   | VPU |   | OLT3 | OLT2 | OLT1 | OLT0 | P |
|                   |   |   |   |   |   |    | 0   | 0 | 0 | 0   | 0 | 1    | 0    | 0    | 0    |   |

\*Power-on reset value shown below each input register bit.

### Config 4: Bridge Diagnostics

VTH[5:0] High-side VDS overvoltage threshold.

$$V_{DSTH} = n \times 50 \text{ mV}$$

where n is a positive integer defined by VTH[5:0],

e.g. for the power-on-reset condition

VTH[5:0] = [01 1000] then  $V_{DSTH} = 1.2 \text{ V}$ .

The range of  $V_{DSTH}$  is 0 to 3.15 V.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Config 5: Bridge Monitor

AOL On-state open-load detect.

| AOL | On-State Open-Load Detect | Default |
|-----|---------------------------|---------|
| 0   | Inactive                  | D       |
| 1   | Active                    |         |

VPU VBRG Undervoltage threshold.

| VPU | VBRGUV Threshold | Default |
|-----|------------------|---------|
| 0   | 20 V             | D       |
| 1   | 36 V             |         |

OLT[3:0] Open-load threshold.

$$V_{OLTH} = n \times 25 \text{ mV}$$

where n is a positive integer defined by OLT[3:0],

e.g. for the power-on-reset condition

OLT[3:0] = [1000] then  $V_{OLT} = 200 \text{ mV}$ .

The range of  $V_{OLTH}$  is 0 to 375 mV.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                   |   |   |   |   |   |    |     |   |   |      |      |      |      |      |      |   |
|-------------------|---|---|---|---|---|----|-----|---|---|------|------|------|------|------|------|---|
| 6: Bridge Monitor | 0 | 0 | 1 | 1 | 0 | WR | EWD |   |   | VPT5 | VPT4 | VPT3 | VPT2 | VPT1 | VPT0 | P |
|                   |   |   |   |   |   |    | 0   | 0 | 0 | 1    | 0    | 0    | 0    | 0    | 0    |   |

|           |   |   |   |   |   |    |     |     |      |      |      |     |   |     |     |   |
|-----------|---|---|---|---|---|----|-----|-----|------|------|------|-----|---|-----|-----|---|
| 7: System | 0 | 0 | 1 | 1 | 1 | WR | VIO | VCL | BRE  | CPM1 | CPM0 | DSR |   | DG1 | DG0 | P |
|           |   |   |   |   |   |    | 0†  | 0‡  | 0/1† | 0    | 0    | 0   | 0 | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Register 6: Bridge Monitor Settings

EWD ENABLE Watchdog.

| EWD | ENABLE Watchdog | Default |
|-----|-----------------|---------|
| 0   | Disabled        | D       |
| 1   | Active          |         |

VPT[5:0] Phase comparator threshold.

$$V_{PT} = (n / 64) \times V_{BRG}$$

where n is a positive integer defined by VPT[5:0],

e.g. for the power-on-reset condition

VPT[5:0] = [10 0000] then  $V_{PT} = 50\% V_{BRG}$ .

The range of  $V_{PT}$  is 0 to 98.4%  $V_{BRG}$ .

P Parity bit. Ensures an odd number of 1s in any serial transfer.

\* Note that the BRE bit must be set in NVM. Changing the value of BRE in the SPI register will have no effect on operation. Only the value of the BRE bit stored in NVM can set the regulator mode.

† Factory-set power-on-reset value of BRE is selected by part number:

AMT49100KJPTR-A-3, AMT49100KJPTR-A-5:

BRE = 1, Buck Enabled.

AMT49100KJPTR-B-3, AMT49100KJPTR-B-5:

BRE = 0, Buck Disabled.

‡ Factory-set power-on-reset values of VIO and VCL are selected by part number:

AMT49100KJPTR-A-5, AMT49100KJPTR-B-5:

VIO = 1 (Logic I/O Voltage = 5V),

VCL = 1 (Clamp = 5.2 V).

AMT49100KJPTR-A-3, AMT49100KJPTR-B-3:

VIO = 0 (Logic I/O Voltage = 3V3),

VCL = 1 (Clamp = 3.5 V).

### Register 7: System

VIO Select Logic I/O voltage.

| VIO | Logic I/O Voltage | Default |
|-----|-------------------|---------|
| 0   | 3.3 V             | ‡       |
| 1   | 5 V               | ‡       |

VCL Select Sense Amp Clamp voltage.

| VCL | Sense Amp Clamp Voltage | Default |
|-----|-------------------------|---------|
| 0   | 3.5 V                   | ‡       |
| 1   | 5.2 V                   | ‡       |

BRE\* Buck regulator enable.

| BRE | Buck Regulator Operation | Default |
|-----|--------------------------|---------|
| 0   | Disabled                 | †       |
| 1   | Enabled                  | †       |

CPM Charge pump mode.

| CPM1 | CPM0 | Charge Pump Mode        | Default |
|------|------|-------------------------|---------|
| 0    | 0    | Auto 5 mA / 200 $\mu$ A | D       |
| 0    | 1    | 200 $\mu$ A             |         |
| 1    | 0    | 5 mA                    |         |
| 1    | 1    | Off                     |         |

DSR Disable Serial Reset.

| DSR | Reset on serial read | Default |
|-----|----------------------|---------|
| 0   | Enabled              | D       |
| 1   | Disabled             |         |

DG Select signal routed to DIAG.

| DG1 | DG0 | Signal on DIAG output | Default |
|-----|-----|-----------------------|---------|
| 0   | 0   | Fault – low true      | D       |
| 0   | 1   | Pulse Fault           |         |
| 1   | 0   | Temperature           |         |
| 1   | 1   | Clock                 |         |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                    |   |   |   |   |   |    |   |      |      |      |      |      |      |      |      |   |
|--------------------|---|---|---|---|---|----|---|------|------|------|------|------|------|------|------|---|
| 8: HS Drive Timing | 0 | 1 | 0 | 0 | 0 | WR |   | THR3 | THR2 | THR1 | THR0 | THF3 | THF2 | THF1 | THF0 | P |
|                    |   |   |   |   |   |    | 0 | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |   |

|                     |   |   |   |   |   |    |   |       |       |       |       |       |       |       |       |   |
|---------------------|---|---|---|---|---|----|---|-------|-------|-------|-------|-------|-------|-------|-------|---|
| 9: HS Drive Current | 0 | 1 | 0 | 0 | 1 | WR |   | IHR13 | IHR12 | IHR11 | IHR10 | IHF13 | IHF12 | IHF11 | IHF10 | P |
|                     |   |   |   |   |   |    | 0 | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |

\*Power-on reset value shown below each input register bit.

### Register 8: High-side gate drive timing

THR[3:0] High-side rising t<sub>1</sub> Time.

$$t_1 = 60 \text{ ns} + (n \times 16 \text{ ns})$$

where n is a positive integer defined by THR[3:0],

e.g. if THR[3:0] = [0001] then t<sub>1</sub> = 76 ns.

The range of t<sub>1</sub> is 60 to 300 ns.

THF[3:0] High-side falling t<sub>1</sub> Time.

$$t_1 = 60 \text{ ns} + (n \times 16 \text{ ns})$$

where n is a positive integer defined by THF[3:0],

e.g. if THF[3:0] = [0001] then t<sub>1</sub> = 76 ns.

The range of t<sub>1</sub> is 60 to 300 ns.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 9: High-side gate drive current

IHR1[3:0] High-side rising I<sub>1</sub> Current.

$$I_1 = n \times -16 \text{ mA}$$

where n is a positive integer defined by IHR1[3:0],

e.g. if IHR1[3:0] = [1000] then I<sub>1</sub> = -128 mA.

The range of I<sub>1</sub> is -16 to -240 mA. Selecting a value of 0 will set maximum gate drive to turn on the MOSFET as quickly as possible.

IHF1[3:0] High-side falling I<sub>1</sub> Current.

$$I_1 = n \times 16 \text{ mA}$$

where n is a positive integer defined by IHF1[3:0],

e.g. if IHF1[3:0] = [1000] then I<sub>1</sub> = 128 mA.

The range of I<sub>1</sub> is 16 to 240 mA. Selecting a value of 0 will set maximum gate drive to turn off the MOSFET as quickly as possible.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|                      | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8     | 7     | 6     | 5     | 4     | 3     | 2     | 1     | 0 |
|----------------------|----|----|----|----|----|----|---|-------|-------|-------|-------|-------|-------|-------|-------|---|
| 10: HS Drive Current | 0  | 1  | 0  | 1  | 0  | WR |   | IHR23 | IHR22 | IHR21 | IHR20 | IHF23 | IHF22 | IHF21 | IHF20 | P |
|                      |    |    |    |    |    |    | 0 | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |
| 11: LS Drive Timing  | 0  | 1  | 0  | 1  | 1  | WR |   | TLR3  | TLR2  | TLR1  | TLR0  | TLF3  | TLF2  | TLF1  | TLF0  | P |
|                      |    |    |    |    |    |    | 0 | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |

\*Power-on reset value shown below each input register bit.

### Register 10: High-side gate drive current

IHR2[3:0] High-side rising I<sub>2</sub> Current.

$$I_2 = n \times -16 \text{ mA}$$

where n is a positive integer defined by IHR2[3:0],  
e.g. if IHR2[3:0] = [1000] then I<sub>2</sub> = -128 mA.  
The range of I<sub>2</sub> is -16 to -240 mA. Selecting a value of 0 will set maximum gate drive to turn on the MOSFET as quickly as possible.

IHF2[3:0] High-side falling I<sub>2</sub> Current.

$$I_2 = n \times 16 \text{ mA}$$

where n is a positive integer defined by IHF2[3:0],  
e.g. if IHF2[3:0] = [1000] then I<sub>2</sub> = 128 mA.  
The range of I<sub>2</sub> is 16 to 240 mA. Selecting a value of 0 will set maximum gate drive to turn off the MOSFET as quickly as possible.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 11: Low-side gate drive timing

TLR[3:0] Low-side rising t<sub>1</sub> Time.

$$t_1 = 60 \text{ ns} + (n \times 16 \text{ ns})$$

where n is a positive integer defined by TLR[3:0],  
e.g. if TLR[3:0] = [0001] then t<sub>1</sub> = 76 ns.  
The range of t<sub>1</sub> is 60 to 300 ns.

TLF[3:0] Low-side falling t<sub>1</sub> Time.

$$t_1 = 60 \text{ ns} + (n \times 16 \text{ ns})$$

where n is a positive integer defined by TLF[3:0],  
e.g. if TLF[3:0] = [0001] then t<sub>1</sub> = 76 ns.  
The range of t<sub>1</sub> is 60 to 300 ns.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                      |   |   |   |   |   |    |   |       |       |       |       |       |       |       |       |   |
|----------------------|---|---|---|---|---|----|---|-------|-------|-------|-------|-------|-------|-------|-------|---|
| 12: LS Drive Current | 0 | 1 | 1 | 0 | 0 | WR |   | ILR13 | ILR12 | ILR11 | ILR10 | ILF13 | ILF12 | ILF11 | ILF10 | P |
|                      | 0 | 0 | 0 | 0 | 0 | 0  | 0 | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |

|                      |   |   |   |   |   |    |   |       |       |       |       |       |       |       |       |   |
|----------------------|---|---|---|---|---|----|---|-------|-------|-------|-------|-------|-------|-------|-------|---|
| 13: LS Drive Current | 0 | 1 | 1 | 0 | 1 | WR |   | ILR23 | ILR22 | ILR21 | ILR20 | ILF23 | ILF22 | ILF21 | ILF20 | P |
|                      | 0 | 0 | 0 | 0 | 0 | 0  | 0 | 0     | 0     | 0     | 0     | 0     | 0     | 0     | 0     |   |

\*Power-on reset value shown below each input register bit.

### Register 12: Low-side gate drive current

ILR1[3:0] Low-side rising I1 Current.

$$I_1 = n \times -16 \text{ mA}$$

where n is a positive integer defined by ILR1[3:0],  
e.g. if ILR1[3:0] = [1000] then  $I_1 = -128 \text{ mA}$ .  
The range of  $I_1$  is -16 to -240 mA. Selecting a value of 0 will set maximum gate drive to turn on the MOSFET as quickly as possible.

ILF1[3:0] Low-side falling I1 Current.

$$I_1 = n \times 16 \text{ mA}$$

where n is a positive integer defined by ILF1[3:0],  
e.g. if ILF1[3:0] = [1000] then  $I_1 = 128 \text{ mA}$ .  
The range of  $I_1$  is 16 to 240 mA. Selecting a value of 0 will set maximum gate drive to turn off the MOSFET as quickly as possible.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 13: Low-side gate drive current

ILR2[3:0] Low-side rising I2 Current.

$$I_2 = n \times -16 \text{ mA}$$

where n is a positive integer defined by ILR2[3:0],  
e.g. if ILR2[3:0] = [1000] then  $I_2 = -128 \text{ mA}$ .  
The range of  $I_2$  is -16 to -240 mA. Selecting a value of 0 will set maximum gate drive to turn on the MOSFET as quickly as possible.

ILF2[3:0] Low-side falling I2 Current.

$$I_2 = n \times 16 \text{ mA}$$

where n is a positive integer defined by ILF2[3:0],  
e.g. if ILF2[3:0] = [1000] then  $I_2 = 128 \text{ mA}$ .  
The range of  $I_2$  is 16 to 240 mA. Selecting a value of 0 will set maximum gate drive to turn off the MOSFET as quickly as possible.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|                      | 15 | 14 | 13 | 12 | 11 | 10 | 9    | 8    | 7    | 6    | 5    | 4    | 3    | 2    | 1    | 0 |
|----------------------|----|----|----|----|----|----|------|------|------|------|------|------|------|------|------|---|
| 14: Sense Amp Offset | 0  | 1  | 1  | 1  | 0  | WR | S3C  | S2C  | S1C  |      |      | SAO3 | SAO2 | SAO1 | SAO0 | P |
|                      |    |    |    |    |    |    | 0    | 0    | 0    | 0    | 0    | 1    | 1    | 1    | 1    |   |
| 15: Sense Amp Gain   | 0  | 1  | 1  | 1  | 1  | WR | S3G2 | S3G1 | S3G0 | S2G2 | S2G1 | S2G0 | S1G2 | S1G1 | S1G0 | P |
|                      |    |    |    |    |    |    | 0    | 1    | 0    | 0    | 1    | 0    | 0    | 1    | 0    |   |

\*Power-on reset value shown below each input register bit.

### Register 14: Sense Amp Offset

S3C Sense amplifier 3 input offset calibrate

S2C Sense amplifier 2 input offset calibrate

S1C Sense amplifier 1 input offset calibrate

A zero to one transition initiates calibration cycle.

SAO[3:0] Sense amp offset

| SAO | Offset | Default |
|-----|--------|---------|
| 0   | 0      |         |
| 1   | 0      |         |
| 2   | 100 mV |         |
| 3   | 100 mV |         |
| 4   | 200 mV |         |
| 5   | 300 mV |         |
| 6   | 400 mV |         |
| 7   | 500 mV |         |
| 8   | 750 mV |         |
| 9   | 1 V    |         |
| 10  | 1.25 V |         |
| 11  | 1.5 V  |         |
| 12  | 1.65 V |         |
| 13  | 2 V    |         |
| 14  | 2.25 V |         |
| 15  | 2.5 V  | D       |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 15: Sense Amp Gain

S3G[2:0] Sense amplifier 3 gain.

| S3G | Gain | Default |
|-----|------|---------|
| 0   | 10   |         |
| 1   | 15   |         |
| 2   | 20   | D       |
| 3   | 25   |         |
| 4   | 30   |         |
| 5   | 35   |         |
| 6   | 40   |         |
| 7   | 50   |         |

S2G[2:0] Sense amplifier 2 gain.

| S2G | Gain | Default |
|-----|------|---------|
| 0   | 10   |         |
| 1   | 15   |         |
| 2   | 20   | D       |
| 3   | 25   |         |
| 4   | 30   |         |
| 5   | 35   |         |
| 6   | 40   |         |
| 7   | 50   |         |

S1G[2:0] Sense amplifier 1 gain.

| S1G | Gain | Default |
|-----|------|---------|
| 0   | 10   |         |
| 1   | 15   |         |
| 2   | 20   | D       |
| 3   | 25   |         |
| 4   | 30   |         |
| 5   | 35   |         |
| 6   | 40   |         |
| 7   | 50   |         |

where SxG is a positive integer defined by SxG[2:0].

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|               |   |   |   |   |   |    |      |      |   |   |   |   |   |   |   |   |
|---------------|---|---|---|---|---|----|------|------|---|---|---|---|---|---|---|---|
| 16: NVM Write | 1 | 0 | 0 | 0 | 0 | WR | SAV1 | SAV0 |   |   |   |   |   |   |   | P |
|               |   |   |   |   |   |    | 0    | 0    | 0 | 0 | 0 | 0 | 0 | 0 | 0 |   |

\*Power-on reset value shown below each input register bit.

### Register 16: Write NVM control

SAV[1:0] Save parameters to Non-Volatile Memory (NVM)

When SAV[1:0] is changed from 01 to 10, the present contents of registers 0 to 15, 18, 19, 25 to 27, and register 31 are written to NVM.

When the NVM save has completed successfully, SAV[1:0] will be set to 01 and can be read to verify completion of the write. If SAV[1:0] is reset to 00, the save has not completed successfully.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                     |   |   |   |   |   |    |     |     |   |      |   |     |      |      |      |   |
|---------------------|---|---|---|---|---|----|-----|-----|---|------|---|-----|------|------|------|---|
| 18: Stop on Fault 0 | 1 | 0 | 0 | 1 | 0 | WR | FOT | FTW |   | FLSS |   | FSE | FVLU | FVLO | FEWD | P |
|                     |   |   |   |   |   |    | 1   | 1   | 0 | 0    | 0 | 1   | 1    | 1    | 1    |   |

|                     |   |   |   |   |   |    |     |   |      |      |      |      |      |      |      |   |
|---------------------|---|---|---|---|---|----|-----|---|------|------|------|------|------|------|------|---|
| 19: Stop on Fault 1 | 1 | 0 | 0 | 1 | 1 | WR | FOC |   | FDSO | FGSU | FVBU | FVRO | FVRU | FVSO | FVSU | P |
|                     |   |   |   |   |   |    | 1   | 0 | 1    | 1    | 1    | 1    | 1    | 1    | 1    |   |

\*Power-on reset value shown below each input register bit.

### Register 18: Stop on Fault 0

FOT Overtemperature  
 FTW Temperature Warning  
 FLSS LSS Disconnect  
 FSE Serial Error  
 FVLU VIO Undervoltage  
 FVLO Logic Overvoltage  
 FEWD ENABLE WD Timeout

P Parity bit. Ensures an odd number of 1s in any serial transfer.

See Table 6 for details of each diagnostic.

### Register 19: Stop on Fault 1

FOC Overcurrent  
 FDSO VDS Overvoltage  
 FGSU VGS Undervoltage  
 FVBU Bootstrap Undervoltage  
 FVRO VREG Overvoltage  
 FVRU VREG Undervoltage  
 FVSO VBRG Overvoltage  
 FVSU VBRG Undervoltage

P Parity bit. Ensures an odd number of 1s in any serial transfer.

See Table 6 for details of each diagnostic.

## Serial Register Reference

|                      | 15 | 14 | 13 | 12 | 11 | 10 | 9   | 8   | 7   | 6   | 5   | 4    | 3    | 2   | 1   | 0 |
|----------------------|----|----|----|----|----|----|-----|-----|-----|-----|-----|------|------|-----|-----|---|
| 20: Verify Command 0 | 1  | 0  | 1  | 0  | 0  | WR |     | YDO | YRO | YRU | YBU | YLO  | YSO  | YSU | YGU | P |
|                      |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0    | 0    | 0   | 0   |   |
| 21: Verify Command 1 | 1  | 0  | 1  | 0  | 1  | WR | YPH | YPL | YOC | YLU | YOL | YPS1 | YPS0 | YSK | YSC | P |
|                      |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0    | 0    | 0   | 0   |   |
| 22: Verify Command 2 | 1  | 0  | 1  | 1  | 0  | WR | YTW | YOT |     | YLS |     |      |      |     |     | P |
|                      |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0    | 0    | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Register 20: Verify Command 0

|     |                                                                 |
|-----|-----------------------------------------------------------------|
| YDO | VDS Overvoltage                                                 |
| YRO | VREG Overvoltage                                                |
| YRU | VREG Undervoltage                                               |
| YBU | Bootstrap Capacitor Undervoltage                                |
| YLO | Logic Overvoltage                                               |
| YSO | VBRG Supply Overvoltage                                         |
| YSU | VBRG Supply Undervoltage                                        |
| YGU | VGS Undervoltage                                                |
| P   | Parity bit. Ensures an odd number of 1s in any serial transfer. |

### Register 21: Verify Command 1

|     |                            |
|-----|----------------------------|
| YPH | Phase Disconnect High-Side |
| YPL | Phase Disconnect Low-Side  |
| YOC | Overcurrent                |
| YLU | VIO Undervoltage           |
| YOL | On-State Open Load         |

YPS[1:0] Phase diagnostic select.

| YPS1 | YPS0 | Phase Diagnostic     | Default |
|------|------|----------------------|---------|
| 0    | 0    | Phase B Disconnect   | D       |
| 0    | 1    | Phase A Disconnect   |         |
| 1    | 0    | Phase C Disconnect   |         |
| 1    | 1    | Off-state open load* |         |

|     |                                                            |
|-----|------------------------------------------------------------|
| YSK | I <sub>SD</sub> (2.5 mA) sink on phase selected by YPS*    |
| YSC | I <sub>SU</sub> (−410 μA) source on phase selected by YPS* |

\* When YPS = 3, Phase B has a fixed 2.5 mA sink and the source current on phases A and C are common and set by YSC.

|   |                                                                 |
|---|-----------------------------------------------------------------|
| P | Parity bit. Ensures an odd number of 1s in any serial transfer. |
|---|-----------------------------------------------------------------|

### Register 22: Verify Command 2

|     |                                                                 |
|-----|-----------------------------------------------------------------|
| YTW | Temperature Warning                                             |
| YOT | Overttemperature                                                |
| YLS | LSS Disconnect                                                  |
| P   | Parity bit. Ensures an odd number of 1s in any serial transfer. |

### For Verify Command Registers except YPS, YSK, and YSC

| Yxx | Verification        | Default |
|-----|---------------------|---------|
| 0   | Inactive            | D       |
| 1   | Active and Initiate |         |

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|                     |   |   |   |   |   |   |     |     |     |     |     |     |     |     |     |   |
|---------------------|---|---|---|---|---|---|-----|-----|-----|-----|-----|-----|-----|-----|-----|---|
| 23: Verify Result 0 | 1 | 0 | 1 | 1 | 1 | 0 | PCD | PBD | PAD | CHM | CLM | BHM | BLM | AHM | ALM | P |
|                     |   |   |   |   |   |   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |

|                     |   |   |   |   |   |   |   |   |     |     |     |     |     |     |     |   |
|---------------------|---|---|---|---|---|---|---|---|-----|-----|-----|-----|-----|-----|-----|---|
| 24: Verify Result 1 | 1 | 1 | 0 | 0 | 0 | 0 |   |   | GDO | SCS | SBS | SAS | S3D | S2D | S1D | P |
|                     |   |   |   |   |   |   | 0 | 0 | 1   | 0   | 0   | 0   | 0   | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Register 23: Verify Result 0 (read only)

|     |                                           |
|-----|-------------------------------------------|
| PCD | Phase C connected                         |
| PBD | Phase B connected                         |
| PAD | Phase A connected                         |
| CHM | Phase C high-side gate drive output state |
| CLM | Phase C low-side gate drive output state  |
| BHM | Phase B high-side gate drive output state |
| BLM | Phase B low-side gate drive output state  |
| AHM | Phase A high-side gate drive output state |
| ALM | Phase A low-side gate drive output state  |

| xxx | Verification Result | Default |
|-----|---------------------|---------|
| 0   | Not detected        | D       |
| 1   | Detected            |         |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 24: Verify Result 1 (read only)

|     |                        |
|-----|------------------------|
| GDO | All gate drives off    |
| SCS | Phase C state          |
| SBS | Phase B state          |
| SAS | Phase A state          |
| S3D | Sense amp 3 disconnect |
| S2D | Sense amp 2 disconnect |
| S1D | Sense amp 1 disconnect |

| xxx | Verification Result | Default |
|-----|---------------------|---------|
| 0   | Not detected        | D       |
| 1   | Detected            |         |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|                   | 15 | 14 | 13 | 12 | 11 | 10 | 9   | 8   | 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0 |
|-------------------|----|----|----|----|----|----|-----|-----|-----|-----|-----|-----|-----|-----|-----|---|
| <b>25: Mask 0</b> | 1  | 1  | 0  | 0  | 1  | WR | LCD | LBD | LAD | CHU | CLU | BHU | BLU | AHU | ALU | P |
|                   |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| <b>26: Mask 1</b> | 1  | 1  | 0  | 1  | 0  | WR | VRO | VRU | VBR | CHO | CLO | BHO | BLO | AHO | ALO | P |
|                   |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| <b>27: Mask 2</b> | 1  | 1  | 0  | 1  | 1  | WR | VS  | VLO | BSU | TW  | VLU |     |     |     |     | P |
|                   |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Register 25: Mask 0

|     |                                                                 |
|-----|-----------------------------------------------------------------|
| LCD | LSSC disconnect                                                 |
| LBD | LSSB disconnect                                                 |
| LAD | LSSA disconnect                                                 |
| CHU | Phase C high-side VGS undervoltage                              |
| CLU | Phase C low-side VGS undervoltage                               |
| BHU | Phase B high-side VGS undervoltage                              |
| BLU | Phase B low-side VGS undervoltage                               |
| AHU | Phase A high-side VGS undervoltage                              |
| ALU | Phase A low-side VGS undervoltage                               |
| P   | Parity bit. Ensures an odd number of 1s in any serial transfer. |

### Register 26: Mask 1

|     |                                                                 |
|-----|-----------------------------------------------------------------|
| VRO | VREG Overvoltage                                                |
| VRU | VREG Undervoltage                                               |
| VBR | Buck regulator Fault                                            |
| CHO | Phase C high-side VDS overvoltage                               |
| CLO | Phase C low-side VDS overvoltage                                |
| BHO | Phase B high-side VDS overvoltage                               |
| BLO | Phase B low-side VDS overvoltage                                |
| AHO | Phase A high-side VDS overvoltage                               |
| ALO | Phase A low-side VDS overvoltage                                |
| P   | Parity bit. Ensures an odd number of 1s in any serial transfer. |

### Register 27: Mask 2

|     |                                                                 |
|-----|-----------------------------------------------------------------|
| VS  | VBRG out of range                                               |
| VLO | Logic Overvoltage                                               |
| BSU | Bootstrap undervoltage                                          |
| TW  | Temperature Warning                                             |
| VLU | VIO undervoltage                                                |
| P   | Parity bit. Ensures an odd number of 1s in any serial transfer. |

### For All Mask Registers

| xxx | Fault Mask                | Default |
|-----|---------------------------|---------|
| 0   | Fault detection permitted | D       |
| 1   | Fault detection disabled  |         |

If a bit is set to one in the mask registers, then the corresponding diagnostic will be completely disabled. No fault states for the disabled diagnostic will be generated, no fault flags or diagnostic bits will be set, and no action will be taken if the corresponding fault conditions are present.

## Serial Register Reference

|                             | 15 | 14 | 13 | 12 | 11 | 10 | 9   | 8   | 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0 |
|-----------------------------|----|----|----|----|----|----|-----|-----|-----|-----|-----|-----|-----|-----|-----|---|
| <b>28:<br/>Diagnostic 0</b> | 1  | 1  | 1  | 0  | 0  | 0  | LCD | LBD | LAD | CHU | CLU | BHU | BLU | AHU | ALU | P |
|                             |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| <b>29:<br/>Diagnostic 1</b> | 1  | 1  | 1  | 0  | 1  | 0  | VRO | VRU | VBR | CHO | CLO | BHO | BLO | AHO | ALO | P |
|                             |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |
| <b>30:<br/>Diagnostic 2</b> | 1  | 1  | 1  | 1  | 0  | 0  | VC  | VB  | VA  | VSO | VSU | OC3 | OC2 | OC1 | OL  | P |
|                             |    |    |    |    |    |    | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Register 28: Diagnostic 0 (read only)

|     |                                    |
|-----|------------------------------------|
| LCD | LSSC disconnect                    |
| LBD | LSSB disconnect                    |
| LAD | LSSA disconnect                    |
| CHU | Phase C high-side VGS undervoltage |
| CLU | Phase C low-side VGS undervoltage  |
| BHU | Phase B high-side VGS undervoltage |
| BLU | Phase B low-side VGS undervoltage  |
| AHU | Phase A high-side VGS undervoltage |
| ALU | Phase A low-side VGS undervoltage  |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 29: Diagnostic 1 (read only)

|     |                                   |
|-----|-----------------------------------|
| VRO | VREG Overvoltage                  |
| VRU | VREG Undervoltage                 |
| VBR | Buck regulator fault              |
| CHO | Phase C high-side VDS overvoltage |
| CLO | Phase C low-side VDS overvoltage  |
| BHO | Phase B high-side VDS overvoltage |
| BLO | Phase B low-side VDS overvoltage  |
| AHO | Phase A high-side VDS overvoltage |
| ALO | Phase A low-side VDS overvoltage  |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### Register 30: Diagnostic 2 (read only)

|     |                                |
|-----|--------------------------------|
| VC  | Phase C bootstrap undervoltage |
| VB  | Phase B bootstrap undervoltage |
| VA  | Phase A bootstrap undervoltage |
| VSO | VBRG Overvoltage               |
| VSU | VBRG Undervoltage              |
| OC3 | Overcurrent on sense amp 3     |
| OC2 | Overcurrent on sense amp 2     |
| OC1 | Overcurrent on sense amp 1     |
| OL  | Open load                      |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

### For All Diagnostic Registers

| xxx | Status            |
|-----|-------------------|
| 0   | No fault detected |
| 1   | Fault detected    |

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

|             |   |   |   |   |   |    |     |     |   |    |    |    |    |    |    |   |
|-------------|---|---|---|---|---|----|-----|-----|---|----|----|----|----|----|----|---|
| 31: Control | 1 | 1 | 1 | 1 | 1 | WR | HSI | LSI |   | CH | CL | BH | BL | AH | AL | P |
|             |   |   |   |   |   |    | 0   | 0   | 0 | 0  | 0  | 0  | 0  | 0  | 0  |   |

\*Power-on reset value shown below each input register bit.

### Register 31: Control

HSI Invert high-side logic inputs

LSI Invert low-side logic inputs

CH Phase C, High-side gate drive

CL Phase C, Low-side gate drive

BH Phase B, High-side gate drive

BL Phase B, Low-side gate drive

AH Phase A, High-side gate drive

AL Phase A, Low-side gate drive

See Table 2 and Table 3 for control logic operation.

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## Serial Register Reference

|    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|

| Status | FF | POR | SE | EE | OT | TW | VS | VLO | ETO | VR | VLU | LDF | BSU | GSU | DSO | P |
|--------|----|-----|----|----|----|----|----|-----|-----|----|-----|-----|-----|-----|-----|---|
|        | 1  | 1   | 0  | 0  | 0  | 0  | 0  | 0   | 0   | 0  | 0   | 0   | 0   | 0   | 0   |   |

\*Power-on reset value shown below each input register bit.

### Status

|     |                          |
|-----|--------------------------|
| FF  | Status register flag     |
| POR | Power-on-reset           |
| SE  | Serial Error             |
| EE  | EEPROM Error             |
| OT  | Overtemperature          |
| TW  | High temperature warning |
| VS  | VBRG out of range        |
| VLO | Logic overvoltage        |
| ETO | ENABLE watchdog timeout  |
| VR  | VREG out of range        |
| VLU | VIO undervoltage         |
| LDF | Load fault               |
| BSU | Bootstrap undervoltage   |
| GSU | VGS undervoltage         |
| DSO | VDS overvoltage          |

| xxx | Status            |
|-----|-------------------|
| 0   | No fault detected |
| 1   | Fault detected    |

### Status Register Bit Mapping

| Status Register Bit | Related Diagnostic Register Bits |
|---------------------|----------------------------------|
| FF                  | None                             |
| POR                 | None                             |
| SE                  | None                             |
| EE                  | None                             |
| OT                  | None                             |
| TW                  | None                             |
| VS                  | VSU, VSO                         |
| VLO                 | None                             |
| ETO                 | None                             |
| VR                  | VRU, VRO, VBR                    |
| VLU                 | None                             |
| VLO                 | None                             |
| LDF                 | OC1, OC2, OC3, OL                |
| BSU                 | VA, VB, VC                       |
| GSU                 | AHU, ALU, BHU, BLU, CHU, CLU     |
| DSO                 | AHO, ALO, BHO, BLO, CHO, CLO     |

P Parity bit. Ensures an odd number of 1s in any serial transfer.

## APPLICATION INFORMATION

## Dead Time Selection

The choice of power MOSFET and external series gate resistance determines the selection of the dead time. The dead time,  $t_{\text{DEAD}}$ , should be made long enough to ensure that one MOSFET has stopped conducting before the complementary MOSFET starts conducting. This should also account for the tolerance and variation of the MOSFET gate capacitance, the series gate resistance, and the on-resistance of the driver in the AMT49100.

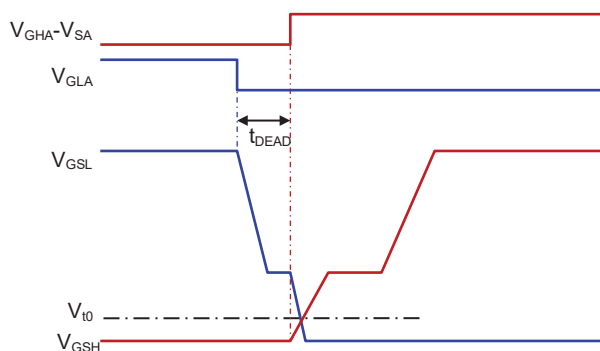


Figure 11: Minimum Dead Time

Figure 11 shows the typical switching characteristics of a pair of complementary MOSFETs. Ideally, one MOSFET should start to turn on just after the other has completely turned off. The point at which a MOSFET starts to conduct is the threshold voltage  $V_{\text{I0}}$ . The dead time should be long enough to ensure that the gate-source voltage of the MOSFET that is switching off is just below  $V_{\text{I0}}$  before the gate-source voltage of the MOSFET that is switching on rises to  $V_{\text{I0}}$ . This will be the minimum theoretical dead time but in practice the dead time will have to be longer than this to accommodate variations in MOSFET and driver parameters for process variations and over temperature.

## Bootstrap Capacitor Selection

The AMT49100 requires three bootstrap capacitors:  $C_{\text{BOOTA}}$ ,  $C_{\text{BOOTB}}$ , and  $C_{\text{BOOTC}}$ . To simplify this description of the bootstrap capacitor selection criteria, generic naming is used here. So, for example,  $C_{\text{BOOT}}$ ,  $Q_{\text{BOOT}}$ , and  $V_{\text{BOOT}}$  refer to any of the three capacitors, and  $Q_{\text{GATE}}$  refers to any of the six associated MOSFETs.  $C_{\text{BOOT}}$  must be correctly selected to ensure proper operation of the device: too large and time will be wasted charging the capacitor, resulting in a limit on the maximum duty cycle and PWM frequency; too small and there can be a large voltage drop at the time the charge is transferred from  $C_{\text{BOOT}}$  to the MOSFET gate.

To keep the voltage drop due to charge sharing small, the charge in the bootstrap capacitor,  $Q_{\text{BOOT}}$ , should be much larger than  $Q_{\text{GATE}}$ , the charge required by the gate:

$$Q_{\text{BOOT}} \gg Q_{\text{GATE}}$$

A factor of 20 is a reasonable value.

$$Q_{\text{BOOT}} = C_{\text{BOOT}} \times V_{\text{BOOT}} = Q_{\text{GATE}} \times 20$$

$$C_{\text{BOOT}} = (Q_{\text{GATE}} \times 20) / V_{\text{BOOT}}$$

where  $V_{\text{BOOT}}$  is the voltage across the bootstrap capacitor.

The voltage drop,  $\Delta V$ , across the bootstrap capacitor as the MOSFET is being turned on can be approximated by:

$$\Delta V = Q_{\text{GATE}} / C_{\text{BOOT}}$$

So, for a factor of 20,  $\Delta V$  will be 5% of  $V_{\text{BOOT}}$ .

The maximum voltage across the bootstrap capacitor under normal operating conditions is  $V_{\text{REG max}}$ . However, in some circumstances, the voltage may transiently reach a maximum of 20 V, which is the clamp voltage of the Zener diode between the Cx terminal and the Sx terminal. In most applications with a good ceramic capacitor, the working voltage can be limited to 18 V.

## VREG Capacitor Selection

Regulated voltage,  $V_{\text{REG}}$ , supplies current for the low-side gate-drive circuits and the initial charging current for the bootstrap capacitors. When a low-side MOSFET is turned on, the gate-drive circuit will provide the high transient current to the gate that is necessary to turn the MOSFET on quickly. This current, which can be in the region of an amp, cannot be provided directly by the buck regulator ( $\text{BRE}=1$ ) or externally connected regulated supply ( $\text{BRE}=0$ ) and must be supplied by an external capacitor,  $C_{\text{REG}}$ , connected between the VREG terminal and GND.

The turn on current for the high-side MOSFET is similar in value but is mainly supplied by the bootstrap capacitor. However, the bootstrap capacitor must then be recharged from  $C_{\text{REG}}$ , either directly through the VREG terminal or via the internal pump regulator. Unfortunately, the bootstrap recharge can occur a very short time after the low-side turn on occurs. This means that the value of  $C_{\text{REG}}$  between VREG and GND should be high enough to minimize the transient voltage drop on VREG for the combination of a low-side MOSFET turn-on and a bootstrap capacitor recharge. For block commutation control (trapezoidal drive), where only one high side and one low side are switching during each PWM period, a minimum value of  $20 \times C_{\text{BOOT}}$  is

reasonable. For sinusoidal control schemes, a minimum value of  $40 \times C_{BOOT}$  is recommended. If operating in the buck enabled (BRE=1) configuration, the fitted value of  $C_{REG}$  must also comply with the 10  $\mu$ F minimum required for correct buck operation. That is, the fitted value of  $C_{REG}$  should be the larger of the value determined by the bootstrap capacitor-based calculation above or 10  $\mu$ F.

As the maximum working voltage of  $C_{REG}$  will never exceed  $V_{REG}$ , the part's voltage rating can be as low as 15 V. However, it is recommended that a capacitor rated to at least twice the maximum working voltage should be used to reduce any impact operating voltage may have on capacitance value. For best performance,  $C_{REG}$  should be ceramic rather than electrolytic.  $C_{REG}$  should be mounted as close to the VREG terminal as possible.

## Braking

The AMT49100 can be used to perform dynamic braking by either forcing all low-side MOSFETs on and all high-side MOSFETs off or, inversely, by forcing all low-side off and all high-side on. This will effectively short-circuit the back emf of the motor, creating a braking torque. During braking, the load current,  $I_{BRAKE}$ , can be approximated by:

$$I_{BRAKE} = V_{BEMF} / R_L$$

where  $V_{bemf}$  is the voltage generated by the motor, and  $R_L$  is the resistance of the phase winding. Care must be taken during braking to ensure that the power MOSFETs' maximum ratings are not exceeded. Dynamic braking is equivalent to slow decay with synchronous rectification and all phases enabled.

The AMT49100 can also be used to perform regenerative braking. This is equivalent to using fast decay with synchronous rectification. Note that the supply must be capable of managing the reverse current, for example, by connecting a resistive load or dumping the current to a battery or capacitor.

## Current Sense Amplifier Configuration

Amplifier gain,  $A_V$ , and output offset zero point voltage,  $V_{OOS}$ , may be set to a range of values by the SxG[2:0] and SAO[3:0] variables, respectively, as defined in the Current Sense Amplifiers section above. It is important that both values are selected to ensure the *absolute* voltage at the CSxO output,  $V_{CSO}$ , remains within the amplifier's dynamic range,  $V_{CSOUT}$ , as set by the VCL bit and the dynamic range of any downstream signal processing circuitry. Allowance must be made for both positive and negative current flows within the sense resistor.

With reference to Figure 2, the relationship between phase cur-

rent,  $I_{PH}$ , sense resistor value,  $R_S$ , and differential amplifier input voltage,  $V_{ID}$  is given by:

$$V_{ID} = V_{CSP} - V_{CSM} = I_{PH} \times R_S$$

The current sense amplifier's output voltage on CSxO with respect to the programmed value of output offset  $V_{OOS}$  is:

$$V_{CSD} = (V_{CSP} - V_{CSM}) \times A_V$$

The absolute voltage on CSxO with respect to ground is therefore:

$$V_{CSO} = [(V_{CSP} - V_{CSM}) \times A_V] + V_{OOS}$$

If, for example, the following parameter values are assumed:

$$R_S = 1 \text{ m}\Omega$$

$$I_{PH} = -20 \text{ A to } +40 \text{ A}$$

$$A_V = 20 \text{ (SxG[2:0] = 0b010)}$$

$$V_{OOS} = 1 \text{ V (SAO[3:0] = 0b1001)}$$

$$VCL = 1$$

$V_{ID}$  ranges between  $-20 \text{ mV}$  and  $+40 \text{ mV}$  and  $V_{CSO}$  between  $0.6 \text{ V}$  and  $1.8 \text{ V}$ .  $V_{CSO}$  remains within the amplifier dynamic range,  $V_{CSOUT}$ , of  $0.3 \text{ V}$  to  $4.8 \text{ V}$ . However, if  $A_V$  is increased to 50,  $V_{CSO}$  attempts to drive to  $0 \text{ V}$  and  $3.0 \text{ V}$ , the amplifier dynamic range limits are not complied with, and the amplifier output saturates at its negative limit. This situation could be remedied by reducing  $A_V$  to 30 ( $0.4 \text{ V} < V_{CSO} < 2.2 \text{ V}$ ) or increasing  $V_{OOS}$  to  $1.5 \text{ V}$  ( $0.5 \text{ V} < V_{CSO} < 3.5 \text{ V}$ ).

## Current Sense Amplifier Output Signals

As defined in Figure 2, the current sense amplifier output signals on the CSxO pins are internally referenced to the  $V_{OOS}$  voltage. Consequently, the signal voltages on CSxO should be determined with respect to this reference point ( $V_{CSD}$ ). This requires a multi-step process.

Step 1: YOL is set to 1 to make  $V_{OOS}$  available on all CSxO terminals allowing this voltage to be measured.

Step 2: YOL is set to 0 to make  $V_{CSO} = V_{OOS} + V_{CSD}$  available on each CSxO terminal allowing these voltages to be measured.

Step 3: The value measured at Step 1 is subtracted from those measured at Step 2 to eliminate  $V_{OOS}$  and give the required result:

$$V_{CSO} - V_{OOS} = (V_{OOS} + V_{CSD}) - V_{OOS} = V_{CSD}$$

As  $V_{OOS}$  does not change rapidly during operation (that is, it is effectively a steady value that drifts, predominantly, with temperature change), it may be possible to measure and update

this value at a relatively low rate rather than every time  $V_{CSO}$  is measured.

The Input Offset Voltage,  $V_{IOS}$ , and the associated drift,  $\Delta V_{IOS}$ , multiplied by the selected amplifier gain,  $A_v$ , represent the offset and offset drift limits that apply to  $V_{CSD}$ . The Output Offset Error,  $E_{VO}$ , and Output Offset Drift,  $V_{OOSD}$ , limits apply to  $V_{OOS}$ . If the three step measurement technique described above is used,  $V_{OOS}$  is eliminated from the measurement and  $E_{VO}$  and  $V_{OOSD}$  do not affect the accuracy of the measured current as represented by  $V_{CSD}$ .

## INPUT/OUTPUT STRUCTURES

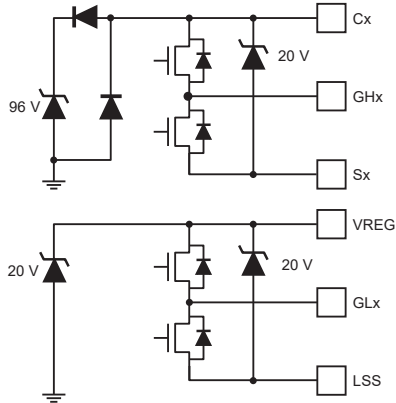


Figure 12a: Gate Drive Outputs

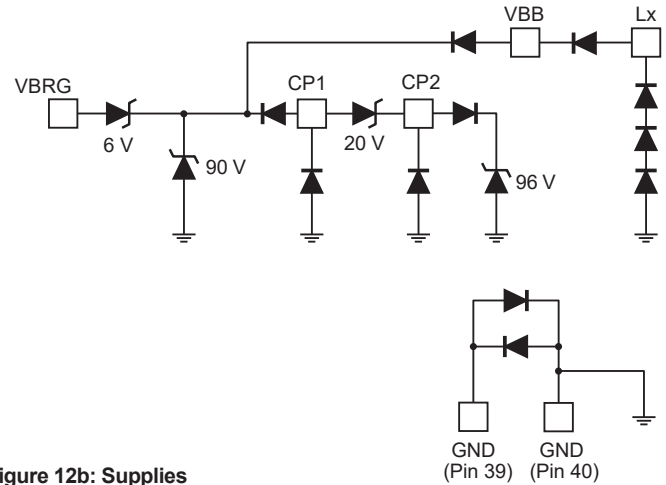


Figure 12b: Supplies

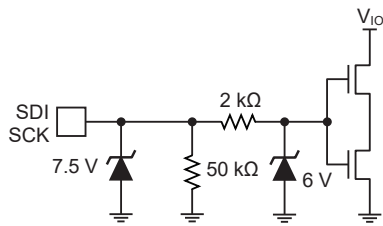


Figure 12c: SDI, SCK Inputs

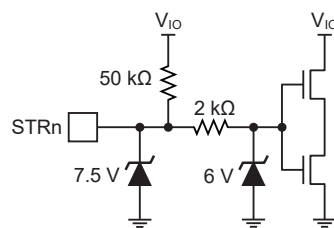


Figure 12d: STRn Input

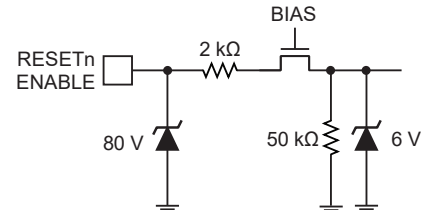


Figure 12e: ENABLE, RESETn Inputs

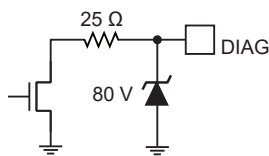


Figure 12f: DIAG Output

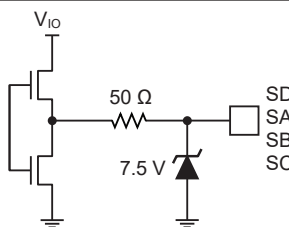


Figure 12g: SDO, SxL Outputs

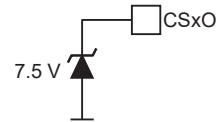


Figure 12h: CSxO Output

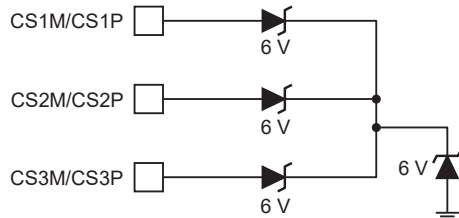


Figure 12i: CSxM, CSxP Inputs

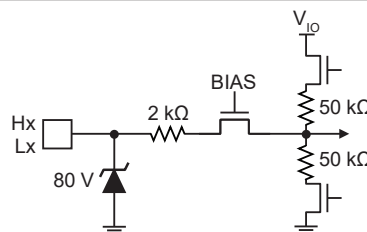


Figure 12j: Hx, Lx Inputs

## LAYOUT RECOMMENDATIONS

Careful consideration must be given to PCB layout when designing high-frequency, fast-switching, high-voltage, high-current circuits. The following comments give general guidance and should be read in conjunction with Figure 13.

- The two AMT49100 ground terminals, both designated GND, must be connected together on the PCB close to the device for correct operation. This common point should return separately to the negative side of the motor supply filtering capacitor. This will minimize the effect of switching noise on the device logic and analog reference.
- The exposed thermal pad should be connected to the common point of the two GND terminals.
- Minimize stray inductance by using short, wide copper tracks at the drain and source terminals of all power MOSFETs. This includes motor lead connections, the input power bus, and the common source of the low-side power MOSFETs. This will minimize voltages induced by fast switching of large load currents.
- Keep the gate discharge return connections  $S_x$  and  $LSS_x$  ( $x=A, B, \text{ or } C$ ) as short as possible. Any inductance on these tracks will cause negative transitions on the corresponding AMT49100 terminals, which may exceed the absolute maximum ratings. If this is likely, consider the use of clamping diodes to limit the negative excursion on these terminals with respect to the GND terminals.
- Gate charge drive paths and gate discharge return paths may carry a large transient current pulse. Therefore, the traces from  $GH_x$ ,  $GL_x$ ,  $S_x$ , and  $LSS_x$  should be as short as possible to reduce the track inductance.
- Provide an independent connection from each  $LSS_x$  terminal to the source of the corresponding low-side MOSFET in the power bridge. Connection of the  $LSS_x$  terminals directly to the GND terminals of the AMT49100 is not recommended as this may inject noise into sensitive functions such as the various voltage monitors.
- If using the part in the buck-enabled mode a ceramic decoupling capacitor,  $C_{BB}$ , of at least  $4.7\ \mu\text{F}$  should be connected between VBB and GND as close to the AMT49100 terminals as possible. If using the part in the buck-disabled mode a ceramic decoupling capacitor,  $C_{BB}$ , of at least 100 nF should be connected between VBB and GND as close to the AMT49100 terminals as possible.
- A decoupling capacitor of at least 100 nF, should be connected between VBRG and GND as close to the AMT49100 terminals as possible.
- The VREG capacitor,  $C_{REG}$ , as determined by the selection guidelines in the Applications Information section of this datasheet should be connected between VREG and GND as close to the AMT49100 terminals as possible.
- Each bootstrap capacitor  $C_{BOOTx}$ , should be mounted as close to the AMT49100 as possible and connect to the  $C_X$  and  $S_X$  terminals by short tracks.
- The pump regulator capacitor,  $C_p$ , should be mounted as close to the AMT49100 as possible and connect to the CP1 and CP2 terminals by short tracks.
- The DC link (or bulk) capacitor(s), represented by C4 in Figure A, should be mounted as close as possible to the three phases of the bridge.
- A dedicated ceramic capacitor, C1, C2, C3 in Figure A, should be mounted close to and connected across each phase from high-side MOSFET drain to the corresponding current sense resistor supply common terminal.
- Consider the addition of RC snubber networks between source to drain on all power MOSFETs in the bridge to dampen excessive motor phase ringing. These should be located as close to the MOSFET terminals as possible. Connections direct to the power and ground planes should be avoided.
- If using the part in the buck-enabled mode the external inductor, L, and recirculating diode, D, should be mounted as close to the AMT49100 GND, LX, and VREG terminals as possible and be interconnected by tracks that are as short as possible.
- A low-cost diode can be placed in the connection to VBB to provide reverse-battery protection. In reverse-battery conditions, it is possible to use the body diodes of the power MOSFETs to clamp the reverse voltage to approximately 4 V. In this case, the additional diode in the VBB connection will prevent damage to the AMT49100 and the VBRG input will survive the reverse voltage.

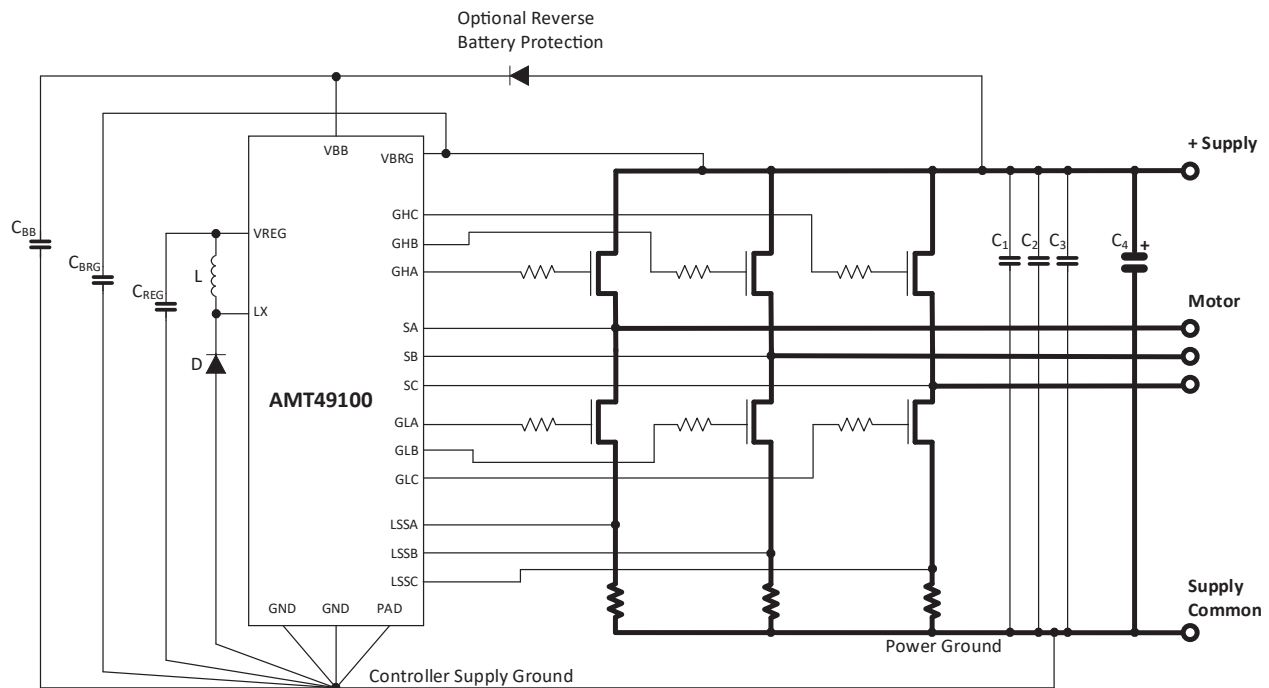


Figure 13: Supply Routing Suggestions

## For Reference Only – Not for Tooling Use

(Reference Allegro DWG-0000386, Rev. 5 or JEDEC MS-026 BBCHD)

NOT TO SCALE

Dimensions in millimeters

Dimensions exclusive of mold flash, gate burrs, and dambar protrusions

Exact case and lead configuration at supplier discretion within limits shown

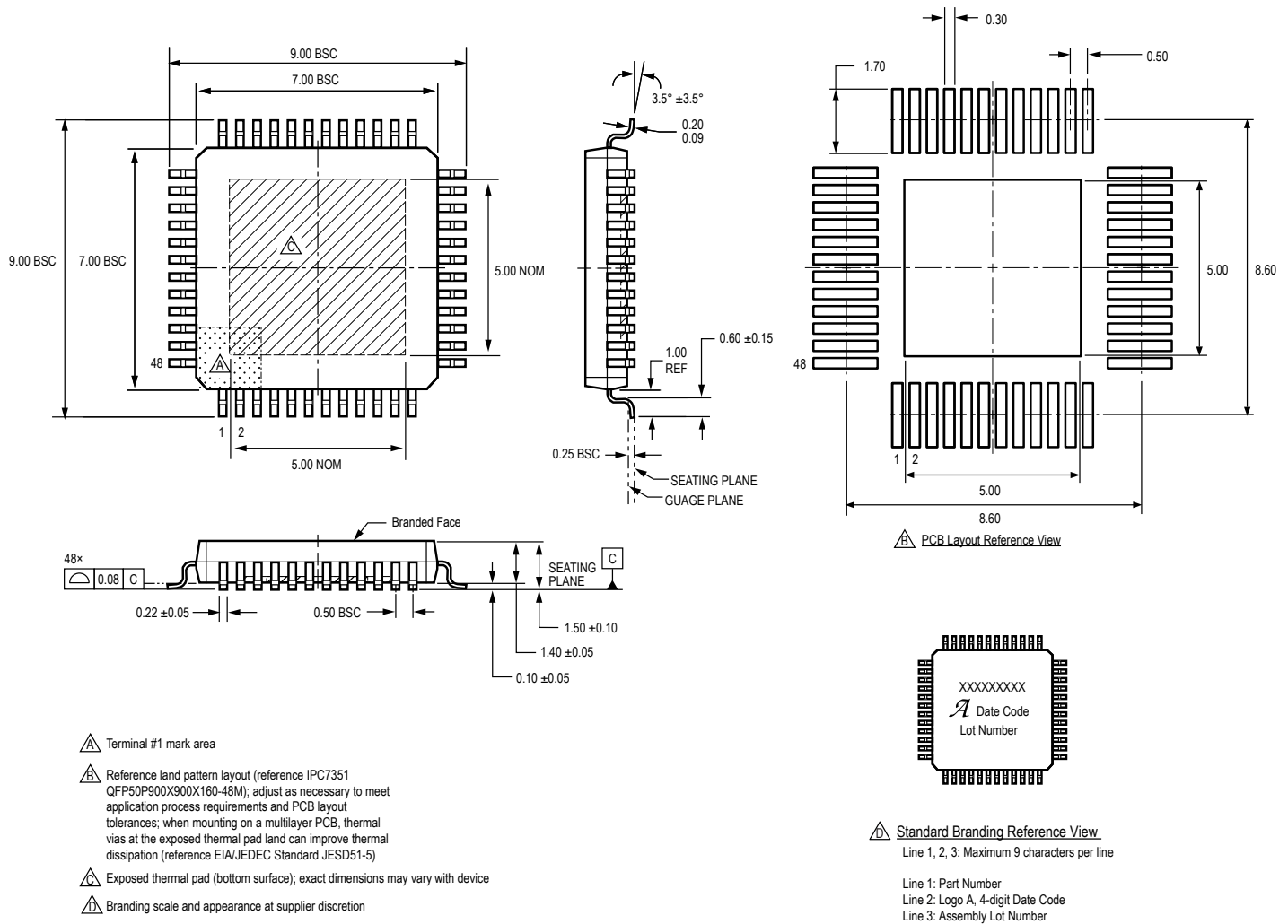


Figure 14: JP Package, 48-Pin LQFP with Exposed Thermal Pad

## Revision History

| Number | Date             | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
|--------|------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| –      | March 24, 2020   | Initial release                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 1      | May 8, 2020      | Updated GHx and GLx Active Pull-Down test conditions and maximum values (page 8), Off-State Test Sink and Source Current test conditions (page 12), External Regulated Supply Mode section (page 19), Gate Drive Control section (page 23), Register 7 (page 46), and Register 6 (page 53). Removed I <sub>REGS</sub> characteristic (page 6).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| 2      | July 9, 2020     | Updated Bootstrap Boost Voltage values (page 6), Pull-Up On-Resistance max values (page 7); removed Input Common Mode Range (page 10); updated VDS Threshold High-Side and Low-Side values (page 11); added footnote 9 to Temperature Warning Threshold, Temperature Warning Hysteresis, Overtemperature Threshold, and Overtemperature Hysteresis (page 12); updated Logic Outputs section (page 24), Monitor: VCC Undervoltage section (page 28), and Bridge: Phase Disconnected section (page 38).                                                                                                                                                                                                                                                                                                                                                                                                                     |
| 3      | October 28, 2021 | Updated VBRG Operating Range, VBRG Input Current, VREG Quiescent Current Regulator Inactive, Bootstrap Boost Voltage (page 6), Pull-Up On-Resistance, Pull-Up Peak Source Current, Pull-Down Peak Source Current (page 7), Input Offset Voltage, Input Common-Mode Range (DC) (page 10), Bootstrap Undervoltage (page 11); removed Input Pulse Filter Time (page 9) and VBRG Input Current (page 11); updated On-State Open Load Timeout, LSS Current (page 12), Input and Output Terminal Functions (page 18), Buck Regulator Mode, External Regulated Supply Mode, VREG Supply Charge Pump Regulator (page 19), High-Side Gate Drive, Low-Side Gate Drive (page 21), Bridge: Bootstrap Capacitor Undervoltage Fault (page 34), On-Line Verification (page 37), VIO, VCL, and BRE footnotes (page 53); added Application Information (page 66-68) and Layout Guidelines (page 70-71); updated package drawing (page 72). |
| 4      | January 17, 2023 | Updated ASIL statement status (page 1); Updated Bootstrap Boost Voltage test conditions and typical value (page 6); typo corrected in Register 6 footnote (page 53)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |

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